



Title	<i>72 W Isolated Flyback Power Supply Using LinkSwitch™-HP LNK6779E</i>
Specification	85 VAC – 265 VAC Input; 12 V / 6 A Output
Application	Appliance
Author	Applications Engineering Department
Document Number	DER-1036
Date	July 11, 2025
Revision	A

Summary and Features

- Primary-side regulated isolated flyback converter with $\pm 5\%$ regulation (including estimated production and temperature variations)
- 132 kHz switching frequency for small transformer and output filter size
- 72 W output power
- Continuous Conduction Mode (CCM) at full load improves efficiency and reduces output capacitor ripple current
- <70 mW no-load input power at 230 VAC
- Multimode operation maximizes efficiency across load range
 - 86% full load efficiency @ 115 VAC and 87% full load efficiency @ 230 VAC
- Extensive protection features including over-temperature protection (OTP), brown-in/out, and lost-regulation (auto-restart)
- Class B Conducted EMI with > 6 db margin

PATENT INFORMATION

The products and applications illustrated herein (including transformer construction and circuits external to the products) may be covered by one or more U.S. and foreign patents, or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at [www.power.com](https://www.power.com/company/intellectual-property-licensing/). Power Integrations grants its customers a license under certain patent rights as set forth at <https://www.power.com/company/intellectual-property-licensing/>.

Power Integrations

5245 Hellyer Avenue, San Jose, CA 95138 USA.
Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.power.com

Table of Contents

1	Introduction	5
2	Power Supply Specification	7
3	Schematic.....	8
4	Circuit Description	9
4.1	Input EMI Filtering and Rectification	9
4.2	LinkSwitch-HP Primary	9
4.3	Primary RZCD Snubber	9
4.4	Output Rectification	10
4.5	External Current Limit Setting.....	10
4.6	Output Feedback	10
5	PCB Layout	11
5.1	PCB Specification	11
6	Bill of Materials	12
6.1	Electrical BOM	12
6.2	Mechanical BOM	14
7	Transformer Specification	14
7.1	Electrical Diagram.....	14
7.2	Electrical Specifications	15
7.3	Material List	15
7.4	Transformer Build Diagram	15
7.5	Transformer Instructions.....	16
7.6	Transformer Winding Illustrations.....	17
8	Common Mode Choke L1 Specification.....	26
8.1	Electrical Diagram.....	26
8.2	Electrical Specifications	26
8.3	Material List	26
8.4	Common Mode Choke Construction	26
9	Design Spreadsheet.....	27
10	Heat Sinks.....	31
10.1	LinkSwitch-HP Heat Sink	31
10.1.1	LinkSwitch-HP Heat Sink Metal Drawing	31
10.1.2	Finished LinkSwitch-HP Heat Sink with Hardware	32
10.1.3	LinkSwitch-HP Heat Sink Assembly.....	33
10.2	Bridge Rectifier Heat Sink.....	34
10.2.1	Bridge Rectifier Heat Sink Metal Drawing	34
10.2.2	Finished Bridge Rectifier Heat Sink with Hardware	35
10.2.3	Bridge Rectifier Heat Sink Assembly	36
10.3	Secondary Diode Heat Sink	37
10.3.1	Secondary Diode Heat Sink Metal Drawing	37
10.3.2	Finished Secondary Diode Heat Sink with Hardware	38
10.3.3	Secondary Diode Heat Sink Assembly	39
11	Performance Data	40
11.1	Full Load Efficiency vs. Line.....	40



11.2	Efficiency vs. Load	41
11.3	Average and 10% Efficiency	42
11.3.1	Average and 10% Efficiency at 115 VAC	42
11.3.2	Average and 10% Efficiency at 230 VAC	42
11.4	No-Load Input Power	43
11.5	Line Regulation	44
11.6	Load Regulation	45
12	Waveforms	46
12.1	Load Transient Response	46
12.1.1	Transient 10% - 100% Load Change	46
12.1.2	Transient 50% - 100% Load Change	47
12.2	Output Start-up	48
12.2.1	Full Load CC Mode	48
12.2.2	Full Load CR Mode	49
12.2.3	No Load	50
12.3	Switching Waveforms	51
12.3.1	Primary MOSFET Drain-Source Voltage and Current at Normal Operation	51
12.3.2	Primary MOSFET Drain-Source Voltage and Current at Start-up Operation	53
12.3.3	Freewheeling Diode Voltage and Current at Normal Operation	55
12.3.4	Freewheeling Diode Voltage and Current at Start-Up	57
12.4	Brown-In and Brown-Out	59
12.5	Output Voltage Ripple	60
12.5.1	Ripple Measurement Technique	60
12.5.2	Measurement Results	61
12.5.3	Output Ripple Voltage Graph	66
13	Thermal Performance	67
13.1	25 °C Ambient Thermals	67
13.1.1	85 VAC Full Load at 25 °C Ambient	68
13.1.2	265 VAC Full Load at 25 °C Ambient	69
13.2	40 °C Ambient Thermals	70
13.2.1	85 VAC Full Load at 40 °C Ambient (Thermal Chamber)	70
13.2.2	265 VAC Full Load at 40 °C Ambient (Thermal Chamber)	71
14	Fault Condition	72
14.1	Output Short-Circuit Protection	72
14.1.1	Start-Up Short	72
14.1.1	Running Short	73
14.2	Over Temperature Protection	76
15	Conducted EMI	78
15.1	Test Set-up Equipment	78
15.1.1	Equipment and Load Used	78
15.2	Output Float	79
16	Line Surge	80
16.1	Differential Mode Surge	80
16.2	Common Mode Ring Wave Surge	81

17	EFT	82
18	ESD.....	83
19	Revision History	84

Important Note: Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.



1 Introduction

This report describes a flyback converter that provides an isolated nominal output voltage of 12 V at 6 A load from a wide input voltage range of 85 VAC to 265 VAC. This power supply utilizes the LNK6779E from the LinkSwitch-HP family of ICs.

This report contains the complete power supply specification, bill of materials, transformer construction, circuit schematic and printed circuit board layout, along with performance data and electrical waveforms.

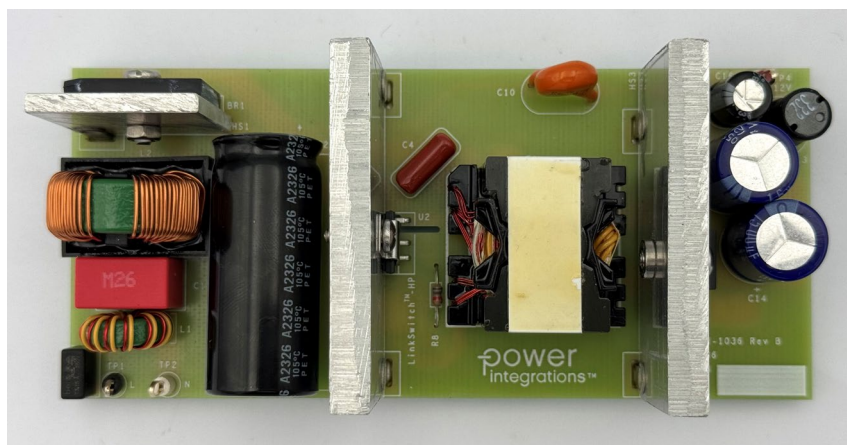


Figure 1 – Populated Circuit Board, Top View.

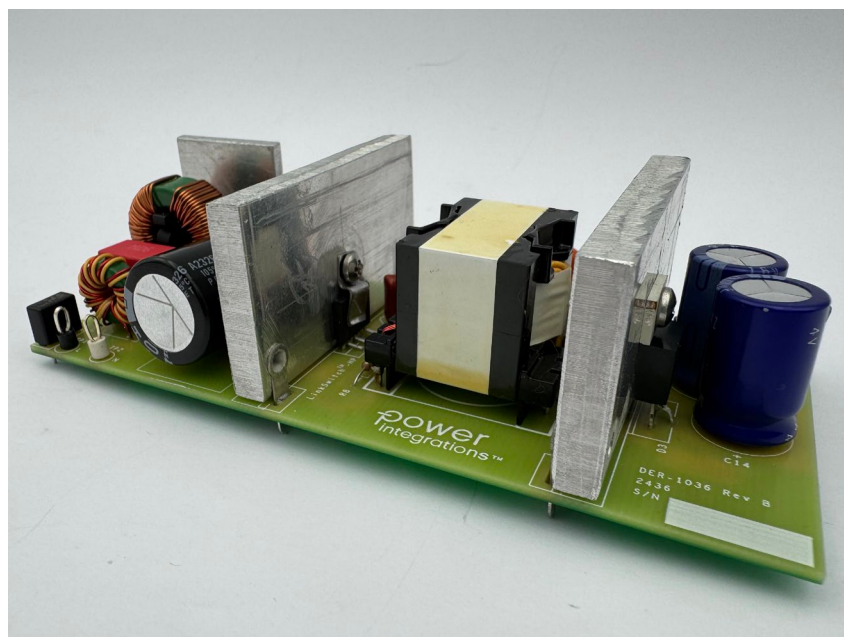


Figure 2 – Populated Circuit Board, Side View.

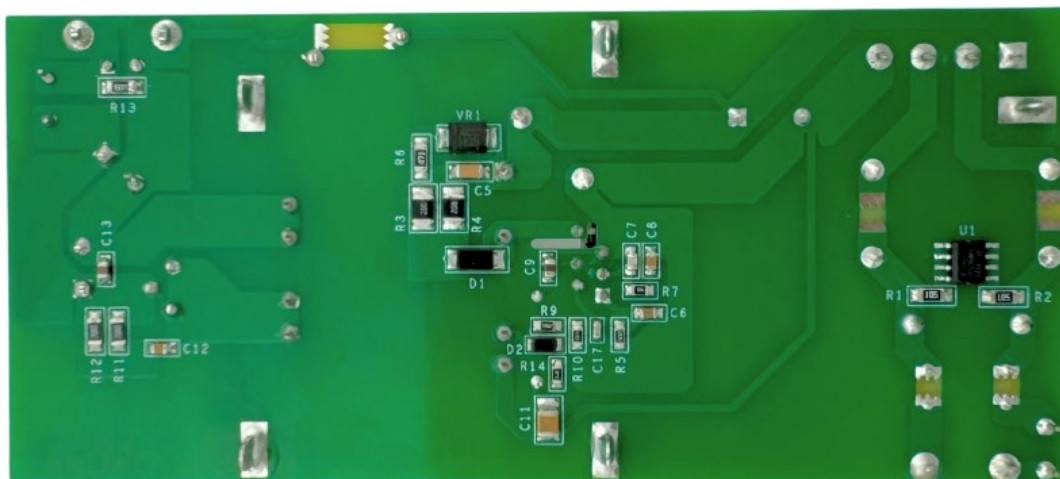


Figure 3 – Populated Circuit Board, Bottom View.

2 Power Supply Specification

The table below represents the minimum acceptable performance of the design. Actual performance is listed in the results section.

Description	Symbol	Min	Typ	Max	Units	Comment
Input						
Voltage	V_{IN}	85	115/230	265	Vac	2 Wire – no P.E.
Frequency	f_{LINE}	47	50 / 60	64	Hz	
No-load Input Power (230 VAC)				70	mW	
Output1						
Output Voltage	V_{OUT1}	11.4	12	12.6	V	± 5% 20 MHz Bandwidth.
Output Ripple Voltage	$V_{RIPPLE1}$			150	mV	
Output Current	I_{OUT1}	0		6	A	
Total Output Power						
Continuous Output Power	P_{OUT}	0		72	W	
Efficiency						
Full Load 115Vac	η_{115Vac}	86			%	Measured at P_{OUT} 25 °C. Measured at Nominal Input 115 VAC and 230 VAC.
Full Load 230Vac	η_{230Vac}	87			%	
Average efficiency at 25, 50, 75 and 100 % of P_{OUT}	η_{DOE}	88			%	
Environmental						
Conducted EMI			Meets CISPR22B / EN55022B			1.2/50 μ s Surge, IEC 61000-4-5
Surge (Differential)				±1	kV	
Ring Wave (Common Mode)				±4	kV	
Electrical Fast Transient				±4	kV	
ESD – Air Discharge				±16.5	kV	
ESD – Contact Discharge				±8.8	kV	Free Convection, Sea Level.
Ambient Temperature	T_{AMB}	0		40	°C	

Table 1 – Power Supply Specifications.

3 Schematic

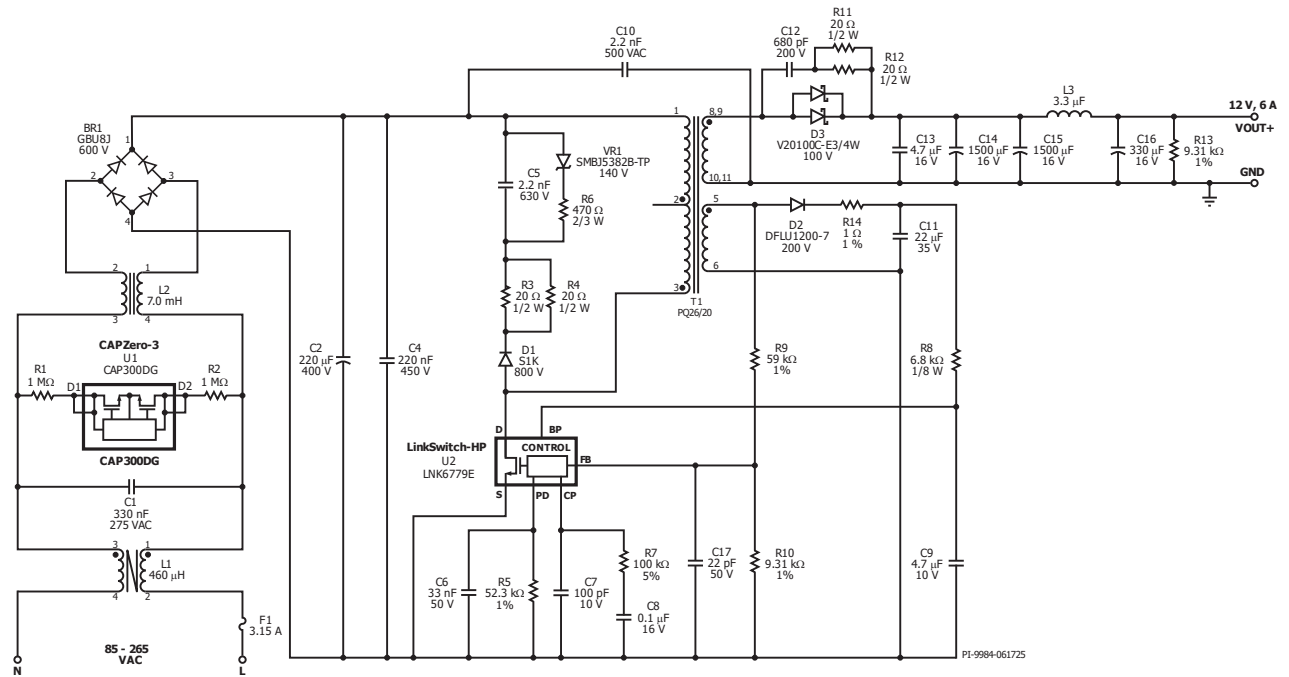


Figure 4 – DER-1036 Schematic.

4 Circuit Description

The circuit shown in Figure 4 utilizes the LNK6779E device in a 12 V, 72 W isolated flyback power supply.

4.1 Input EMI Filtering and Rectification

Fuse F1 isolates the circuit and provides protection from component failure. X-capacitor C1 with common mode chokes L1 and L2 form an EMI filter that attenuates both common mode and differential mode conducted EMI. Resistors R1 and R2 together with the CAP300DG CAPZero™ IC (U1) discharge C1 when Alternating Current (AC) is removed. BR1 converts the AC line voltage into the DC voltage seen across bulk capacitor C2.

4.2 LinkSwitch-HP Primary

The LNK6779E device (U2) integrates an oscillator, error amplifier, multi-mode control circuit, start-up and protection circuitry, and a high-voltage power Metal-Oxide-Semiconductor Field-Effect Transistor (MOSFET) all in one monolithic integrated circuit (IC).

When AC is first applied, an internal current source connected to the DRAIN (D) pin charges C9 to power the controller inside the IC. During normal operation (steady-state), the device controller is powered via the bias winding through the current limiting resistor R8 to minimize losses.

At the start of a switching cycle, the internal power MOSFET turns on, allowing current through the primary winding to ramp to a threshold that is set by the output of the internal error amplifier pin voltage, which is presented on the compensation (CP) pin. Due to the phase orientation of the transformer windings, the freewheeling diode D3 is reverse biased at this point in the cycle. D3 only conducts when the internal power MOSFET is off, allowing the energy stored in the core of the transformer to be delivered to the output.

Capacitor C9 (4.7 μ F) connected to the BYPASS (BP) pin sets over-temperature protection (OTP) to hysteretic mode, and overvoltage protection (OVP) and lost regulation protection to automatic-restart, AR, after a given off-period (typ. 1.5 s).

4.3 Primary RZCD Snubber

Diode D1, Zener Diode VR1, Capacitor C5 and Resistor R6 form a Resistor-Zener Capacitor Diode (RZCD) snubber circuit that is used to limit the voltage stress across the LinkSwitch-HP IC. Peak drain voltage is limited to less than 600 V providing significant margin to the 725 V drain voltage limit (Breakdown Voltage, Drain-Source at Zero Gate-Source Voltage, BVDSS). Zener diode VR1 prevents the capacitor C5 from fully discharging every switching cycle to reduce power consumption during standby operation. Resistors R3 and R4 damp drain oscillations for better output voltage regulation and reduced Electromagnetic Interference (EMI).



4.4 Output Rectification

Schottky diode D3 rectifies the 12 V secondary winding output of T1. The output voltage is filtered by C13, C14, C15, L3, and C16. Resistors R11 and R12 and capacitor C12 snub the voltage spike caused by the commutation of D3. Low Equivalent Series Resistance (ESR) capacitors C14 and C15 minimize output voltage ripple, while the post filter formed by L3 and C16 further attenuate noise and ripple. Resistor R13 acts as a preload to improve load regulation, especially at no load.

4.5 External Current Limit Setting

The maximum cycle-by-cycle current limit is set by the resistor R5 connected to the PROGRAM (PD) pin. A 52.3 k Ω resistor in the design sets the maximum current limit to 80% of the LNK6779E's default current limit.

4.6 Output Feedback

The output voltage is indirectly sensed through the bias winding via a resistor divider (R9 and R10) and applied to the FEEDBACK (FB) pin voltage. This network is also used to indirectly monitor the bus voltage during start-up and enables output power delivery only when the input voltage reaches the brown-in threshold and stops when the input voltage is below brown-out level. If the bus voltage reaches excessive levels (e.g., caused by a line surge) the device stops switching. The cycle-by-cycle current limit is compensated over line to limit the power available in overload.

The voltage sensed at the FB pin produces a control voltage at the CP pin. Resistor R7 and capacitors C7 and C8 are used for control loop compensation. The peak primary current and the switching frequency are determined by the CP pin voltage.

5 PCB Layout

5.1 PCB Specification

- Layer: 1
- Board Thickness: 1.6 mm.
- Copper Thickness: 2 oz.
- Material: FR-4

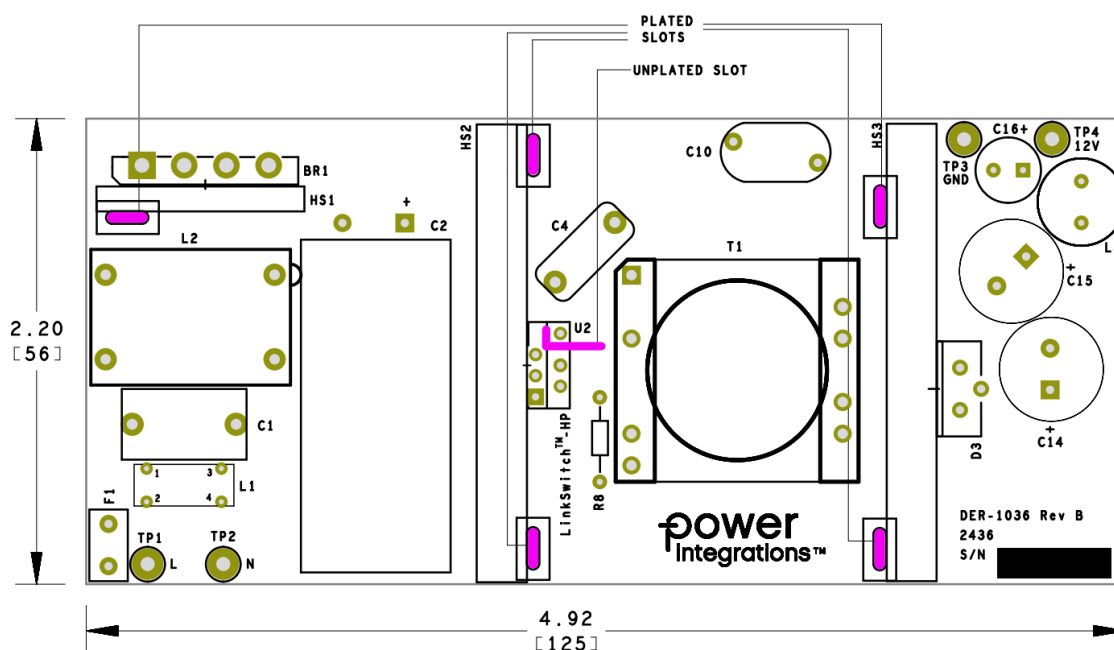


Figure 5 – Printed Circuit Board, Top View.

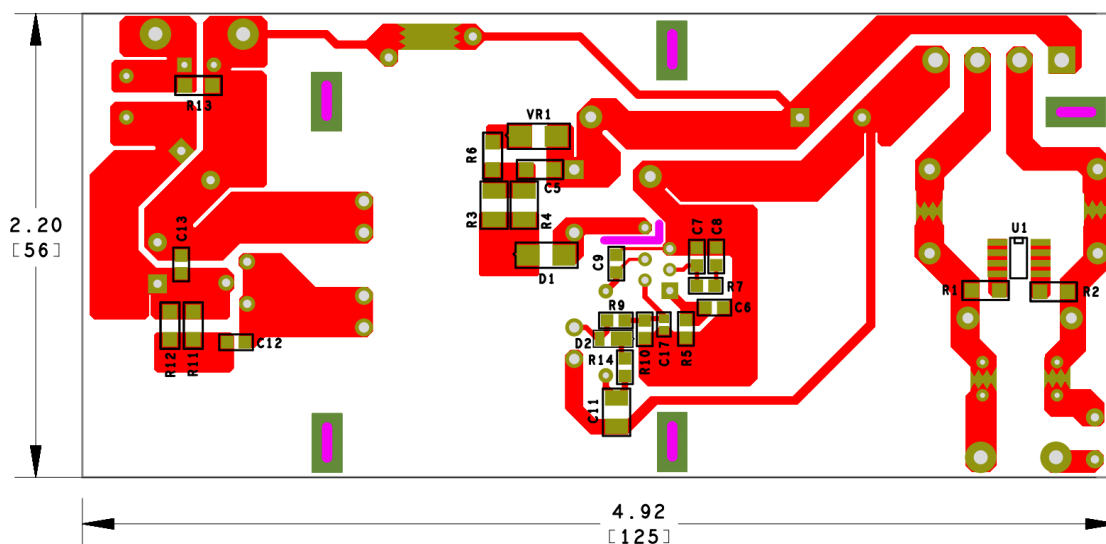


Figure 6 – Printed Circuit Board, Bottom View.

6 Bill of Materials

6.1 Electrical BOM

Item	Qty.	Reference Designator	Description	Mfr. Part Number	Manufacturer
1	1	BR1	600 V, 8 A, Bridge Rectifier, GBU Case	GBU8J-BP	Micro Commercial Co.
2	1	C1	330 nF, $\pm 10\%$, 275 VAC, Polypropylene Film, X2, 15.00mm x 8.50mm	890324024003CS	Wurth Electronics Inc.
3	1	C2	220 μ F, 400 V, Electrolytic, General Purpose, (18 x 40)	400HXW220MEFR18X40	Rubycon
4	1	C4	220 nF, 450 V, Film	MEXXF32204JJ	Duratech
5	1	C5	2.2 nF, 630 V, Ceramic, X7R, 1206	C3216X7R2J222K115AA	TDK Corp
6	1	C6	33 nF, 50 V, Ceramic, X7R, 0805	CC0805KRX7R9BB333	Yageo
7	1	C7	100 pF, $\pm 10\%$, 10 V, Ceramic, X7R, 0805 (2012 Metric)	C0805C101K8RACAUTO	Kemet
8	1	C8	0.1 μ F $\pm 10\%$ 16V Ceramic Capacitor X7R 0805 (2012 Metric)	C0805C104K4RECAUTO	KEMET
9	1	C9	4.7 μ F $\pm 10\%$ 10V Ceramic Capacitor X7R 0805 (2012 Metric)	LMK212B7475KGHT	Taiyo Yuden
10	1	C10	2200PF, $\pm 20\%$, 500VAC (Y1), 760VAC (X1), Ceramic, Y5U (E), RADIAL	440LD22-R	Vishay
11	1	C11	22 μ F, $\pm 20\%$, 35V, Ceramic Capacitor X5R, 1210 (3225 Metric)	GMK325BJ226MM-P	Taiyo Yuden
12	1	C12	680 pF 200V X7R MULTI-LAYER CERAMIC +/- 10 %	C0805C681K2RACAUTO	Kemet
13	1	C13	4.7 μ F, 16 V, Ceramic, X7R, 0805 (2012 Metric)	CL21B475KOFNNNE	Samsung Electro-Mechanics
14	2	C14 C15	1500 μ F, 16 V, Electrolytic, Low ESR, 38 mOhm, (12.5 x 20)	ELXZ160ELL152MK20S	Nippon Chemi-Con
15	1	C16	330 μ F, 16 V, Electrolytic, Very Low ESR, 72 mOhm, (8 x 11.5)	16ZL330M8X11.5	Rubycon
16	1	C17	22 pF, 50 V, Ceramic, NP0, 0603	C1608C0G1H220J	TDK Corp
17	1	D1	DIODE, GEN PURP, 800V, 1A, Standard Recovery >500ns, > 200mA (Io), SMA (DO-214AC)	S1K	ON Semiconductor
18	1	D2	DIODE, UFAST, 200V, 1A, POWERDI123	DFLU1200-7	Diodes Inc
19	1	D3	Diode Array, 1 Pair, Common Cathode, 100 V, 10A, Through Hole TO-220-3	V20100C-E3/4W	Vishay Semiconductor Diodes Division
20	1	F1	3.15 A, 250V, Slow, RST	RST 3.15-BULK	Belfuse
21	1	L1	460 μ H, Toroidal Common Mode Choke, 1.5 A, custom, DER-931, wound on 32-00315-00 core	32-00416-00	Power Integrations
22	1	L2	7.0 mH, 2.2 A, Common Mode Choke	52705C	Murata
23	1	L3	FIXED IND, 3.3uH, $\pm 20\%$, 9.5A, 10 mOHM, TH, 10.5 mmD x 12 mmH	DR0810-332L	Coilcraft
24	2	R1 R2	RES, 1.0 M, 5%, 2/3 W, Thick Film, 1206	ERJ-P08J105V	Panasonic
25	2	R3 R4	RES, 20 Ohm, $\pm 5\%$, 0.5W, 1/2W, 1210 (3225 Metric), Thick Film	CRCW121020R0JNEA	Vishay Dale
26	1	R5	RES, 52.3 k, 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF5232V	Panasonic
27	1	R6	RES, 470 R, 5%, 2/3 W, Thick Film, 1206	ERJ-P08J471V	Panasonic
28	1	R7	RES, 100 k, 5%, 1/8 W, Thick Film, 0805	ERJ-6GEYJ104V	Panasonic
29	1	R8	RES, 6.8 k, 5%, 1/8 W, Carbon Film	CF18JT6K80	Stackpole
30	1	R9	RES, 59.0 k, 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF5902V	Panasonic
31	1	R10	RES, 9.31 k, 1%, 1/8 W, Thick Film, 0805	ERJ-6ENF9311V	Panasonic
32	2	R11 R12	RES, 20 R, 1%, 1/2 W, Thin Film, 1206	RNCP1206FTD20R0	Stackpole Electronics
33	1	R13	RES, 9.31 k, 1%, 1/4 W, Thick Film, 1206	ERJ-8ENF9311V	Panasonic
34	1	R14	RES, 1.00 R, 1%, 1/8W, 0805, Thick Film	RMCF0805FT1R00	Stackpole Electronics Inc.
35	1	T1	Bobbin, PQ26/20, Vertical, 12 pins	B65878E0012D001	EPCOS (TDK)



36	1	U1	CAPZero-3, CAP300DG, SO-8C	CAP300DG	Power Integrations
37	1	U2	LinkSwitch-HP, LNK6779E, Esip-7C	LNK6779E	Power Integrations
38	1	VR1	Zener Diode, 140 V, 5 W, $\pm 5\%$, Surface Mount DO-214AA (SMB)	SMBJ5382B-TP	Micro Commercial Co

Table 2 – Electrical Bill of Materials.

6.2 Mechanical BOM

Item	Qty.	Reference Designator	Description	Mfr. Part Number	Manufacturer
1	1	ESIP CLIP1	Heatsink Hardware, Edge Clip, 12.40 mm x 6.50 mm	TRK-24	Kang Tang Hardware Enterprise Co. Ltd.
2	1	HS1	SHTM, Heat Sink, DER-1036_LinkSwitch_Heatsink	61-00370-00	Custom
3	1	HS2	SHTM, Heat Sink, DER-1036_Bridge_Heatsink	61-00371-00	Custom
4	1	HS3	SHTM, Heat Sink, DER-1036_SEC_Diode_Heatsink	61-00372-00	Custom
5	3	NUT1 NUT2 NUT3	Nut, Hex, 4-40, 3/16W x 1/16 T, Stl Znc	4CSHNZR	Olander Co.
6	3	RTV1 RTV2 RTV3	Thermally conductive Silicone Grease	120-SA	Wakefield
7	3	SCREW1 SCREW2 SCREW3	SCREW MACHINE PHIL 4-40 X 3/8 SS	PMSSS 440 0038 PH	Building Fasteners
8	5	TE1 TE2 TE3 TE4 TE5	Terminal, Eyelet, Tin Plated Brass, Zierick PN 190	190	Zierick
9	1	WASHER1	Washer, Lk, #4 SS	4NSLWS	Olander Co.
10	2	TP1 TP3	Test Point, BLK, THRU-HOLE MOUNT	5011	Keystone
11	1	TP2	Test Point, WHT, THRU-HOLE MOUNT	5012	Keystone
12	1	TP4	Test Point, RED, THRU-HOLE MOUNT	5010	Keystone

Table 3 – Mechanical Bill of Materials.

7 Transformer Specification

7.1 Electrical Diagram

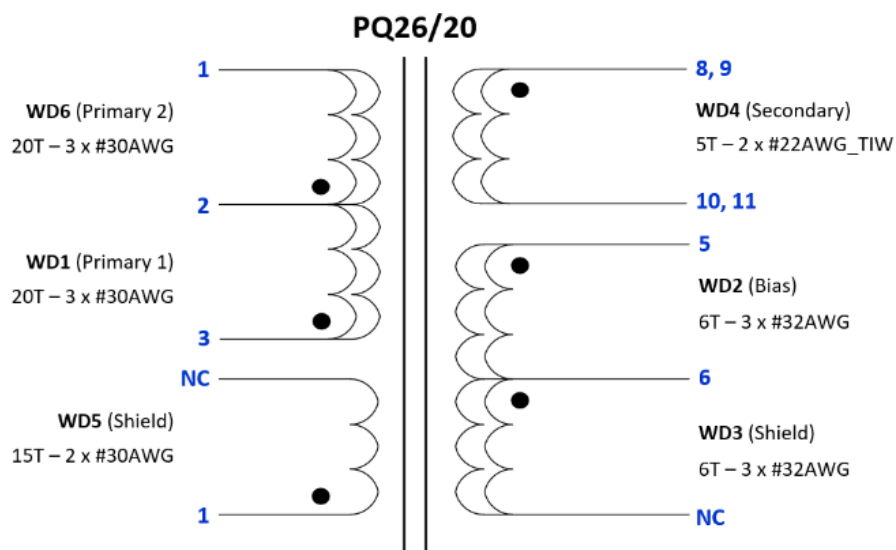


Figure 7 – Transformer Electrical Diagram.

7.2 Electrical Specifications

Parameter	Condition	Spec.
Nominal Primary Inductance	Measured at 1 V _{PK-PK} , 100 kHz switching frequency, between pin 1 and pin 3 with all other windings open.	519 μ H
Tolerance	Tolerance of Primary Inductance.	$\pm 5\%$
Leakage Inductance	Measured across primary winding with all other windings shorted.	< 10.39 μ H

Table 4 – Electrical Specifications.

7.3 Material List

Item	Description
[1]	Core: PQ26/20, TDK-PC95, gapped for ALG of 325 nH/T ² .
[2]	Bobbin: PQ26/20, Vertical, 12 pins (6/6), TDK; or Equivalent.
[3]	Magnet Wire: #30 AWG.
[4]	Magnet Wire: #32 AWG.
[5]	TIW Wire: #22 AWG.
[6]	Polyester Tape: 10 mm.
[7]	Polyester Tape: 11.5 mm.
[8]	Varnish: Dolph BC 359; or Equivalent.

Table 5 – Material List.

7.4 Transformer Build Diagram

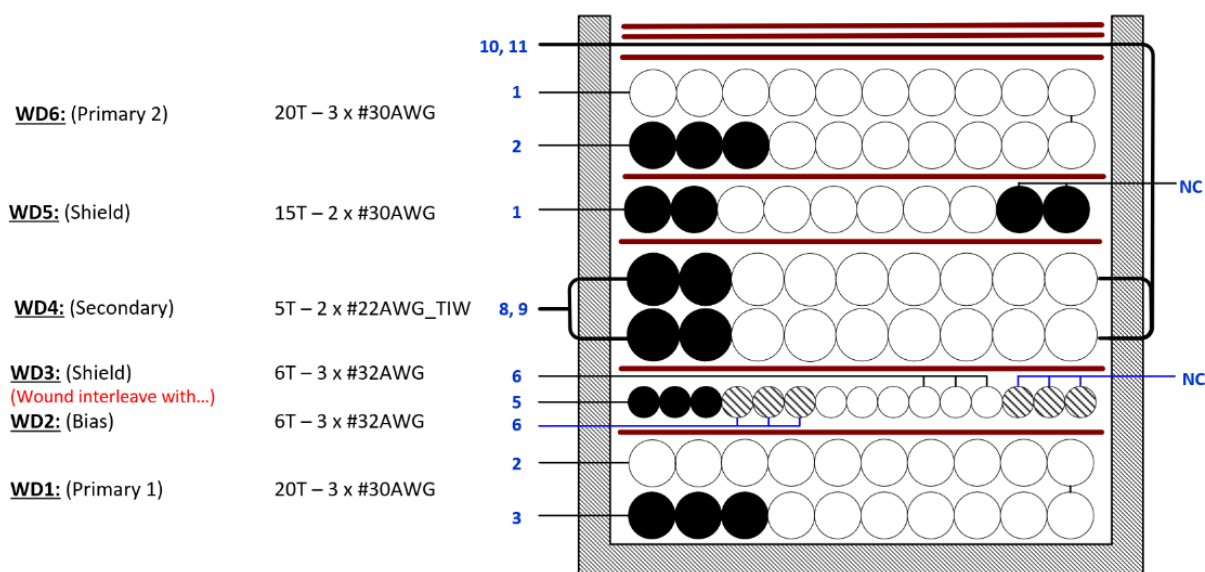


Figure 8 – Transformer Build Diagram.

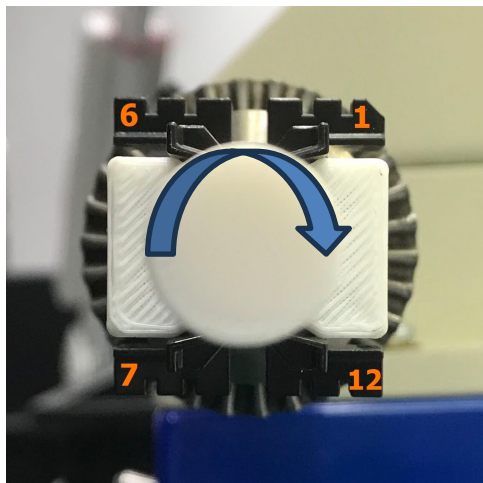
7.5 Transformer Instructions

WD1 1st Primary	Place the bobbin Item [2] such that pins 1-6 are on upper side while 7-12 are on lower side. The notch on the bobbin signifies Pin 1. Winding direction is clockwise as shown. Prepare 3 strands of wire Item [3]. Start at pin 3, wind 10 turns of wire Item [3] for the first layer from left to right. Wind the other 10 turns for the second layer from right to left. Finish WD1 at pin 2.
Insulation	Apply 1 layer of tape Item [6] for insulation. Wrap the tape to cover WD1.
WD2 & WD3 Bias and Shield	Prepare 6 strands of wire Item [4] for WD2 and WD3. Start WD2 at pin 5 with 3 strands and WD3 at pin 6 with another 3 strands. Mark the end of WD2 to avoid confusion. Position WD2 first and followed by WD3. Wind all the wires together for 6 turns from left to right.
Insulation	Apply 1 layer of tape Item [6] for insulation and to hold wires in place. Finish WD2 at Pin 6. Bend the end of WD3 90 degrees, cut as shown and leave it floating. Finish wrapping the tape to cover both WD2 and WD3.
WD4 Secondary	Prepare 4 strands of wire Item [5]. Start by fixing the first 2 strands of wire Item [5] on the left side and fixing it with tape. Wind the first 2 strands of wire 5 turns from left to right. Set aside the remaining wire on the right side and fix it with tape. Place the second 2 strands of wire above the first layer. Wind the second 2 strands of wire above the first layer 5 turns from left to right. Set aside the remaining wire on the right side and fix it with tape.
Insulation	Use 1 layer of tape Item [6] for insulation.
WD5 Shield	Prepare 3 strands of wire Item [3]. Start at pin 1, wind 15 turns of wire Item [3] in 1 layer from left to right.
Insulation	Apply 1 layer of tape Item [6] for insulation and to hold wires in place. Bend the end of WD5 90 degrees, cut as shown and leave it floating. Finish wrapping the tape to cover WD5.
WD6 2nd Primary	Prepare 3 strands of wire Item [3]. Start at pin 2, wind 10 turns of wire Item [3] for the first layer from left to right. Wind the other 10 turns for the second layer from right to left. Finish WD6 at pin 1.
Insulation	Apply 1 layer of tape Item [6] for insulation. Wrap the tape to cover WD6.
WD4 Continuation	Bend the wires from WD4 that are floating at the right side for 180 degrees, placing it beside pins 7-12. Apply 2 layers of tape Item [6] for insulation. Wrap the tape to cover WD4. To finish WD4, bend the wires from the lower side and terminate at pins 8-9 and bend wires from the upper side and terminate at pins 10-11.
Insulation	Apply 2 layers of tape Item [6] for insulation. Wrap the tape to cover WD4. To finish WD4, bend the wires from the lower side to finish winding at pins 8-9 and wires from the upper side to finish winding at pins 10-11.
Assembly	Grind the center leg of the upper half of Item [1] to get 519 μ H measured between Pin 1 and Pin 3 with all other pins open. Wrap the body of transformer with 2 layers of tape Item [7]. Measure Primary Inductance between Pin 1 and Pin 3 with all other pins open, then Leakage Inductance between Pin 1 and Pin 3 with all other pins shorted together.
Finish	Varnish using Item [8]. Check Primary Inductance and Leakage Inductance to confirm that the varnished transformer is within specification.

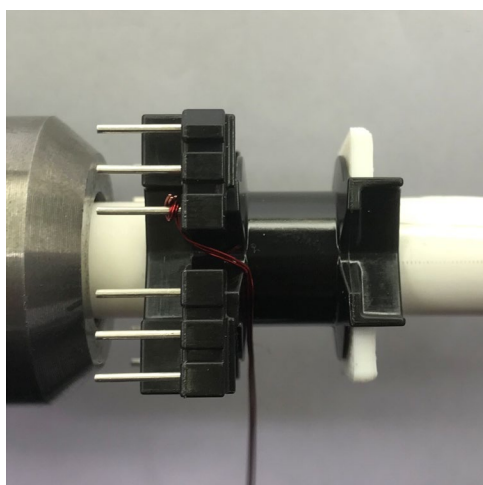
Table 6 – Transformer Instructions.

7.6 Transformer Winding Illustrations

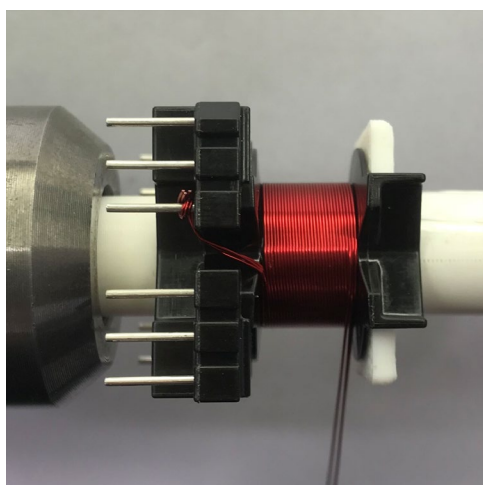
WD1 1st Primary



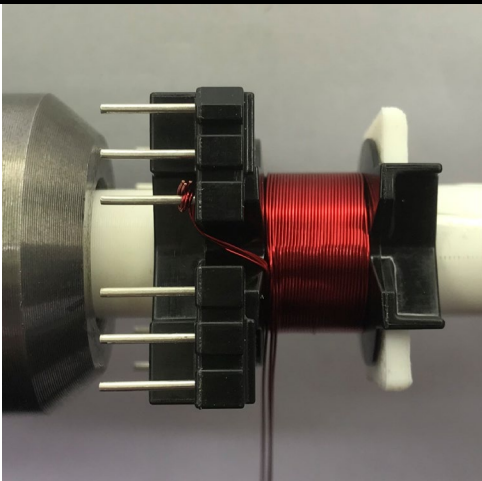
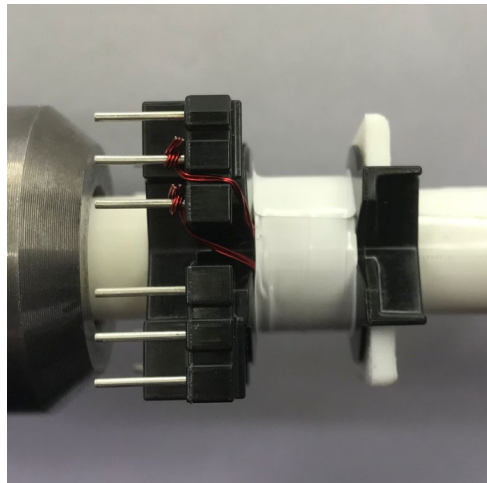
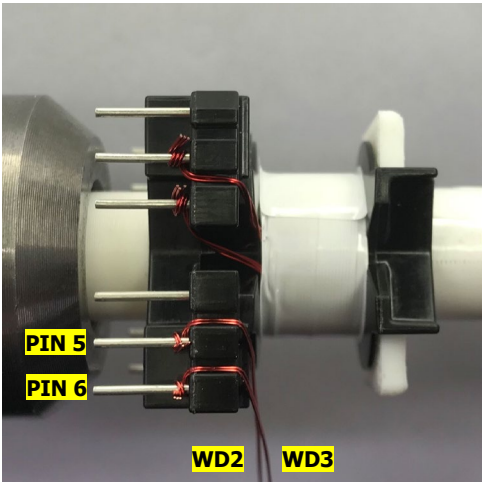
Place the bobbin Item [2] such that pins 1-6 are on upper side while 7-12 are on lower side. The notch on the bobbin signifies Pin 1. Winding direction is clockwise as shown.

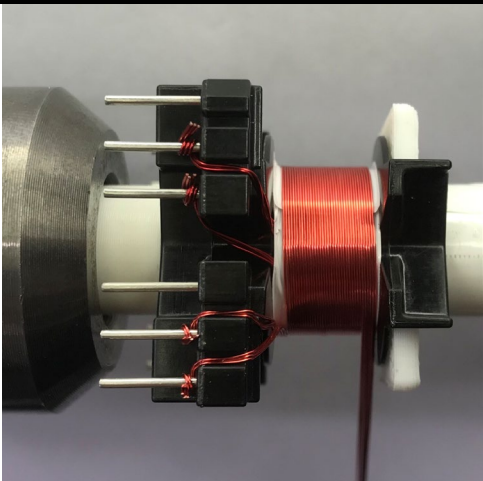
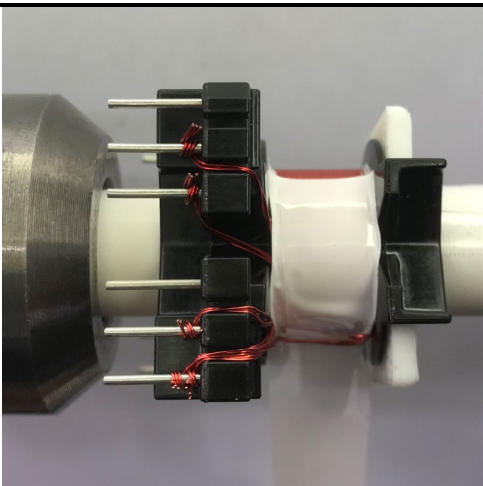
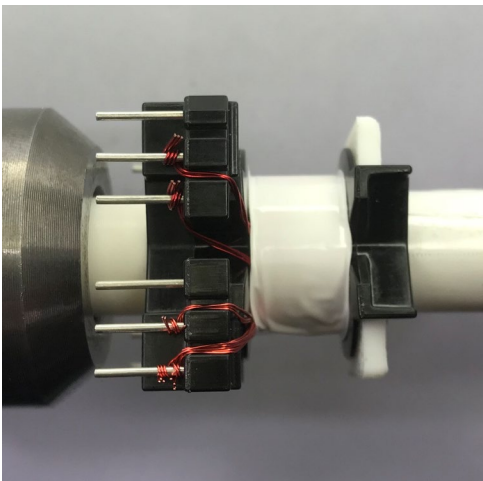


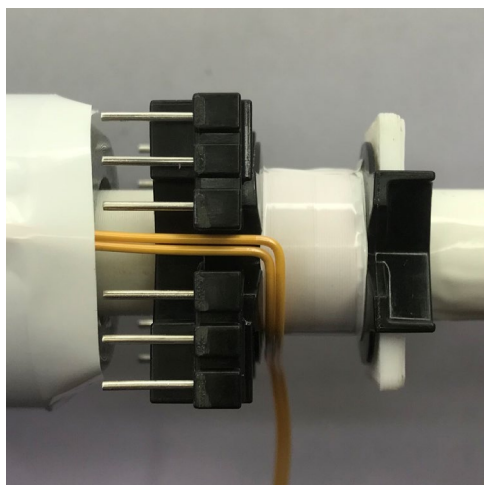
Prepare 3 strands of wire Item [3].



Start at pin 3, wind 10 turns of wire Item [3] for the first layer from left to right.

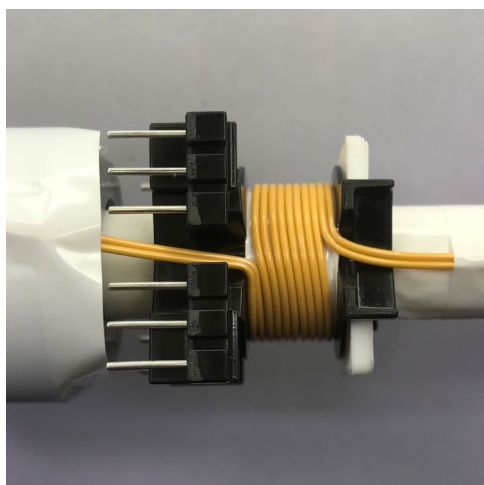
		Wind the other 10 turns for the second layer from right to left. Finish WD1 at pin 2.
Insulation		Apply 1 layer of tape Item [6] for insulation. Wrap the tape to cover WD1.
WD2 & WD3 Bias and Shield		Prepare 6 strands of wire Item [4] for WD2 and WD3. Start WD2 at pin 5 with 3 strands and WD3 at pin 6 with another 3 strands. Mark the end of WD2 to avoid confusion. Position WD2 first and followed by WD3.

		Wind all the wires together for 6 turns from left to right.
Insulation	 	Apply 1 layer of tape Item [6] for insulation and to hold wires in place. Finish WD2 at Pin 6. Bend the end of WD3 90 degrees, cut as shown and leave it floating. Finish wrapping the tape to cover both WD2 and WD3.

**WD4
Secondary**

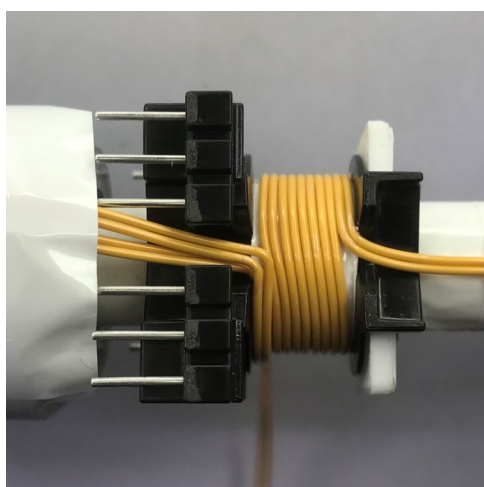
Prepare 4 strands of wire Item [5].

Start by fixing the first 2 strands of wire Item [5] on the left side and fixing it with tape.

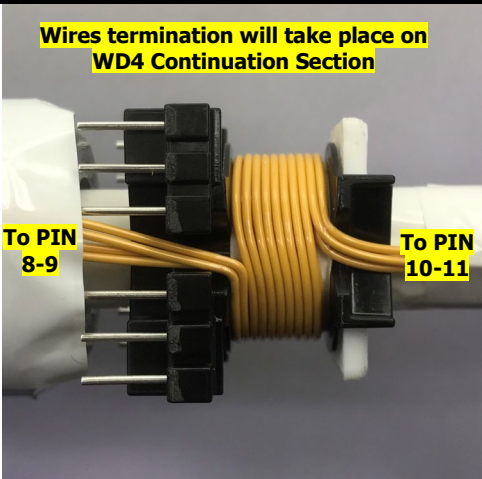
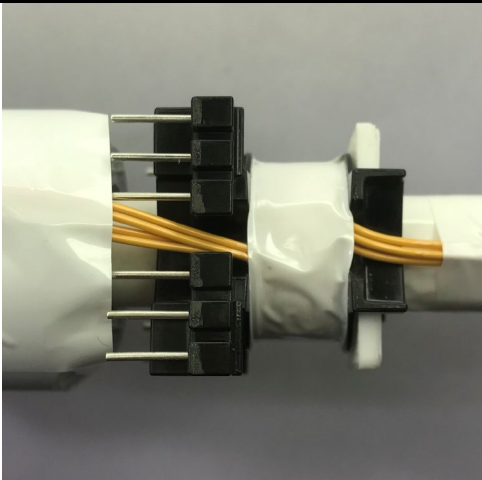
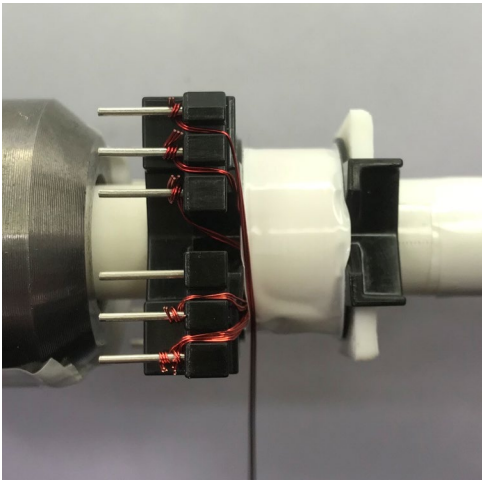


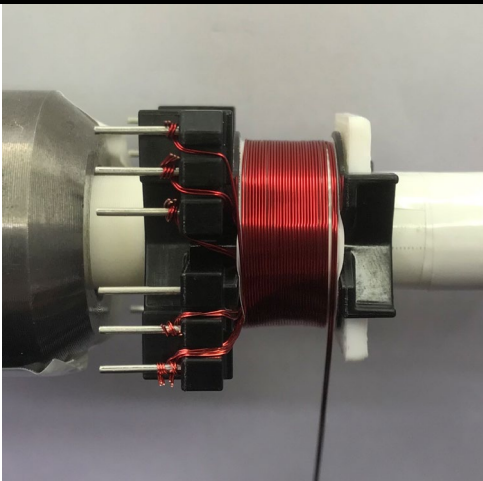
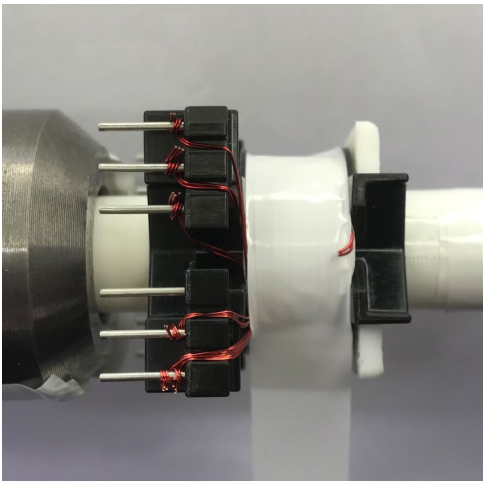
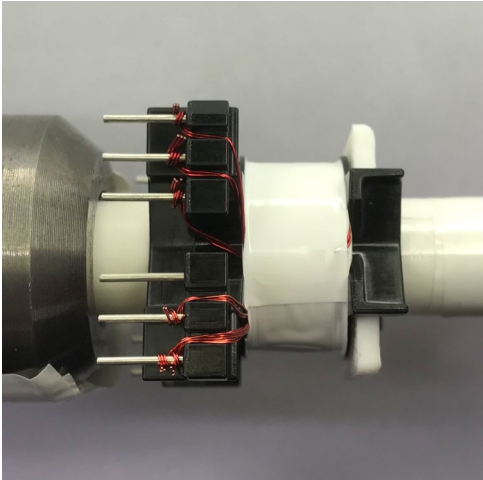
Wind the first 2 strands of wire 5 turns from left to right.

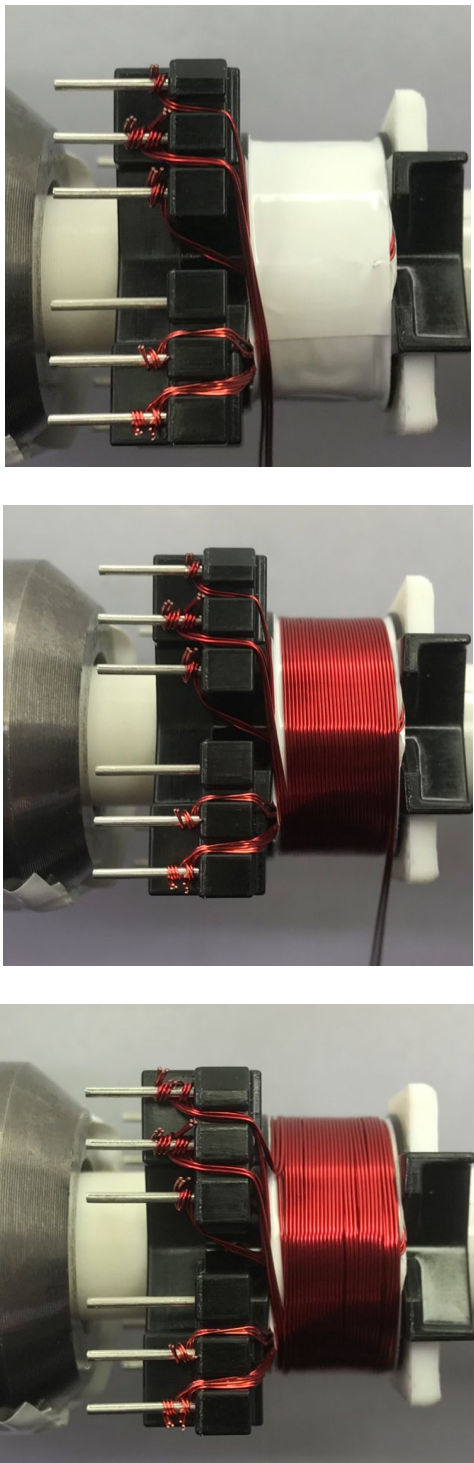
Set aside the remaining wire on the right side and fix it with tape.

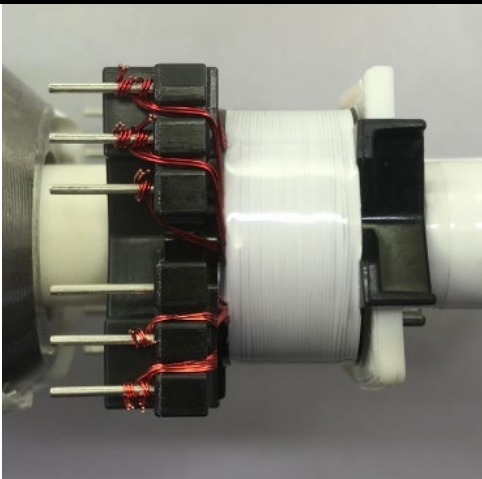
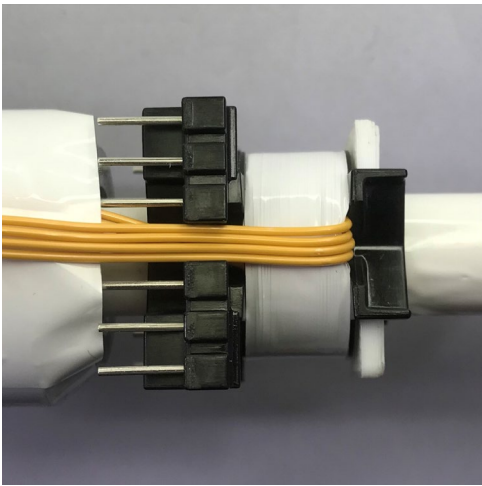
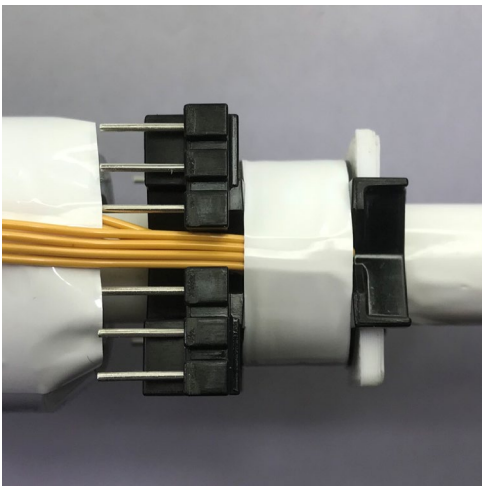


Place the second 2 strands of wire above the first layer.

	 Wires termination will take place on WD4 Continuation Section To PIN 8-9 To PIN 10-11	Wind the second 2 strands of wire above the first layer 5 turns from left to right. Set aside the remaining wire on the right side and fix it with tape.
Insulation		Use 1 layer of tape Item [6] for insulation.
WD5 Shield		Prepare 3 strands of wire Item [3].

		Start at pin 1, wind 15 turns of wire Item [3] in 1 layer from left to right.
Insulation	 	Apply 1 layer of tape Item [6] for insulation and to hold wires in place. Bend the end of WD5 90 degrees, cut as shown and leave it floating (NC). Finish wrapping the tape to cover WD5.

WD6 2nd Primary		Prepare 3 strands of wire Item [3]. Start at pin 2, wind 10 turns of wire Item [3] for the first layer from left to right. Wind the other 10 turns for the second layer from right to left. Finish WD6 at pin 1.
---	--	--

Insulation		Apply 1 layer of tape Item [6] for insulation. Wrap the tape to cover WD6.
WD4 Continuation		Bend the wires from WD4 that are floating at the right side for 180 degrees, placing it beside pins 7-12.
Insulation		Apply 2 layers of tape Item [6] for insulation. Wrap the tape to cover WD4.

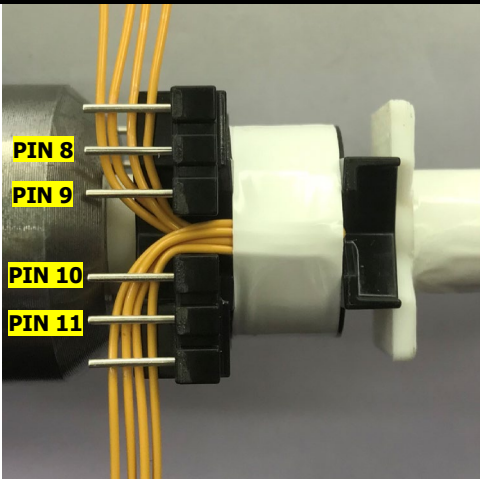
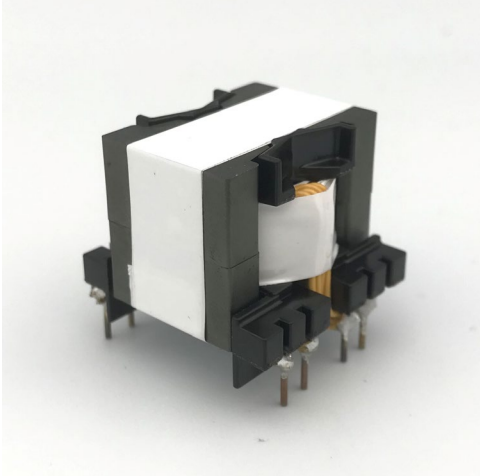
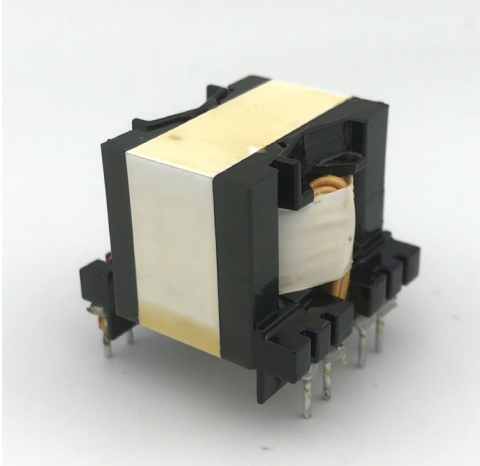
		To finish WD4, bend the wires from the lower side and terminate at pins 8-9 and bend wires from the upper side and terminate at pins 10-11.
Assembly		Grind the center leg of the upper half of Item [1] to get 519 μH measured between Pin 1 and Pin 3 with all other pins open. Wrap the body of transformer with 2 layers of tape Item [7]. Measure Primary Inductance between Pin 1 and Pin 3 with all other pins open, then Leakage Inductance between Pin 1 and Pin 3 with all other pins shorted together.
Finish		Varnish using Item [8]. Check Primary Inductance and Leakage Inductance to confirm that the varnished transformer is within specification.

Table 7 – Transformer Winding Illustrations.

8 Common Mode Choke L1 Specification

8.1 Electrical Diagram

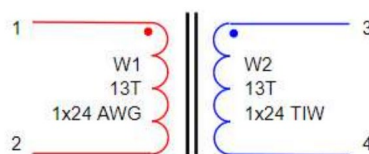


Figure 9 – Choke Electrical Diagram.

8.2 Electrical Specifications

Parameter	Condition	Spec.
Winding Inductance	Pin 1 – Pin 2 (or Pin 3 – Pin 4), all other windings open, measured at 100 kHz, 0.4 V _{RMS} .	460 μH $\pm$ 20%

Table 8 – Electrical Specifications.

8.3 Material List

Item	Description
[1]	Toroid: FERRITE INDUCTOR TOROID 12 mm O.D.; Mfr. Part number: GL50 T 12X6X4-C Dim: 12mm O.D. x 4 mm I.D. x 6 mm Th.
[2]	Triple Insulated Wire: #24 AWG, Triple Coated.
[3]	Magnet Wire: #24 AWG, Double Coated.

Table 9 – Material List.

8.4 Common Mode Choke Construction

Mark the start of the winding as 1 and wind 13 turns of Item [2] on Item [1]. Mark the end of this winding as 2	
Repeat the same procedure as above for the other winding using Item [3], making sure that the start/end and the direction of winding is the same as the first winding. Mark the start of this winding as 3 and the end as 4.	

9 Design Spreadsheet

1	ACDC LinkSwitch-HP_060623; Rev.2.2; Copyright Power Integrations 2023	INPUT	INFO	OUTPUT	UNIT	ACDC LinkSwitchHP_060623 Rev 2-2.xls: LinkSwitch-HP Flyback Continuous/Discontinuous Transformer Design Spreadsheet
2	ENTER APPLICATION VARIABLES					Customer
3	VACMIN	85		85	V	Minimum AC Input Voltage
4	VACMAX	265		265	V	Maximum AC Input Voltage
5	fL			50	Hz	AC Mains Frequency
6	VO	12.00		12.00	V	Output Voltage (main)
7	PO	72.00		72.00	W	Load Power
8	n	0.90		0.90		Efficiency Estimate
9	Z			0.50		Loss Allocation Factor
10	VB	12.00		12.00	V	Bias Voltage
11	tC			3.00	ms	Bridge Rectifier Conduction Time Estimate
12	CIN	220		220	µF	Input Filter Capacitor
13	Package	E/V		E/V		E and V Package Selected
14	Enclosure	Open Frame		Open Frame		Open Frame type enclosure
15	Heatsink	Metal		Metal		Metallic heatsink thermally connected to the exposed metal on the E-package
16						
17						
18	ENTER LinkSwitch-HP VARIABLES					
19	LinkSwitch-HP	LNK6779E		LNK6779E		Manual Device Selection
20	ILIMITMIN			3.162	A	Minimum Current limit
21	ILIMITMAX			3.638	A	Maximum current limit
22	ILIMITMIN_EXT			2.53	A	External Minimum Current limit
23	ILIMITMAX_EXT			2.91	A	External Maximum current limit
24	KI	0.8		0.8		Current limit reduction factor
25	Rpd			52.30	k-ohm	Program delay Resistor
26	Cpd			33.0	nF	Program delay Capacitor
27	Total programmed delay			0.38	sec	Total program delay
28	fS			132	kHz	LinkSwitch-HP Switching Frequency
29	fSmin			120	kHz	LinkSwitch-HP Minimum Switching Frequency
30	fSmax			136	kHz	LinkSwitch-HP Maximum Switching Frequency
31	KP	0.40		0.40		Ripple to Peak Current Ratio (0.4 < KP < 6.0)
32	VOR	100.00		100.00	V	Reflected Output Voltage
33	Voltage Sense					
34	VUVON	100.00		100.00	V	Undervoltage turn on
35	VUVOFF			41.43	V	Undervoltage turn off
36	VOV			454.43	V	Overvoltage threshold
37	FMAX_FULL_LOAD			134.75	kHz	Maximum switching frequency at full load
38	FMIN_FULL_LOAD			118.90	kHz	Minimum switching frequency at full load
39	TSAMPLE_FULL_LOAD			3.58	µs	Minimum available Diode conduction time at full load. This should be greater than 2.5 us
40	TSAMPLE_LIGHT_LOAD			3.12	µs	Minimum available Diode conduction time at light load. This should be greater than 1.4 us
41	VDS			2.09	V	LinkSwitch-HP on-state Drain to Source Voltage.
42	VD			0.50	V	Output Winding Diode Forward Voltage Drop
43	VDB			0.70	V	Bias Winding Diode Forward Voltage Drop
44						
45						
46						
47	FEEDBACK SENSING SECTION					
48	RFB1			59.00	k-ohms	Feedback divider upper resistor
49	RFB2			9.09	k-ohms	Feedback divider lower resistor
50						



51						
52	ENTER TRANSFORMER CORE/CONSTRUCTION VARIABLES					
53	Select Core Size	Custom	Info	Custom		Manual Core Selected
54	Core			Custom		Selected Core
55	Custom Core	PQ26/20				Enter name of custom core is applicable
56	AE	1.21		1.21	cm^2	Core Effective Cross-Sectional Area
57	LE	4.50		4.50	cm	Core Effective Path Length
58	AL	5530		5530	nH/T^2	Ungapped Core Effective Inductance
59	BW	9.00		9.00	mm	Bobbin Physical Winding Width
60	M			0.00	mm	Safety Margin Width (Half the Primary to Secondary Creepage Distance)
61	L			2		Number of Primary Layers
62	NS	5		5		Number of Secondary Turns
63						
64						
65	DC INPUT VOLTAGE PARAMETERS					
66	VMIN			97	V	Minimum DC Input Voltage
67	VMAX			375	V	Maximum DC Input Voltage
68						
69						
70	CURRENT WAVEFORM SHAPE PARAMETERS					
71	DMAX			0.51		Maximum Duty Cycle
72	Iavg			0.83	A	Average Primary Current
73	IP			2.01	A	Peak Primary Current
74	IR			0.80	A	Primary Ripple Current
75	IRMS			1.17	A	Primary RMS Current
76						
77						
78	TRANSFORMER PRIMARY DESIGN PARAMETERS					
79	LP_TYP			519	μH	Typical Primary Inductance
80	LP_TOL	5		5	%	Primary inductance Tolerance
81	NP			40		Primary Winding Number of Turns
82	NB			6		Bias Winding Number of Turns
83	ALG			325	nH/T^2	Gapped Core Effective Inductance
84	BM			2159	Gauss	Maximum Flux Density at PO, VMIN (BM<3100)
85	BP			3279	Gauss	Peak Flux Density (BP<3700)
86	BAC			432	Gauss	AC Flux Density for Core Loss Curves (0.5 X Peak to Peak)
87	ur			1637		Relative Permeability of Ungapped Core
88	LG			0.44	mm	Gap Length (Lg > 0.1 mm)
89	BWE			18	mm	Effective Bobbin Width
90	OD			0.45	mm	Maximum Primary Wire Diameter including insulation
91	INS			0.06	mm	Estimated Total Insulation Thickness (= 2 * film thickness)
92	DIA			0.39	mm	Bare conductor diameter
93	AWG			27	AWG	Primary Wire Gauge (Rounded to next smaller standard AWG value)
94	CM			203	Cmils	Bare conductor effective area in circular mils
95	CMA		Warning	174	Cmils/Amp	!!! INCREASE (200 < CMA < 500) Increase L(primary layers),decrease NS,larger Core
96						
97						
98						
99	TRANSFORMER SECONDARY DESIGN PARAMETERS (SINGLE OUTPUT EQUIVALENT)					



100	Lumped parameters					
101	ISP			16.10	A	Peak Secondary Current
102	ISRMS			9.07	A	Secondary RMS Current
103	IO			6.00	A	Power Supply Output Current
104	IRIPPLE			6.81	A	Output Capacitor RMS Ripple Current
105	CMS			1815	Cmils	Secondary Bare Conductor minimum circular mils
106	AWGS			17	AWG	Secondary Wire Gauge (Rounded up to next larger standard AWG value)
107	DIAS			1.15	mm	Secondary Minimum Bare Conductor Diameter
108	ODS			1.80	mm	Secondary Maximum Outside Diameter for Triple Insulated Wire
109	INSS			0.32	mm	Maximum Secondary Insulation Wall Thickness
110						
111						
112	VOLTAGE STRESS PARAMETERS					
113	VDRAIN			605	V	Peak voltage across drain to source of Linkswitch-HP
114	PIVS			59	V	Output Rectifier Maximum Peak Inverse Voltage
115	PIVB			68	V	Bias Rectifier Maximum Peak Inverse Voltage
116						
117						
118	TRANSFORMER SECONDARY DESIGN PARAMETERS (MULTIPLE OUTPUTS)					
119	1st output					
120	VO1			12.00	V	Output Voltage
121	IO1			6.00	A	Output DC Current
122	PO1			72	W	Output Power
123	VD1			0.50	V	Output Diode Forward Voltage Drop
124	NS1			5.00		Output Winding Number of Turns
125	ISRMS1			9.073	A	Output Winding RMS Current
126	IRIPPLE1			6.81	A	Output Capacitor RMS Ripple Current
127	PIVS1			59	V	Output Rectifier Maximum Peak Inverse Voltage
128	CMS1			1815	Cmils	Output Winding Bare Conductor minimum circular mils
129	AWGS1			17	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
130	DIAS1			1.15	mm	Minimum Bare Conductor Diameter
131	ODS1			1.80	mm	Maximum Outside Diameter for Triple Insulated Wire
132						
133						
134	2nd output					
135	VO2			0.00	V	Output Voltage
136	IO2			0.00	A	Output DC Current
137	PO2			0	W	Output Power
138	VD2			0.70	V	Output Diode Forward Voltage Drop
139	NS2			1.00		Output Winding Number of Turns
140	ISRMS2			0	A	Output Winding RMS Current
141	IRIPPLE2			0.00	A	Output Capacitor RMS Ripple Current
142	PIVS2			9	V	Output Rectifier Maximum Peak Inverse Voltage
143	CMS2			0	Cmils	Output Winding Bare Conductor minimum circular mils
144	AWGS2			N/A	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
145	DIAS2			N/A	mm	Minimum Bare Conductor Diameter



146	ODS2			N/A	mm	Maximum Outside Diameter for Triple Insulated Wire
147						
148						
149	3rd output					
150	VO3			0.00	V	Output Voltage
151	IO3			0.00	A	Output DC Current
152	PO3			0	W	Output Power
153	VD3			0.70	V	Output Diode Forward Voltage Drop
154	NS3			1.00		Output Winding Number of Turns
155	ISRMS3			0	A	Output Winding RMS Current
156	IRIPPLE3			0.00	A	Output Capacitor RMS Ripple Current
157	PIVS3			9	V	Output Rectifier Maximum Peak Inverse Voltage
158	CMS3			0	Cmils	Output Winding Bare Conductor minimum circular mils
159	AWGS3			N/A	AWG	Wire Gauge (Rounded up to next larger standard AWG value)
160	DIAS3			N/A	mm	Minimum Bare Conductor Diameter
161	ODS3			N/A	mm	Maximum Outside Diameter for Triple Insulated Wire
162						
163	Total power			72	W	Total Power for Multi-output section
164						
165	Negative Output	N/A		N/A		If negative output exists enter Output number; e.g. If VO2 is negative output, select 2
166						
112	VOLTAGE STRESS PARAMETERS					

Table 10 – Design Spreadsheet.

Note:

- RFB2 used is 9.31 kΩ.
- PIExpert primary winding CMA 174 Cmils/A due to single AWG 27 wire. Actual transformer winding design is 3 x AWG 30 wire with CMA of 257.36 which is within CMA specification ($200 < \text{CMA} < 500$).

10 Heat Sinks

10.1 LinkSwitch-HP Heat Sink

10.1.1 LinkSwitch-HP Heat Sink Metal Drawing

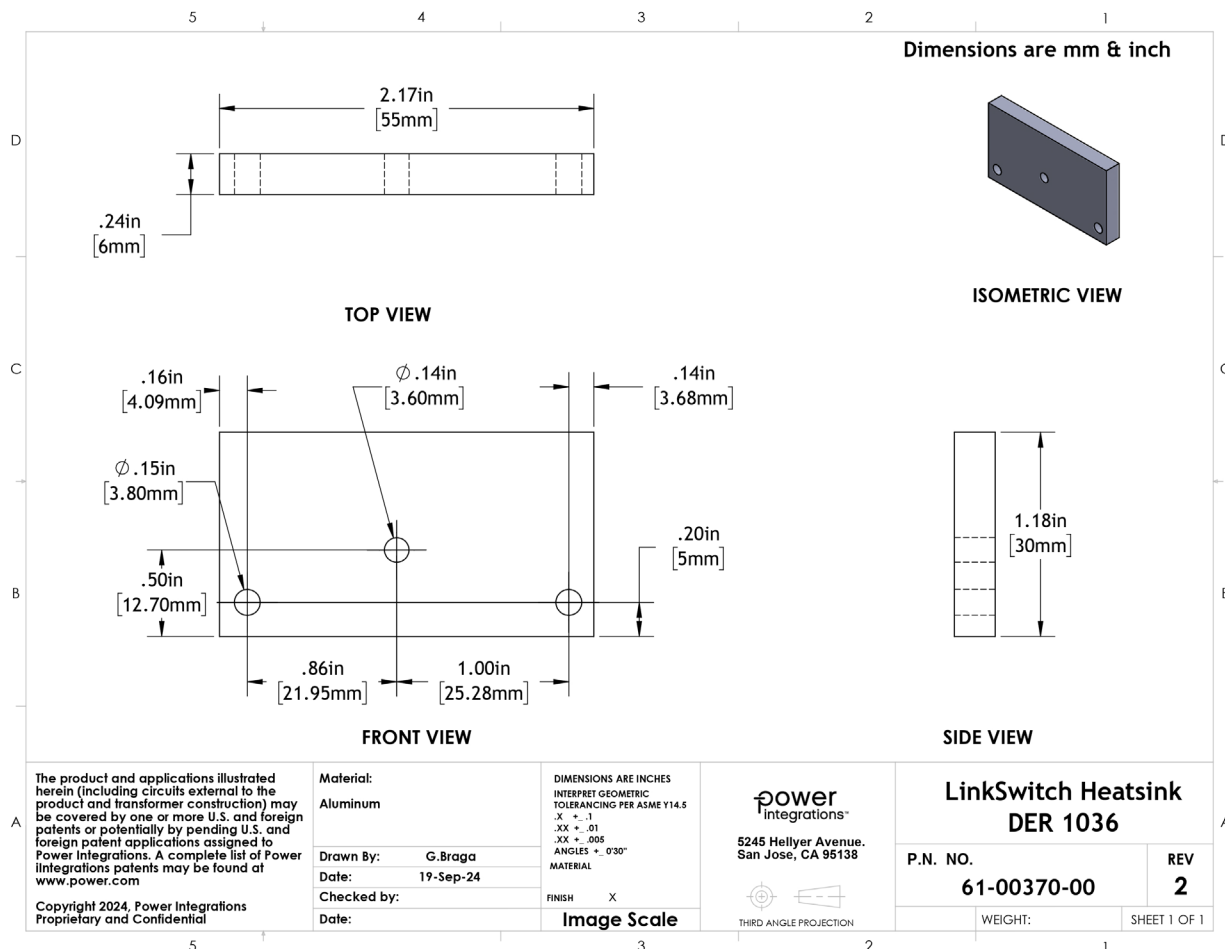


Figure 10 – DER-1036 LinkSwitch-HP Heat Sink Metal Drawing.

10.1.2 Finished LinkSwitch-HP Heat Sink with Hardware

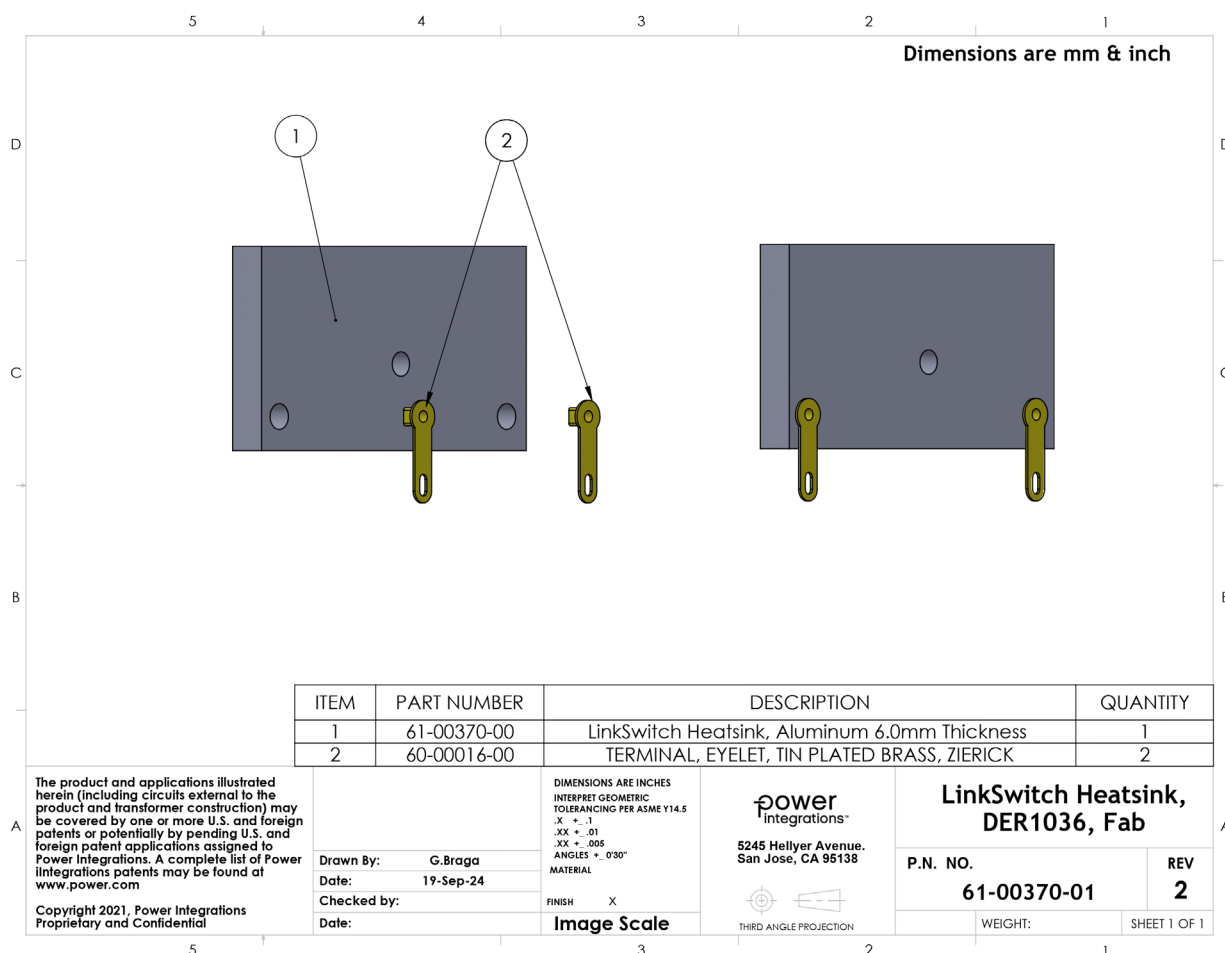


Figure 11 – DER-1036 LinkSwitch-HP Heat Sink with Hardware.

10.1.3 LinkSwitch-HP Heat Sink Assembly

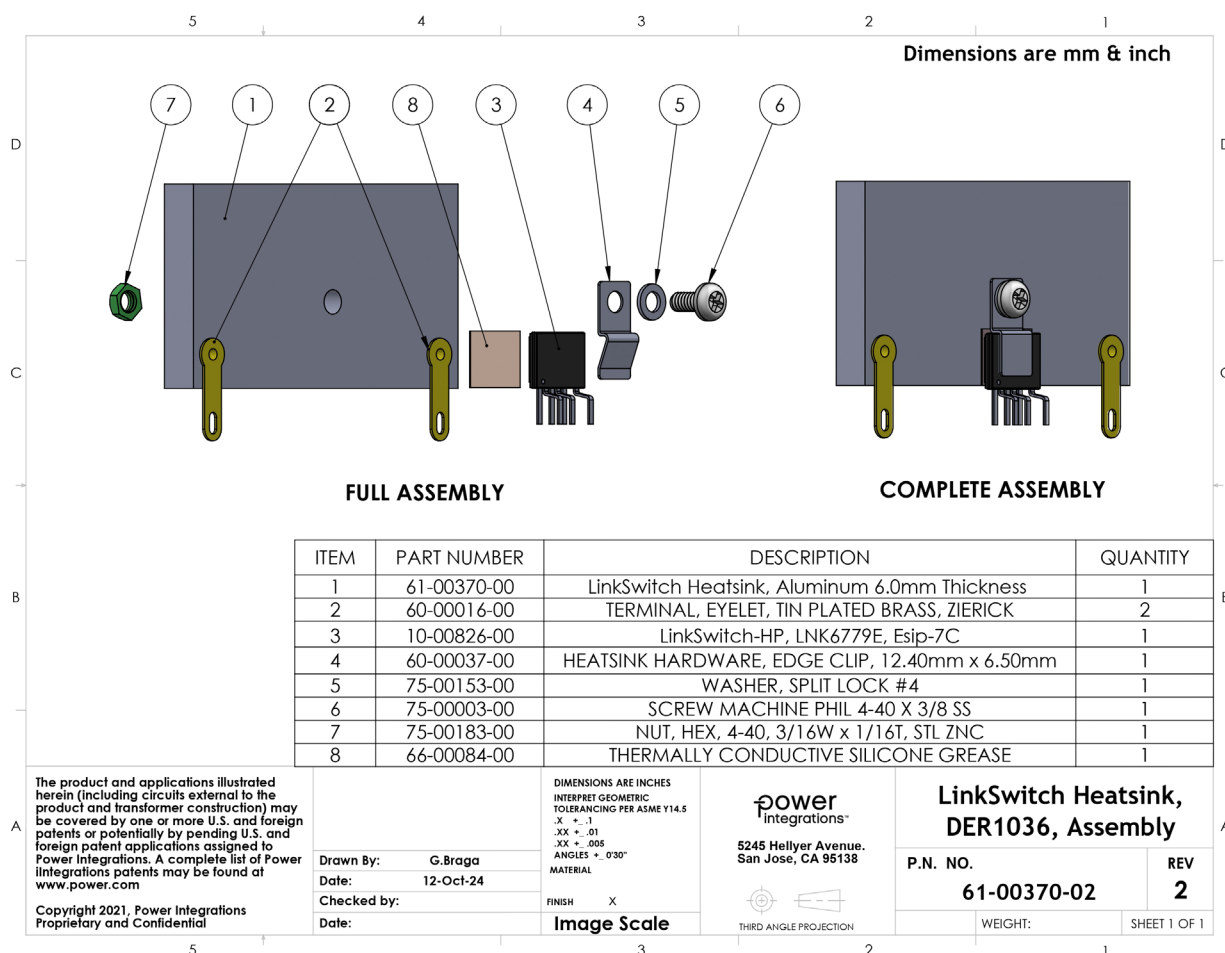


Figure 12 – DER-1036 LinkSwitch-HP Heat Sink Assembly.

10.2 Bridge Rectifier Heat Sink

10.2.1 Bridge Rectifier Heat Sink Metal Drawing

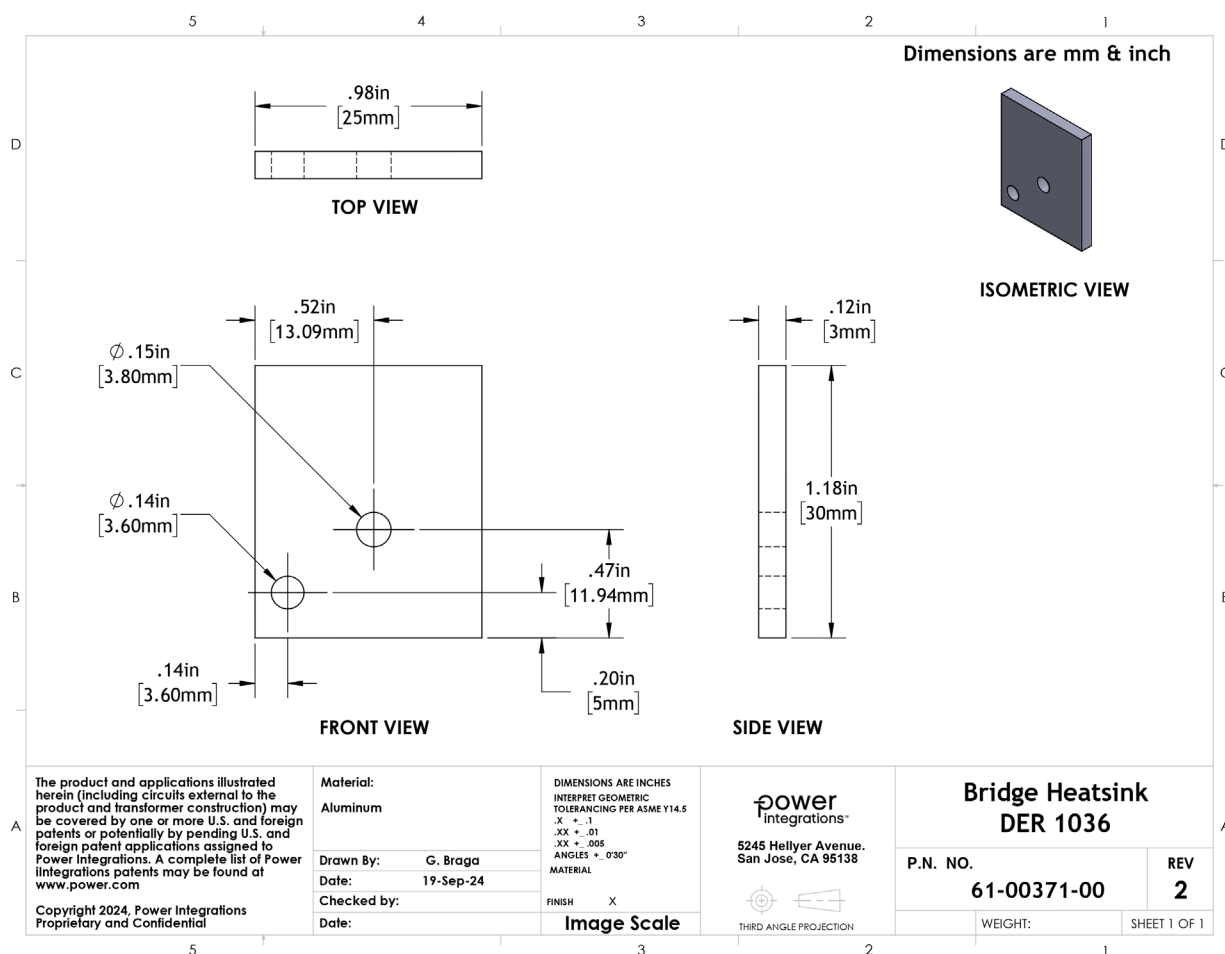


Figure 13 – DER-1036 Bridge Rectifier Heat Sink Metal Drawing.

10.2.2 Finished Bridge Rectifier Heat Sink with Hardware

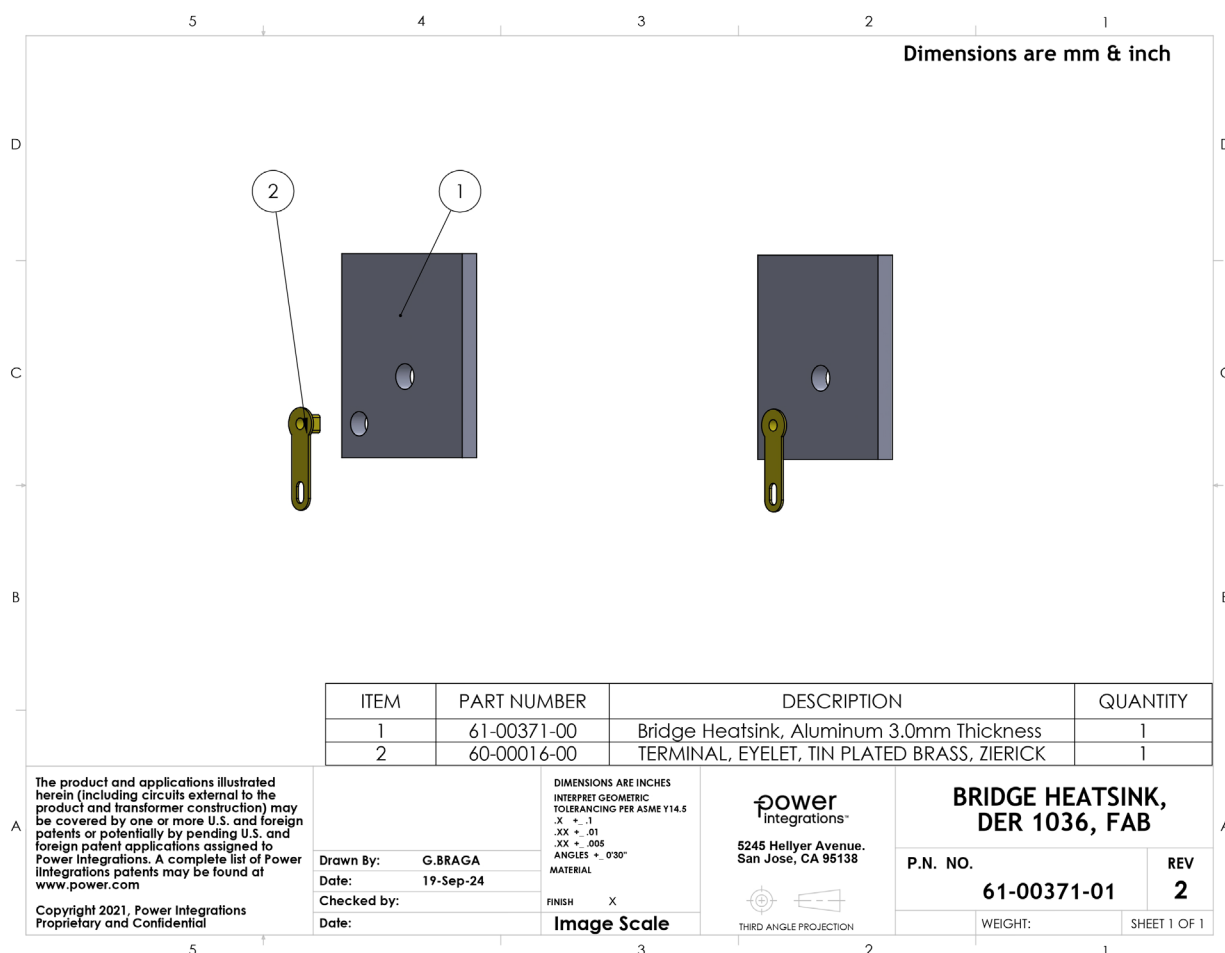


Figure 14 – DER-1036 Bridge Rectifier Heat Sink with Hardware.

10.2.3 Bridge Rectifier Heat Sink Assembly

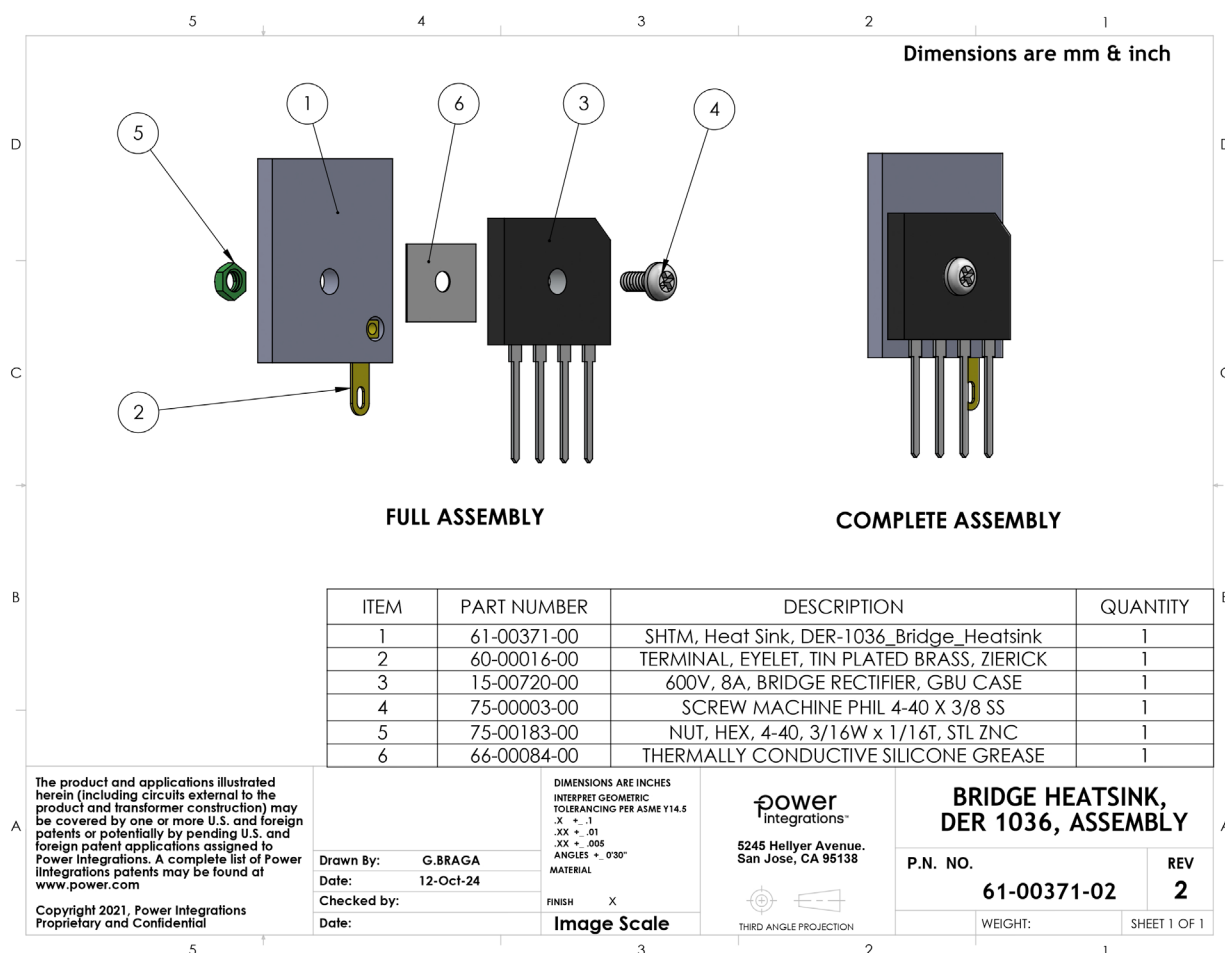


Figure 15 – DER-1036 Bridge Rectifier Heat Sink Assembly.

10.3 Secondary Diode Heat Sink

10.3.1 Secondary Diode Heat Sink Metal Drawing

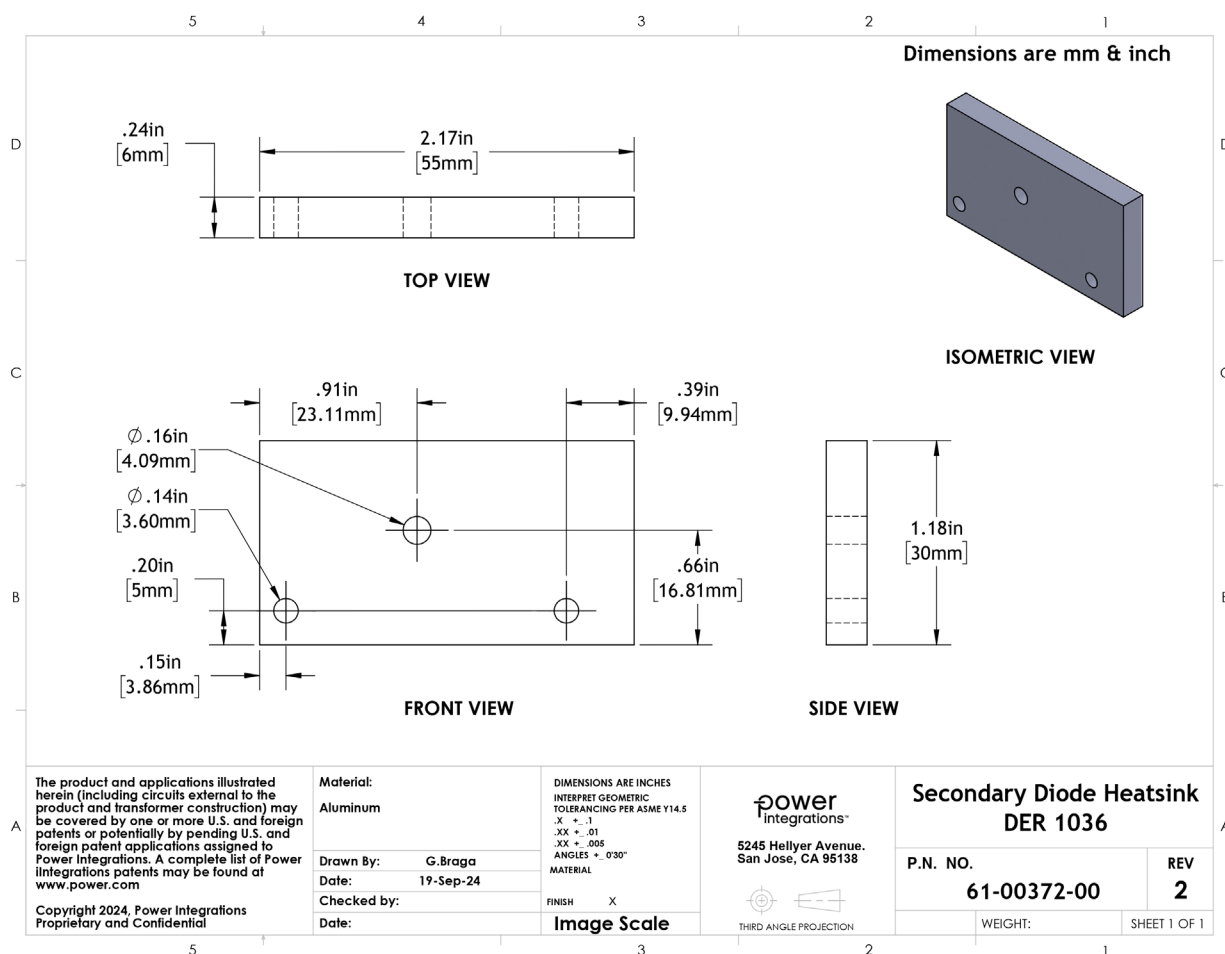


Figure 16 – DER-1036 Secondary Diode Heat Sink Metal Drawing.

10.3.2 Finished Secondary Diode Heat Sink with Hardware

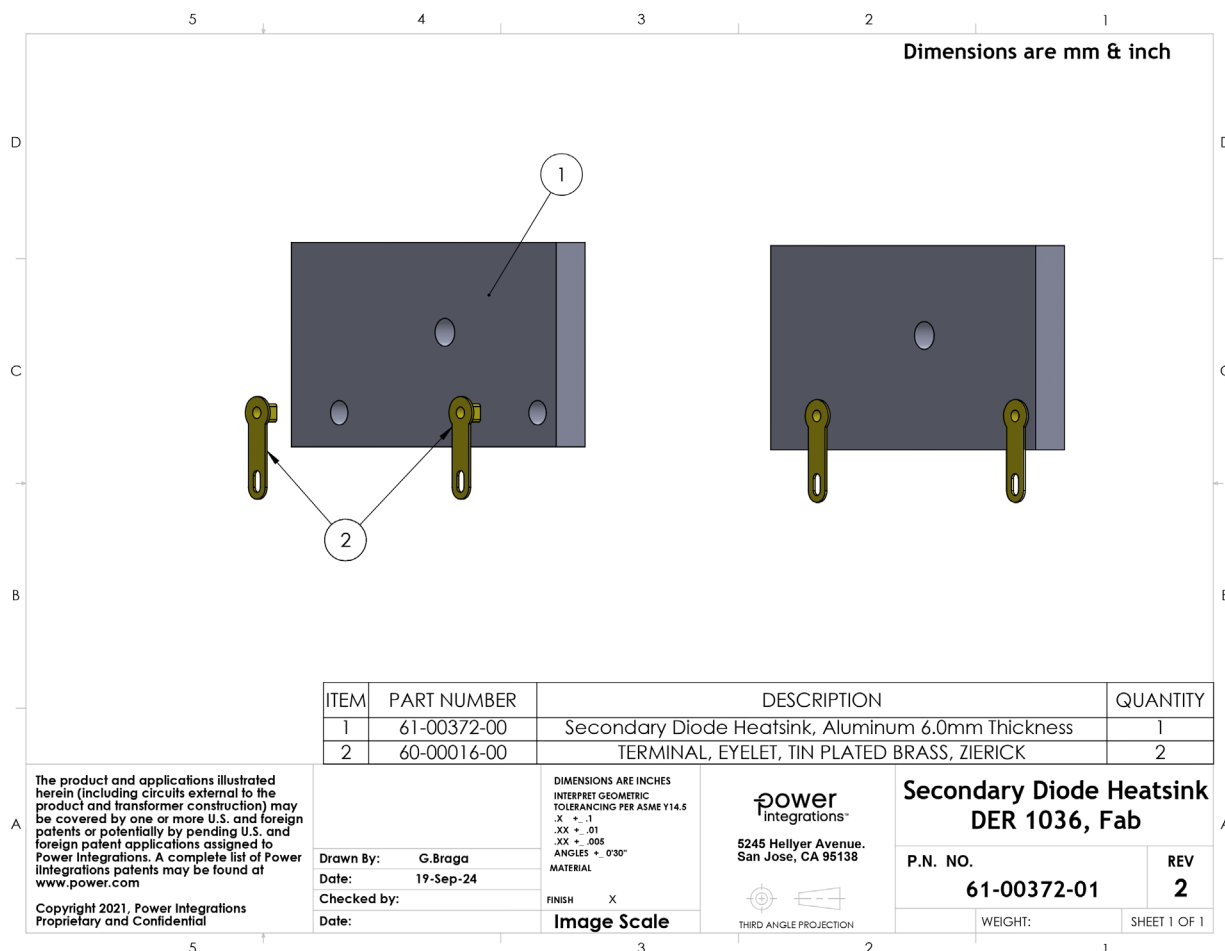


Figure 17 – DER-1036 Secondary Diode Heat Sink with Hardware.

10.3.3 Secondary Diode Heat Sink Assembly

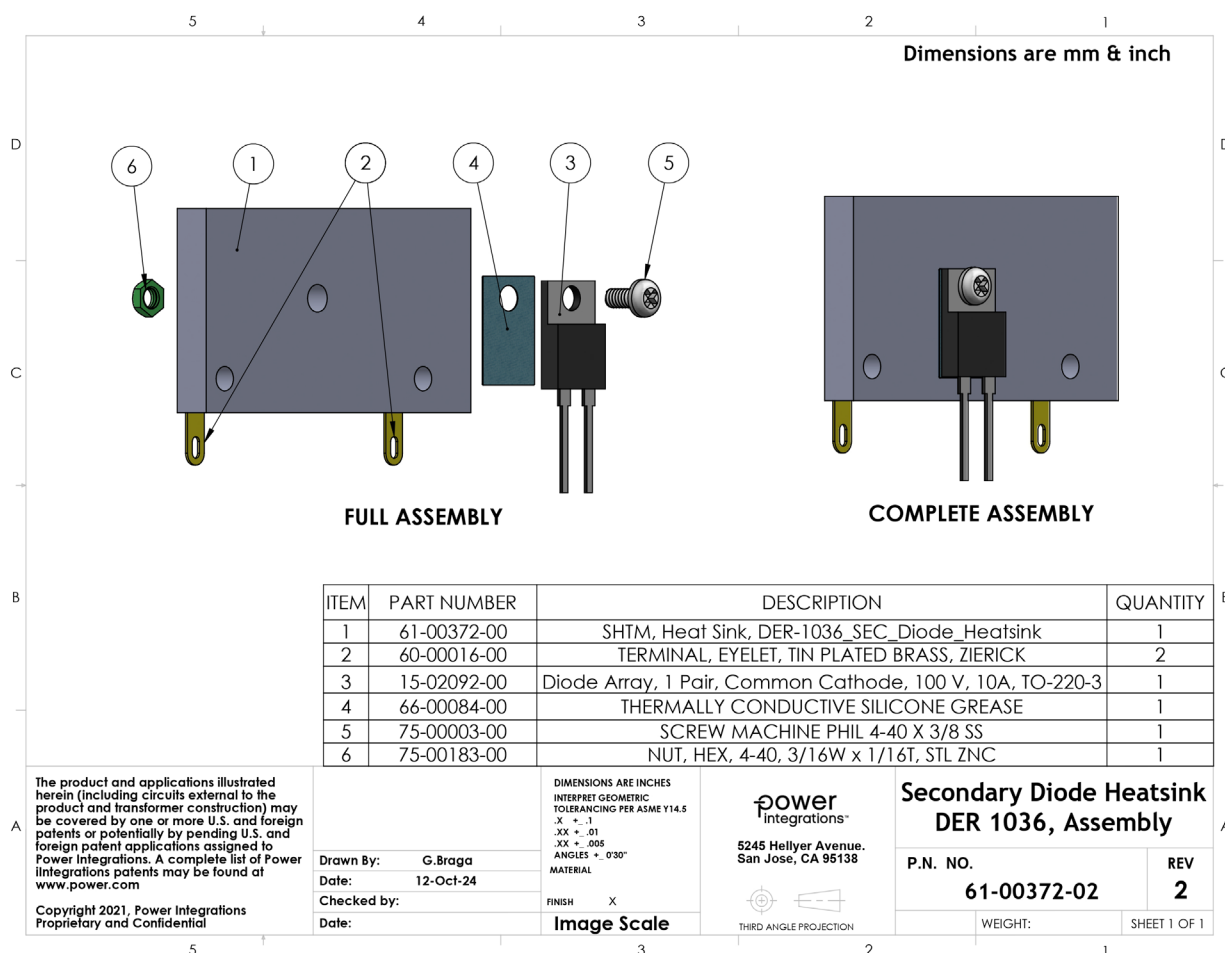


Figure 18 – DER-1036 Secondary Diode Heat Sink Assembly.

11 Performance Data

11.1 Full Load Efficiency vs. Line

Test Condition: Soak for 15 minutes for each line.

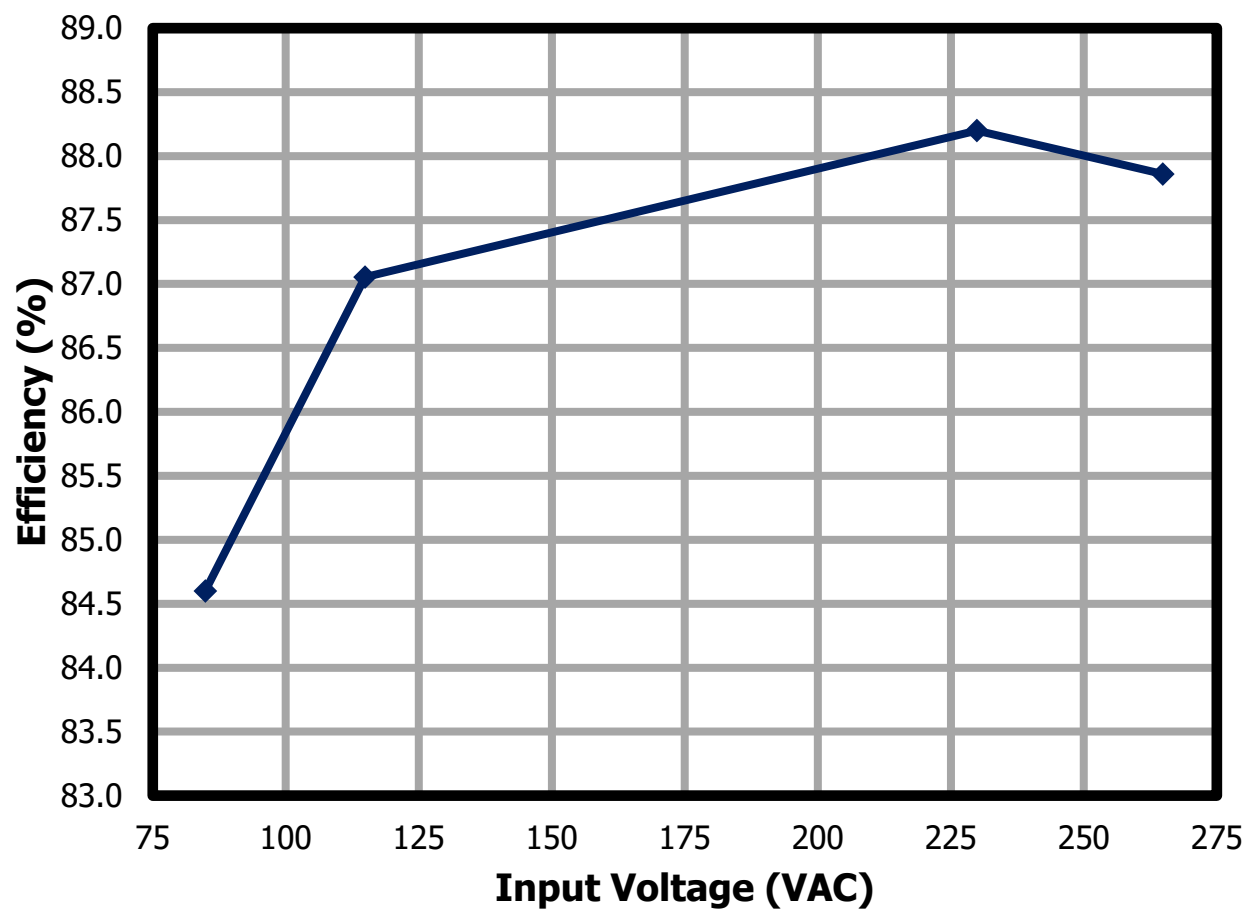


Figure 19 – Efficiency vs. Input Voltage.

11.2 Efficiency vs. Load

Test Condition: Soak for 15 minutes each line at full load, and 10 seconds for each load.

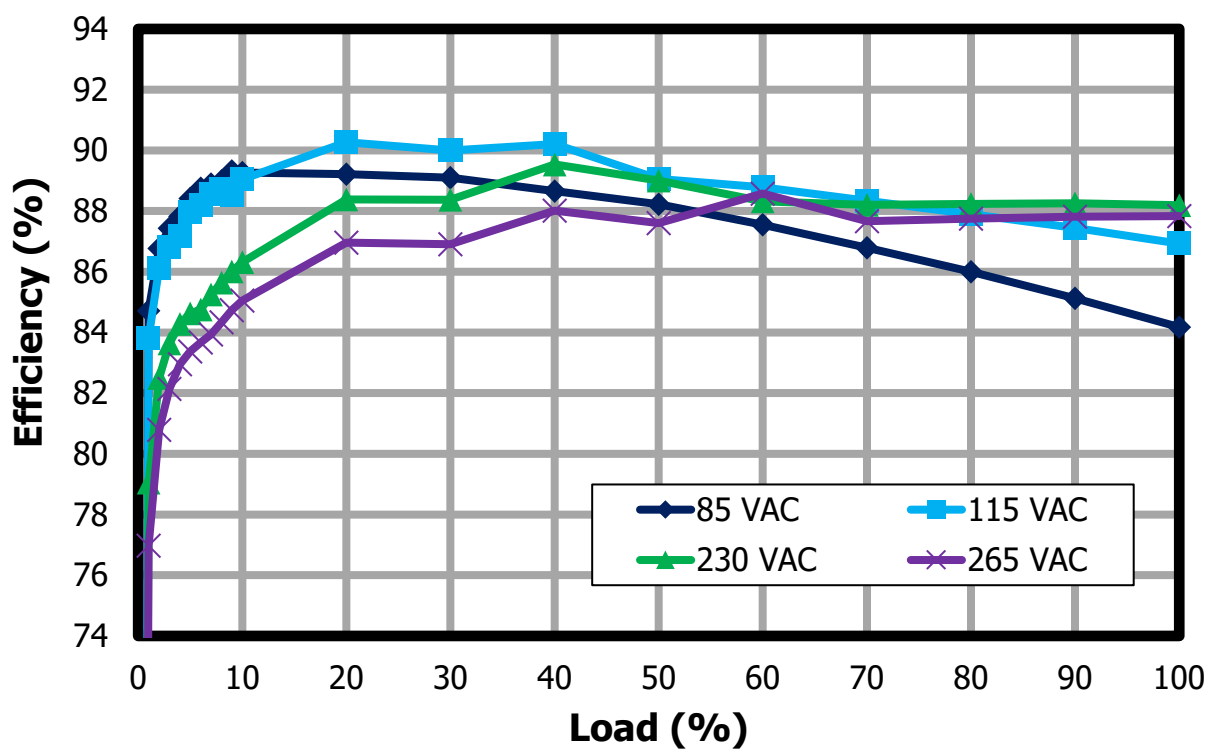


Figure 20 – Efficiency vs. Percentage Load.

11.3 Average and 10% Efficiency

11.3.1 Average and 10% Efficiency at 115 VAC

Load	P _{IN}	V _{OUT} at PCB	I _{OUT}	P _{OUT}	Efficiency at PCB	Average Efficiency	DOE6 Limit
(A)	(W)	(VDC)	(mA _{DC})	(W)	(%)	(%)	(%)
100%	81.3	11.8	6000	70.8	87.1	88.7	88
75%	60.5	11.9	4500	53.4	88.2		
50%	40.4	12	3000	35.9	89.0		
25%	20.0	12.1	1500	18.1	90.3		
10%	8.20	12.2	600	7.31	89.1	---	---

Table 11 – Average and 10% Efficiency at 115 VAC.

11.3.2 Average and 10% Efficiency at 230 VAC

Load	P _{IN}	V _{OUT} at PCB	I _{OUT}	P _{OUT}	Efficiency at PCB	Average Efficiency	DOE6 Limit
(A)	(W)	(VDC)	(mA _{DC})	(W)	(%)	(%)	(%)
100%	80.2	11.8	6000	70.8	88.3	88.6	88
75%	60.5	11.9	4500	53.4	88.2		
50%	40.2	11.9	3000	35.8	89		
25%	20.2	12.0	1500	18.0	89.1		
10%	8.43	12.1	600	7.28	86.4	---	---

Table 12 – Average and 10% Efficiency at 230 VAC.

11.4 No-Load Input Power

Test Condition: Soak for 15 minutes each line and 1 minute integration time.

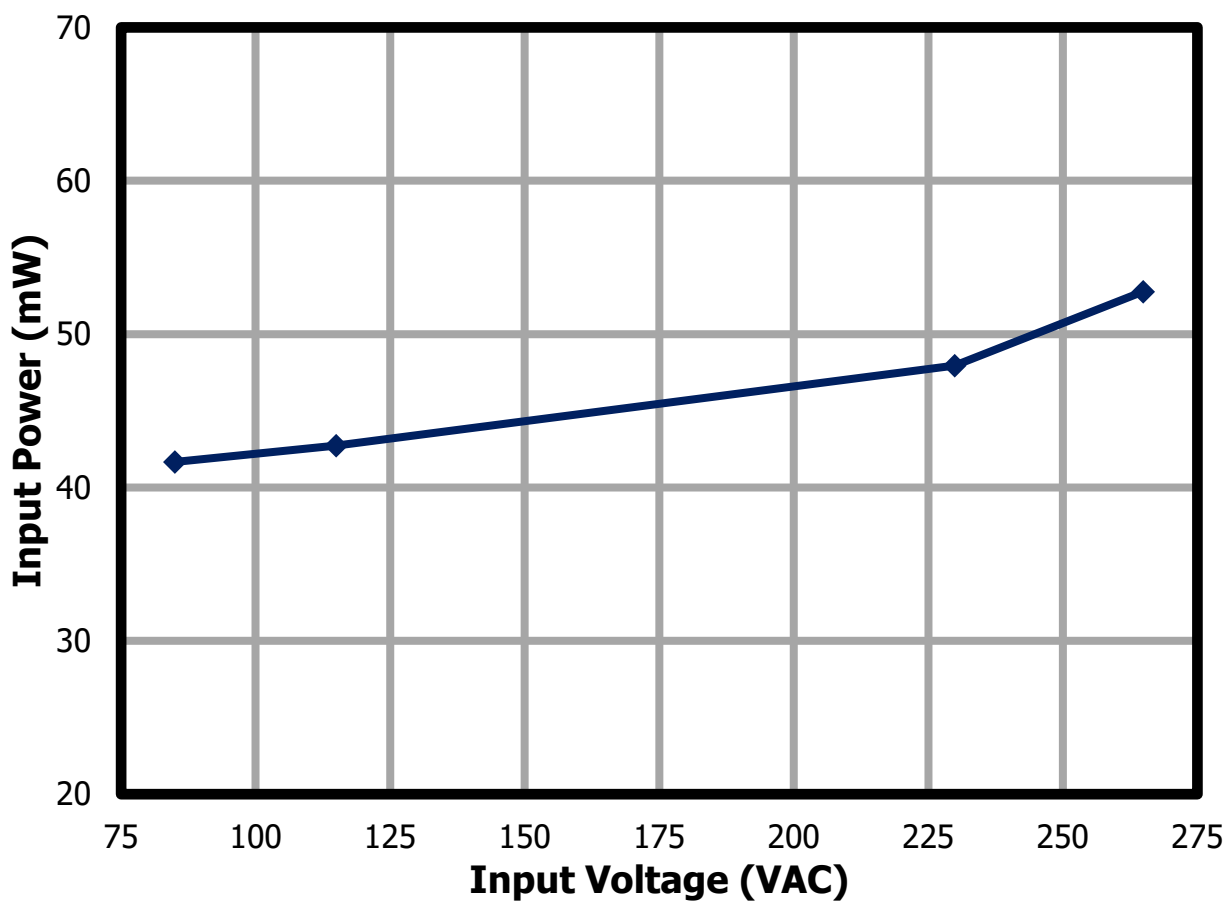


Figure 21 – No-Load Input Power vs. Line at Room Temperature.

11.5 Line Regulation

Test Condition: Soak for 15 minutes for each line.

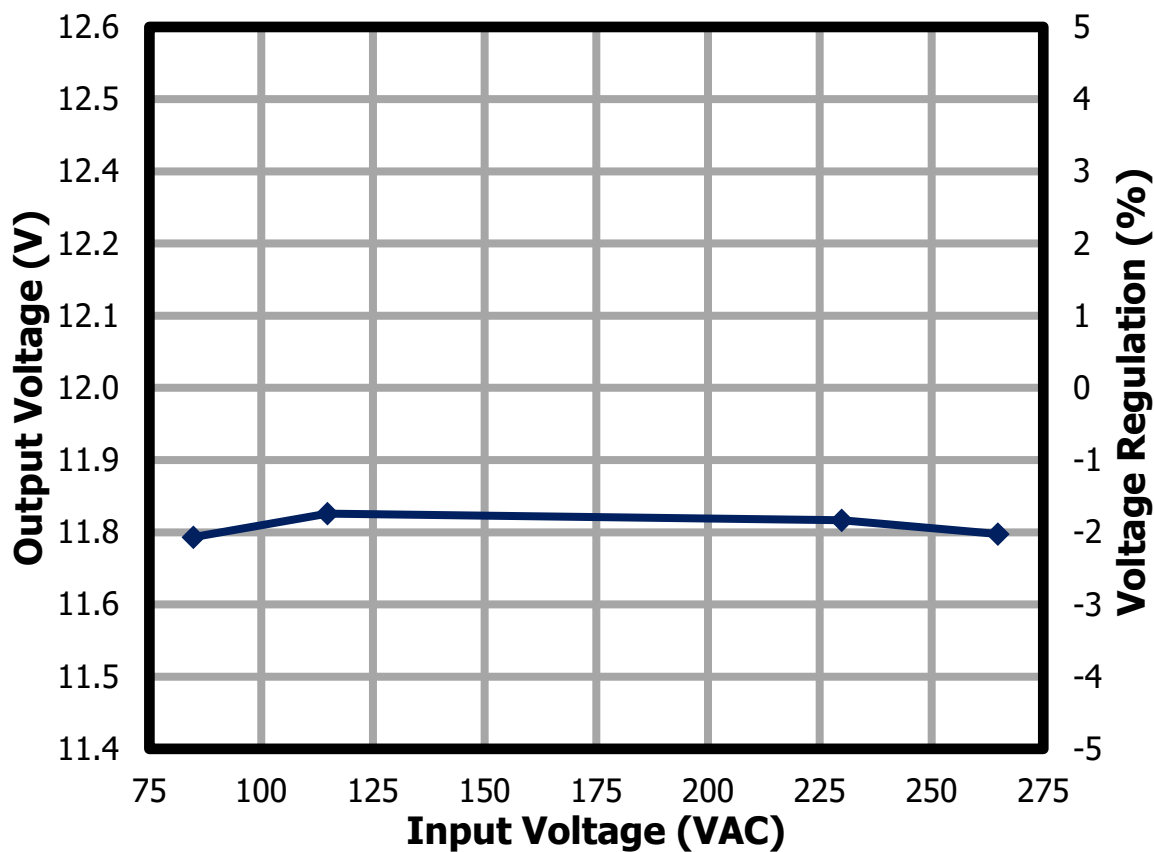


Figure 22 – Output Voltage vs. Line Voltage.

11.6 Load Regulation

Test Condition: Soak for 15 minutes each line at full load, and 10 seconds for each load.

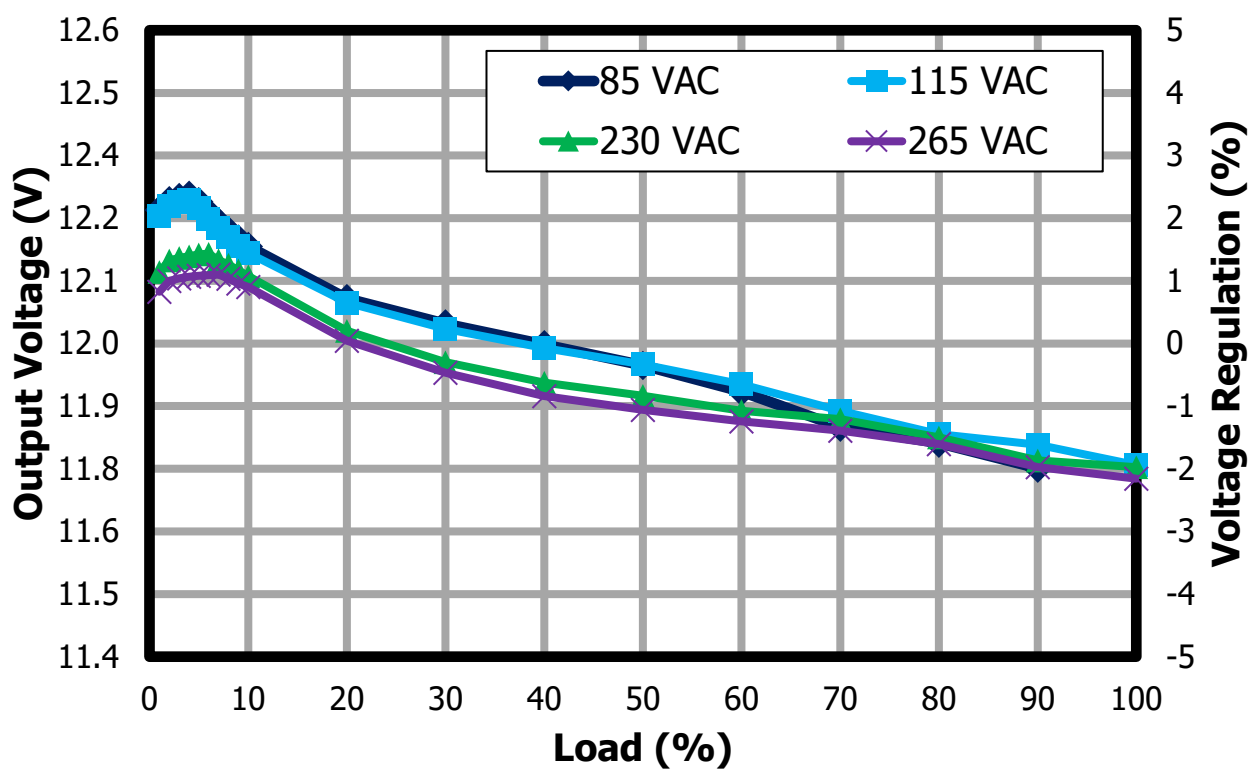


Figure 23 – Output Voltage vs. Percent Load.

12 Waveforms

12.1 Load Transient Response

Test Condition: Dynamic load frequency = 33.3 Hz, Duty cycle = 50 %
Slew Rate = 0.8 A / μ s

12.1.1 Transient 10% - 100% Load Change

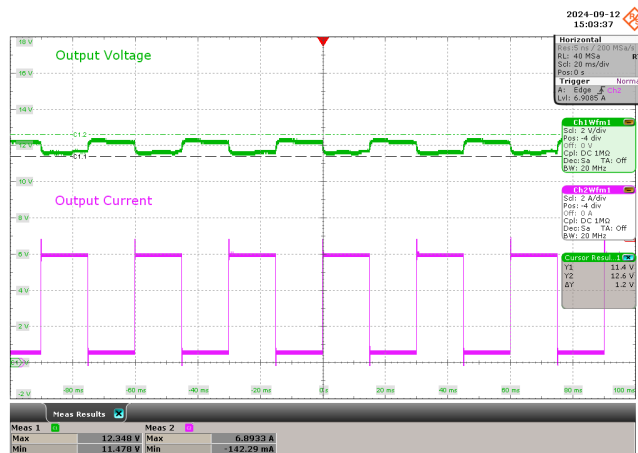


Figure 24 – 85 VAC 60 Hz.

CH1: Output Voltage, 2 V / div., 20 ms / div.

CH2: Output Current, 2 A / div., 20 ms / div.

V_{OUT}: V_{MAX}: 12.3 V

V_{MIN}: 11.5 V

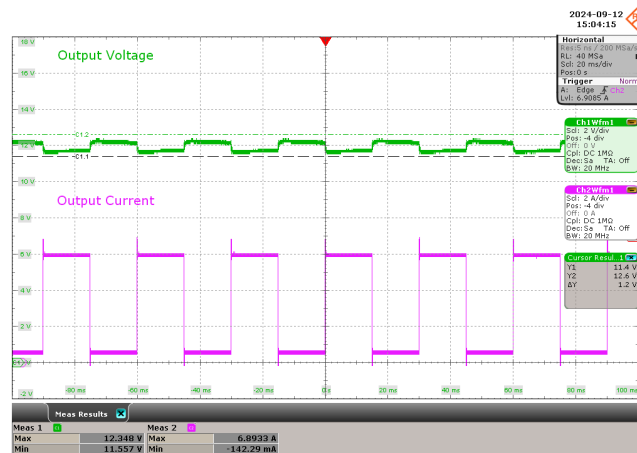


Figure 25 – 115 VAC 60 Hz.

CH1: Output Voltage, 2 V / div., 20 ms / div.

CH2: Output Current, 2 A / div., 20 ms / div.

V_{OUT}: V_{MAX}: 12.3 V

V_{MIN}: 11.6 V

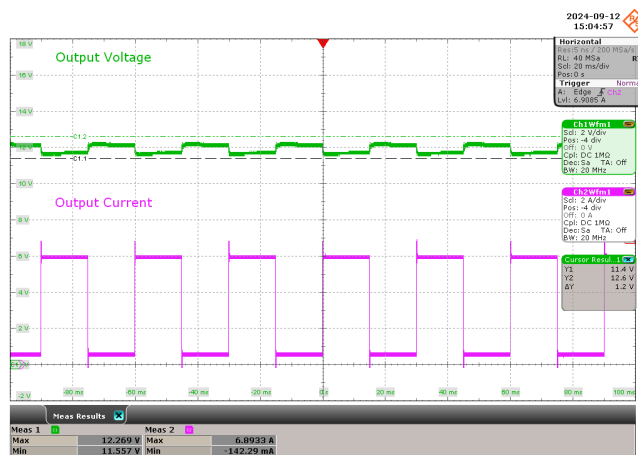


Figure 26 – 230 VAC 50 Hz.

CH1: Output Voltage, 2 V / div., 20 ms / div.

CH2: Output Current, 2 A / div., 20 ms / div.

V_{OUT}: V_{MAX}: 12.3 V

V_{MIN}: 11.6 V

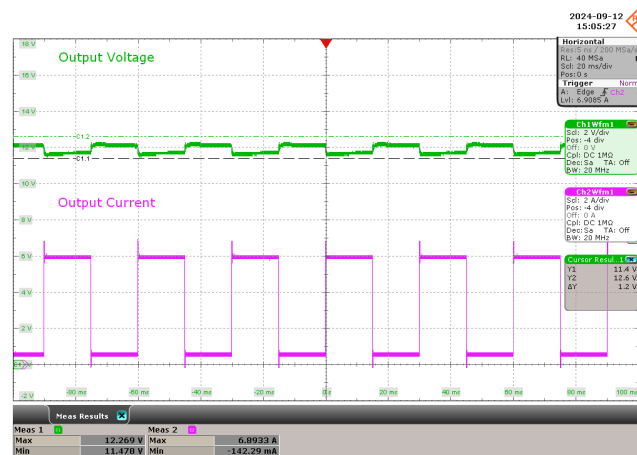


Figure 27 – 265 VAC 50 Hz.

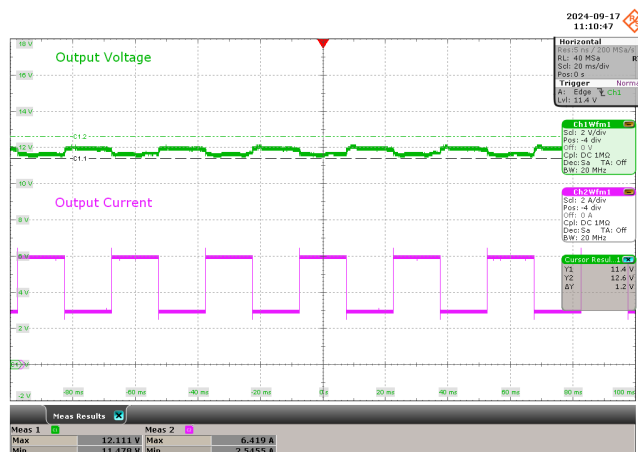
CH1: Output Voltage, 2 V / div., 20 ms / div.

CH2: Output Current, 2 A / div., 20 ms / div.

V_{OUT}: V_{MAX}: 12.3 V

V_{MIN}: 11.5 V

12.1.2 Transient 50% - 100% Load Change



12.2 Output Start-up

12.2.1 Full Load CC Mode

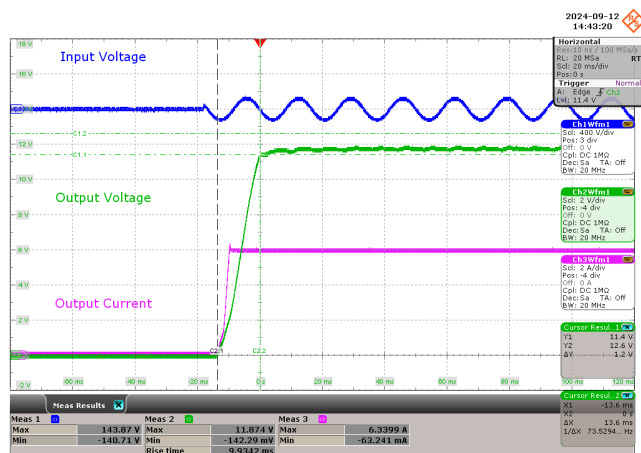


Figure 32 – 85 VAC 60 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.

CH2: Output Voltage, 2 V / div., 20 ms / div.

CH3: Output Current, 2 A / div., 20 ms / div.

Rise Time = 13.6 ms.

V_{MAX} = 11.9 V

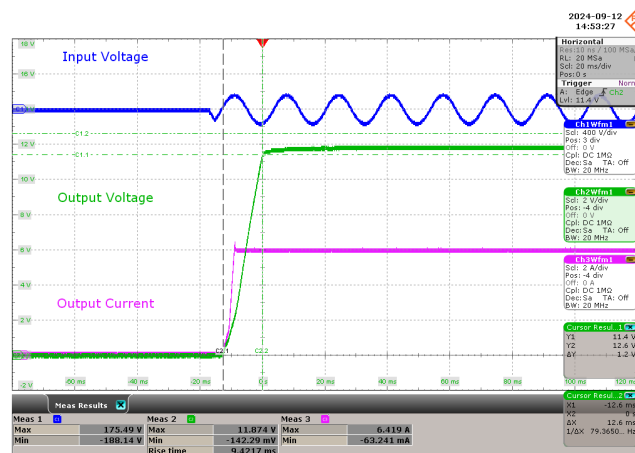


Figure 33 – 115 VAC 60 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.

CH2: Output Voltage, 2 V / div., 20 ms / div.

CH3: Output Current, 2 A / div., 20 ms / div.

Rise Time = 12.6 ms.

V_{MAX} = 11.9 V

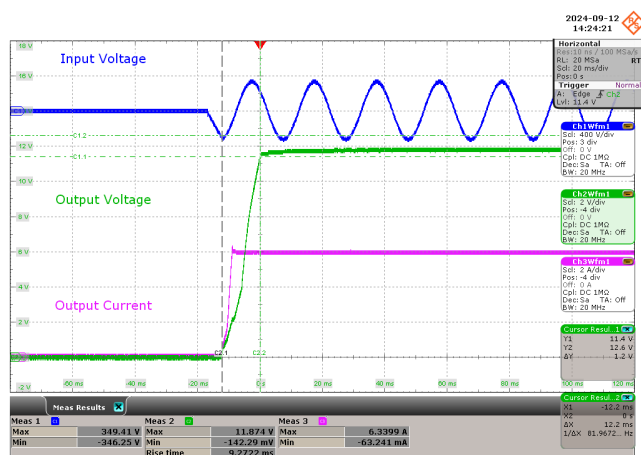


Figure 34 – 230 VAC 50 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.

CH2: Output Voltage, 2 V / div., 20 ms / div.

CH3: Output Current, 2 A / div., 20 ms / div.

Rise Time = 12.2 ms.

V_{MAX} = 11.9 V

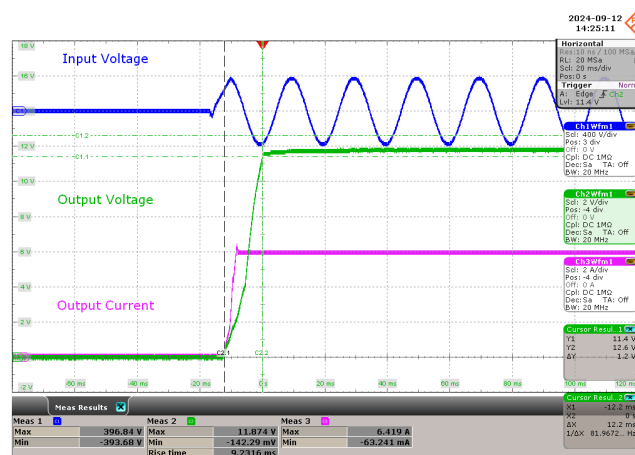


Figure 35 – 265 VAC 50 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.

CH2: Output Voltage, 2 V / div., 20 ms / div.

CH3: Output Current, 2 A / div., 20 ms / div.

Rise Time = 12.2 ms.

V_{MAX} = 11.9 V

12.2.3 No Load

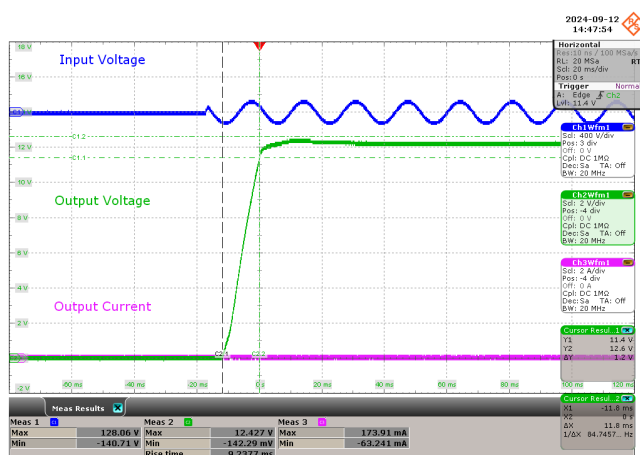


Figure 40 – 85 VAC 60 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.
 CH2: Output Voltage, 2 V / div., 20 ms / div.
 CH3: Output Current, 2 A / div., 20 ms / div.
 Rise Time = 11.8 ms.
 $V_{MAX} = 12.4 V$

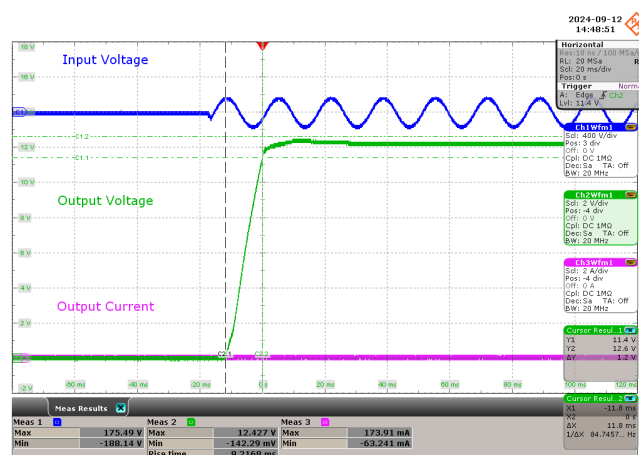


Figure 41 – 115 VAC 60 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.
 CH2: Output Voltage, 2 V / div., 20 ms / div.
 CH3: Output Current, 2 A / div., 20 ms / div.
 Rise Time = 11.8 ms.
 $V_{MAX} = 12.4 V$

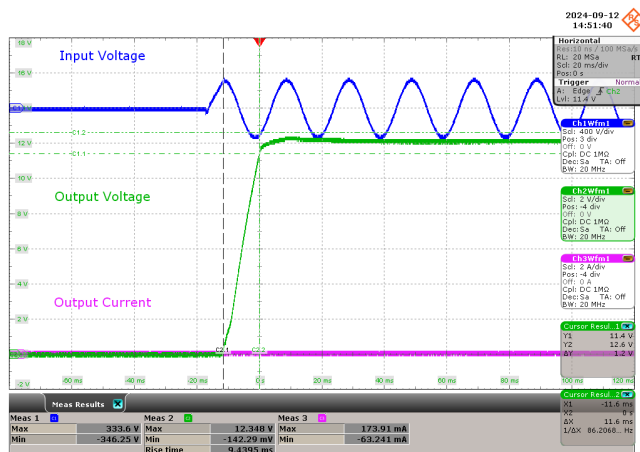


Figure 42 – 230 VAC 50 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.
 CH2: Output Voltage, 2 V / div., 20 ms / div.
 CH3: Output Current, 2 A / div., 20 ms / div.
 Rise Time = 11.6 ms.
 $V_{MAX} = 12.3 V$

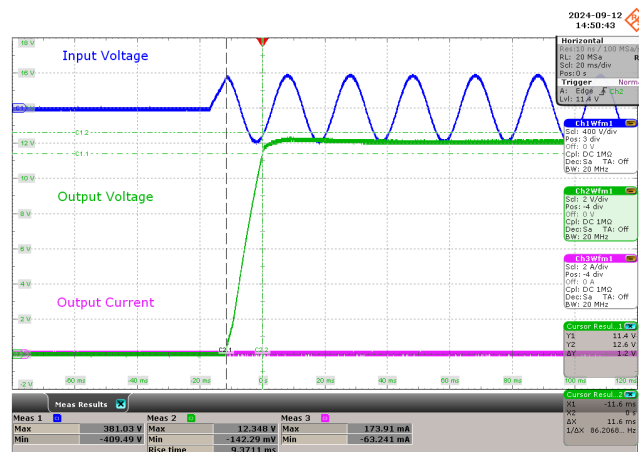


Figure 43 – 265 VAC 50 Hz.

CH1: Input Voltage, 400 V / div., 20 ms / div.
 CH2: Output Voltage, 2 V / div., 20 ms / div.
 CH3: Output Current, 2 A / div., 20 ms / div.
 Rise Time = 11.6 ms.
 $V_{MAX} = 12.3 V$

12.3 Switching Waveforms

12.3.1 Primary MOSFET Drain-Source Voltage and Current at Normal Operation

12.3.1.1 Full Load

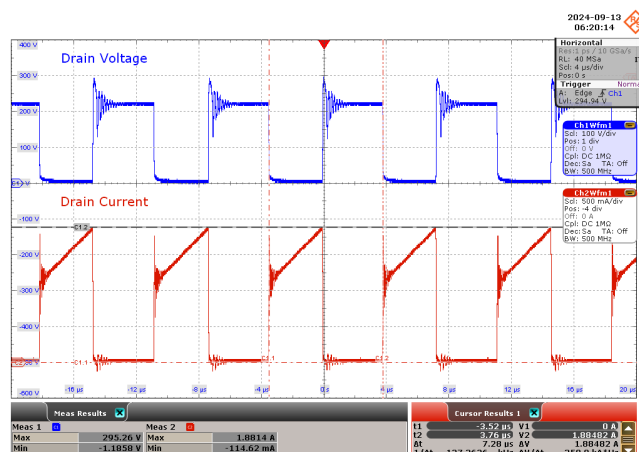


Figure 44 – 85 VAC 60 Hz.

CH1: Drain Voltage, 100 V / div., 4 μ s / div.
 CH2: Drain Current, 500 mA / div., 4 μ s / div.
 Drain Voltage_(MAX) = 295 V
 Drain Current_(MAX) = 1.88 A

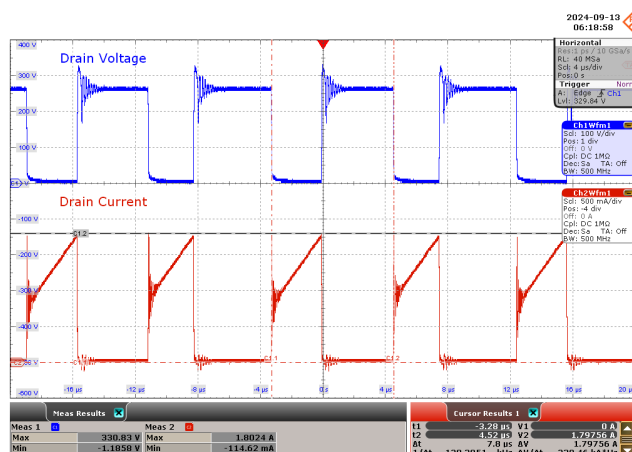


Figure 45 – 115 VAC 60 Hz.

CH1: Drain Voltage, 100 V / div., 4 μ s / div.
 CH2: Drain Current, 500 mA / div., 4 μ s / div.
 Drain Voltage_(MAX) = 331 V
 Drain Current_(MAX) = 1.8 A

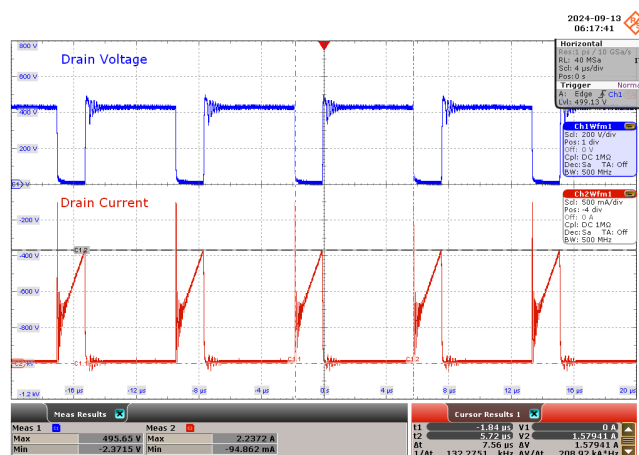


Figure 46 – 230 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 4 μ s / div.
 CH2: Drain Current, 500 mA / div., 4 μ s / div.
 Drain Voltage_(MAX) = 496 V
 Drain Current_(MAX) = 2.24 A

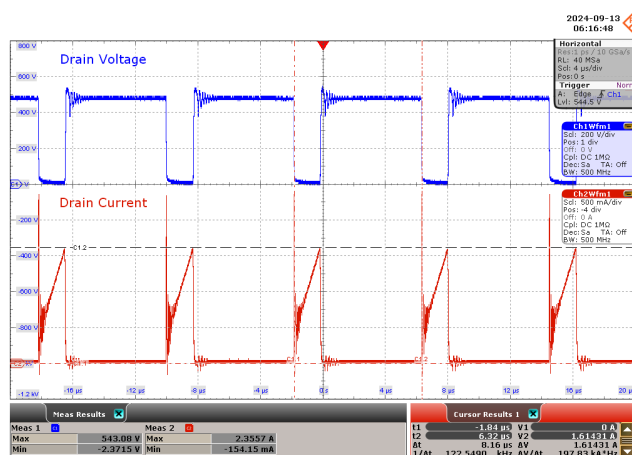
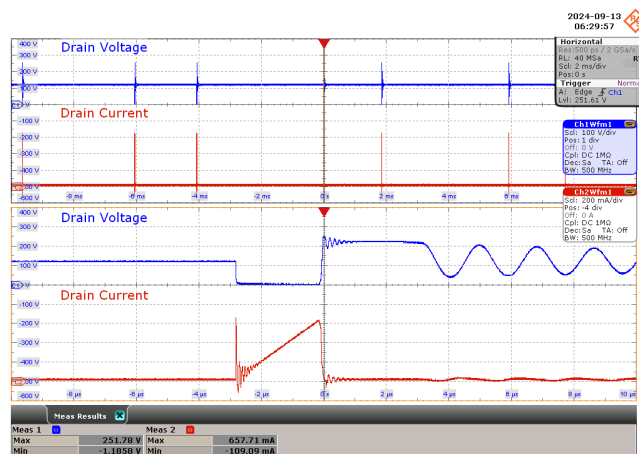


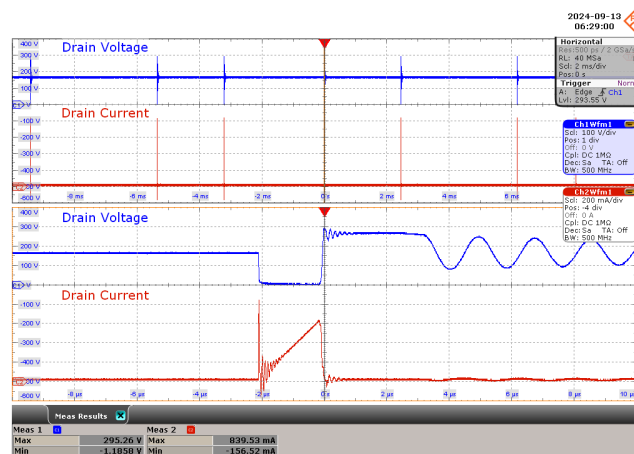
Figure 47 – 265 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 4 μ s / div.
 CH2: Drain Current, 500 mA / div., 4 μ s / div.
 Drain Voltage_(MAX) = 543 V
 Drain Current_(MAX) = 2.36 A

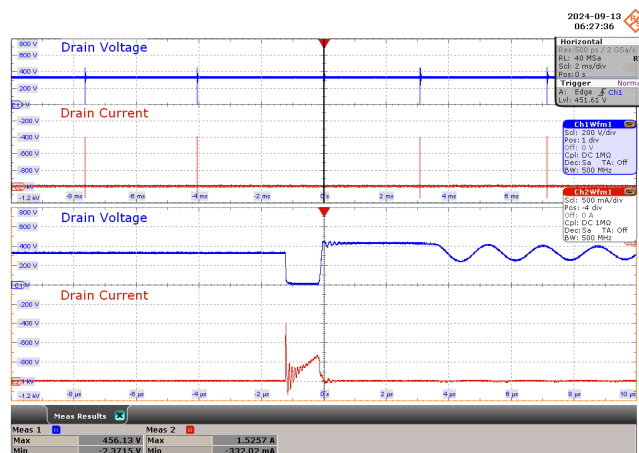
12.3.1.2 No Load

**Figure 48** – 85 VAC 60 Hz.

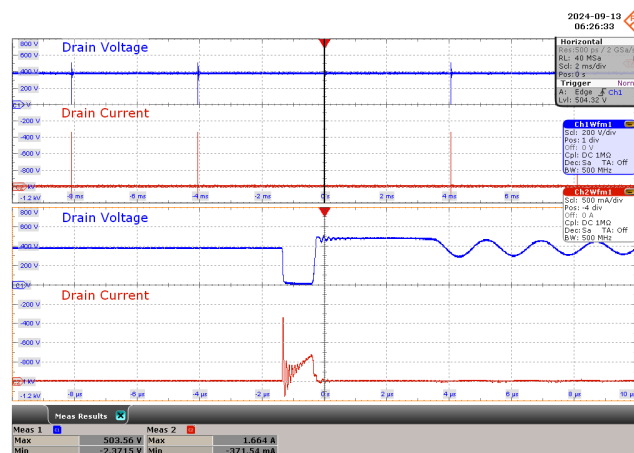
CH1: Drain Voltage, 100 V / div., 2 ms / div.
CH2: Drain Current, 200 mA / div., 2 ms / div.
Zoom: 2 μs / div.
Drain Voltage_(MAX) = 252 V
Drain Current_(MAX) = 658 mA

**Figure 49** – 115 VAC 60 Hz.

CH1: Drain Voltage, 100 V / div., 2 ms / div.
CH2: Drain Current, 200 mA / div., 2 ms / div.
Zoom: 2 μs / div.
Drain Voltage_(MAX) = 295 V
Drain Current_(MAX) = 840 mA

**Figure 50** – 230 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 2 ms / div.
CH2: Drain Current, 500 mA / div., 2 ms / div.
Zoom: 2 μs / div.
Drain Voltage_(MAX) = 456 V
Drain Current_(MAX) = 1.53 A

**Figure 51** – 265 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 2 ms / div.
CH2: Drain Current, 500 mA / div., 2 ms / div.
Zoom: 2 μs / div.
Drain Voltage_(MAX) = 504 V
Drain Current_(MAX) = 1.66 A

12.3.2 Primary MOSFET Drain-Source Voltage and Current at Start-up Operation

12.3.2.1 Full Load

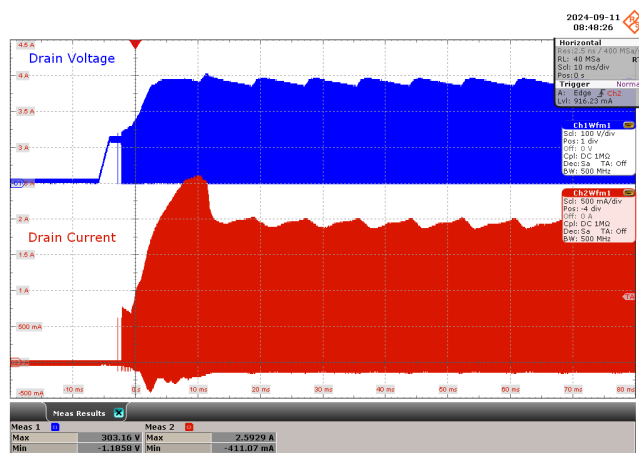


Figure 52 – 85 VAC 60 Hz.

CH1: Drain Voltage, 100 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 303 V
 Drain Current_(MAX) = 2.59 A

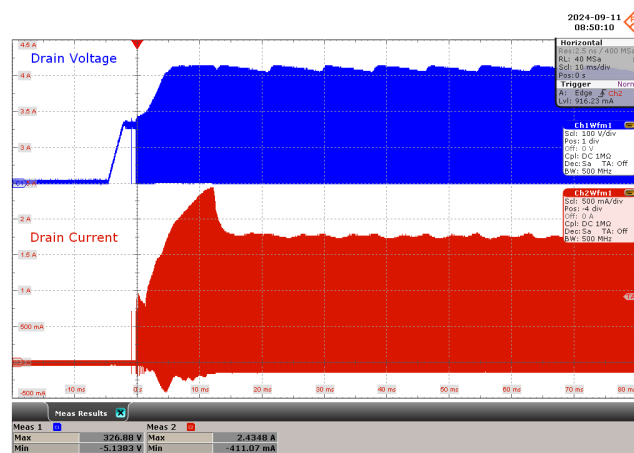


Figure 53 – 115 VAC 60 Hz.

CH1: Drain Voltage, 100 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 327 V
 Drain Current_(MAX) = 2.43 A

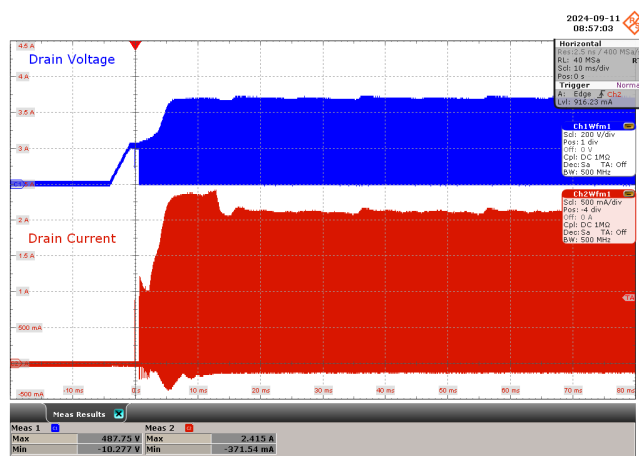


Figure 54 – 230 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 488 V
 Drain Current_(MAX) = 2.41 A

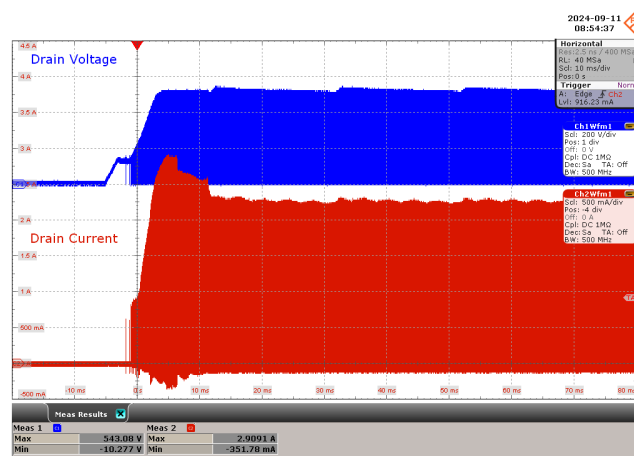
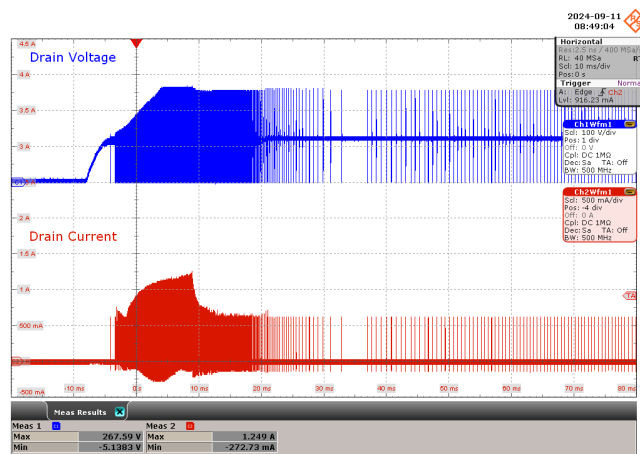


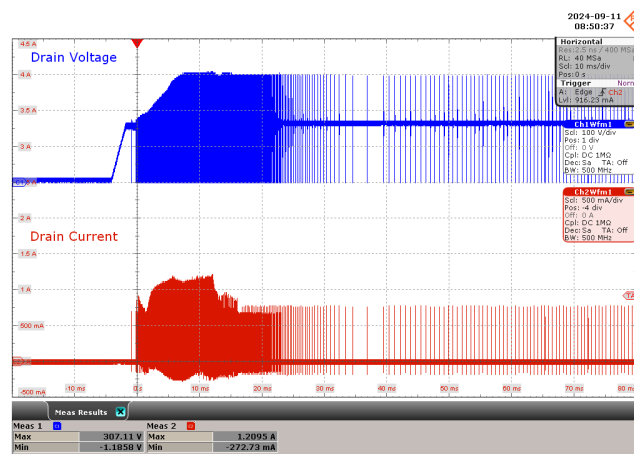
Figure 55 – 265 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 543 V
 Drain Current_(MAX) = 2.91 A

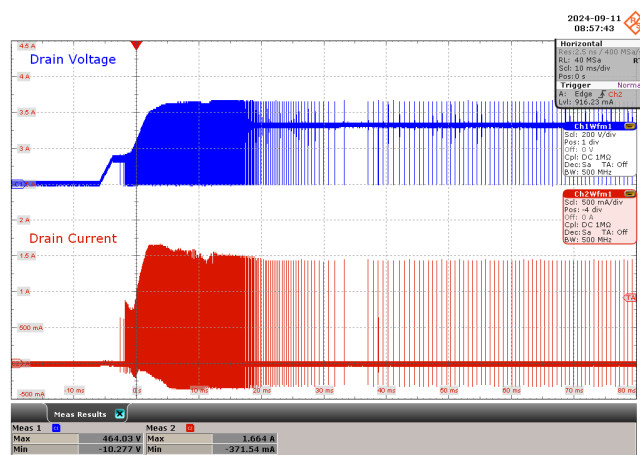
12.3.2.2 No Load

**Figure 56** – 85 VAC 60 Hz.

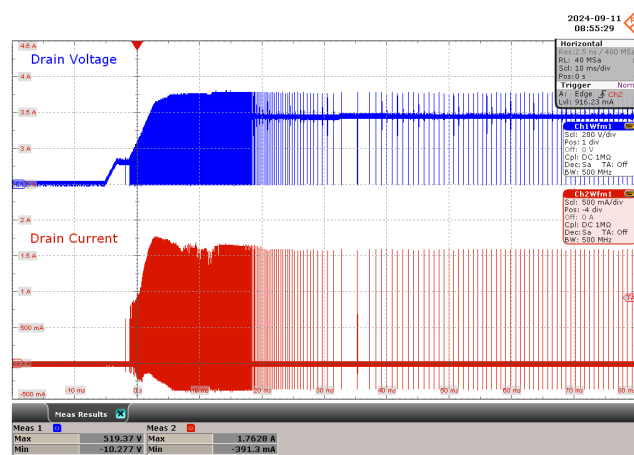
CH1: Drain Voltage, 100 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 268 V
 Drain Current_(MAX) = 1.25 A

**Figure 57** – 115 VAC 60 Hz.

CH1: Drain Voltage, 100 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 307 V
 Drain Current_(MAX) = 1.21 A

**Figure 58** – 230 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 464 V
 Drain Current_(MAX) = 1.66 A

**Figure 59** – 265 VAC 50 Hz.

CH1: Drain Voltage, 200 V / div., 10 ms / div.
 CH2: Drain Current, 500 mA / div., 10 ms / div.
 Drain Voltage_(MAX) = 519 V
 Drain Current_(MAX) = 1.76 A

12.3.3 Freewheeling Diode Voltage and Current at Normal Operation

12.3.3.1 Full Load

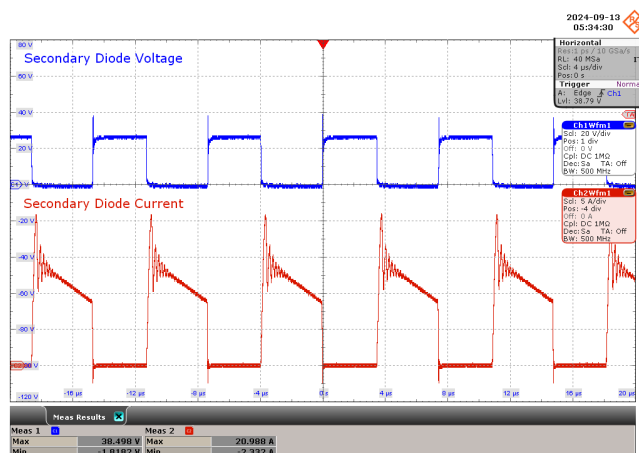


Figure 60 – 85 VAC 60 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 4 μs / div.

CH2: Secondary Diode Current, 5 A / div., 4 μs / div.

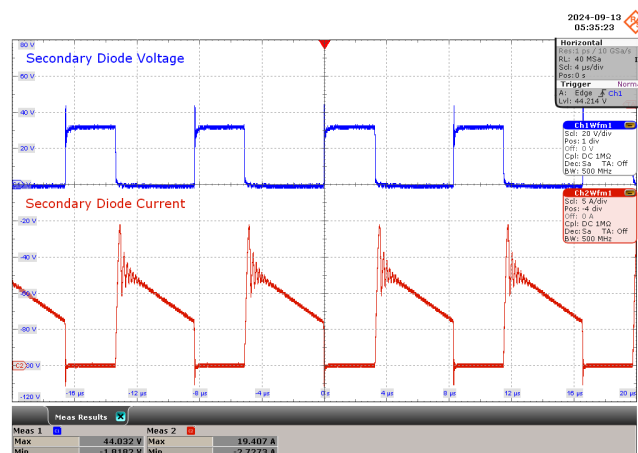
Secondary Diode Voltage_(MAX) = 38.5 VSecondary Diode Current_(MAX) = 21 A

Figure 61 – 115 VAC 60 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 4 μs / div.

CH2: Secondary Diode Current, 5 A / div., 4 μs / div.

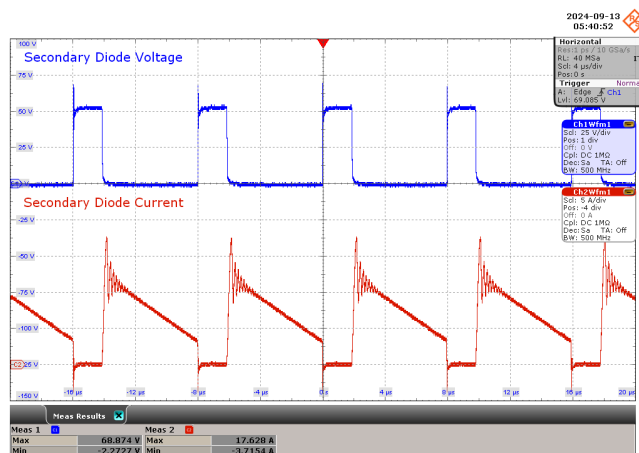
Secondary Diode Voltage_(MAX) = 44.0 VSecondary Diode Current_(MAX) = 19.4 A

Figure 62 – 230 VAC 50 Hz.

CH1: Secondary Diode Voltage, 25 V / div., 4 μs / div.

CH2: Secondary Diode Current, 5 A / div., 4 μs / div.

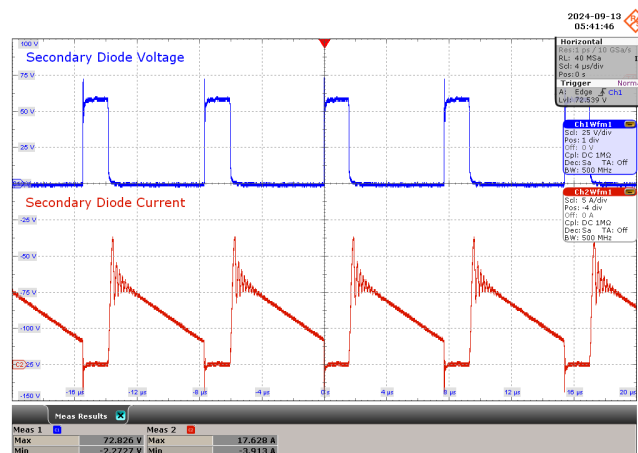
Secondary Diode Voltage_(MAX) = 68.9 VSecondary Diode Current_(MAX) = 17.6 A

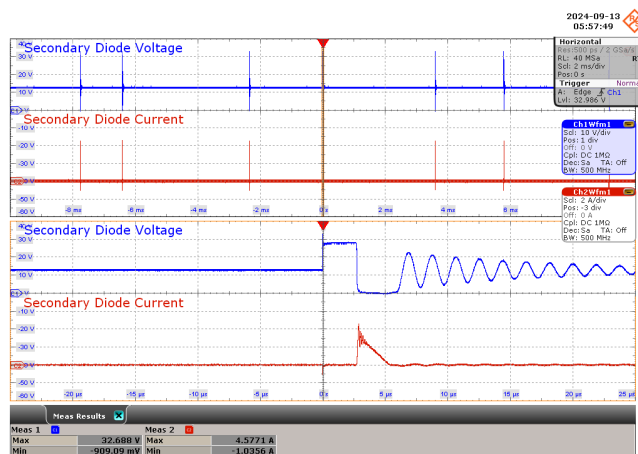
Figure 63 – 265 VAC 50 Hz.

CH1: Secondary Diode Voltage, 25 V / div., 4 μs / div.

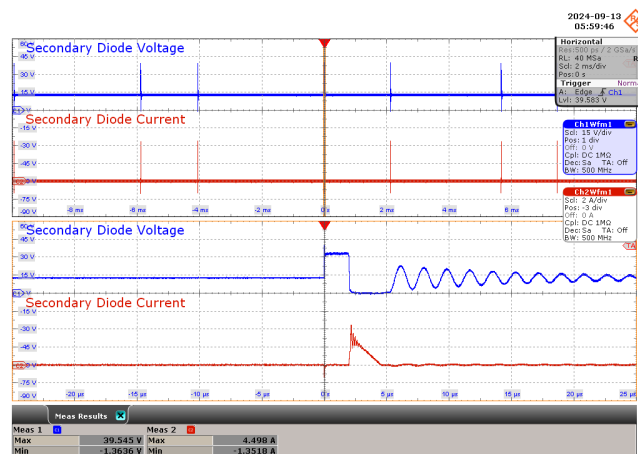
CH2: Secondary Diode Current, 5 A / div., 4 μs / div.

Secondary Diode Voltage_(MAX) = 72.8 VSecondary Diode Current_(MAX) = 17.6 A

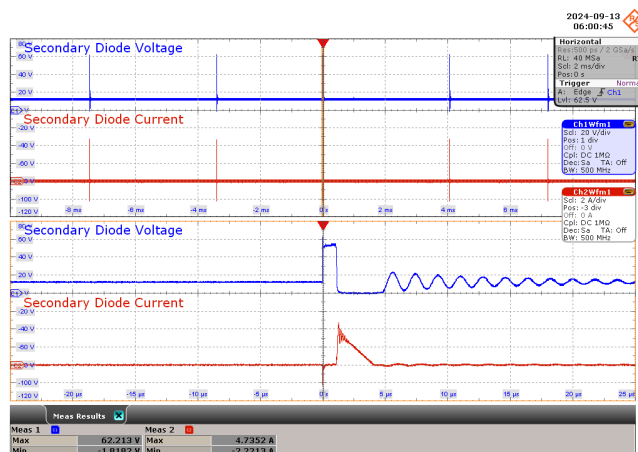
12.3.3.2 No Load

**Figure 64** – 85 VAC 60 Hz.

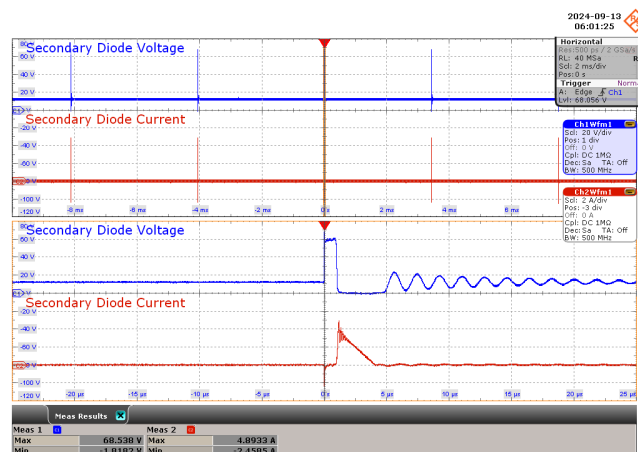
CH1: Secondary Diode Voltage, 10 V / div., 2 ms / div.
 CH2: Secondary Diode Current, 2 A / div., 2 ms / div.
 Zoom: 5 μ s / div.
 Secondary Diode Voltage_(MAX) = 32.7 V
 Secondary Diode Current_(MAX) = 4.58 A

**Figure 65** – 115 VAC 60 Hz.

CH1: Secondary Diode Voltage, 15 V / div., 2 ms / div.
 CH2: Secondary Diode Current, 2 A / div., 2 ms / div.
 Zoom: 5 μ s / div.
 Secondary Diode Voltage_(MAX) = 39.5 V
 Secondary Diode Current_(MAX) = 4.5 A

**Figure 66** – 230 VAC 50 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 2 ms / div.
 CH2: Secondary Diode Current, 2 A / div., 2 ms / div.
 Zoom: 5 μ s / div.
 Secondary Diode Voltage_(MAX) = 62.2 V
 Secondary Diode Current_(MAX) = 4.74 A

**Figure 67** – 265 VAC 50 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 2 ms / div.
 CH2: Secondary Diode Current, 2 A / div., 2 ms / div.
 Zoom: 5 μ s / div.
 Secondary Diode Voltage_(MAX) = 68.5 V
 Secondary Diode Current_(MAX) = 4.89 A

12.3.4 Freewheeling Diode Voltage and Current at Start-Up

12.3.4.1 Full Load

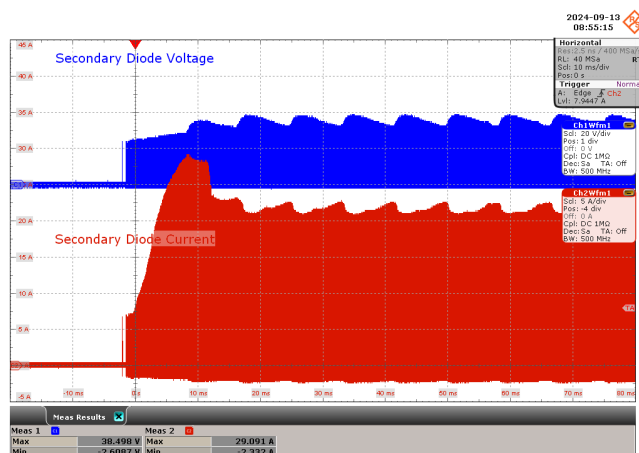


Figure 68 – 85 VAC 60 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

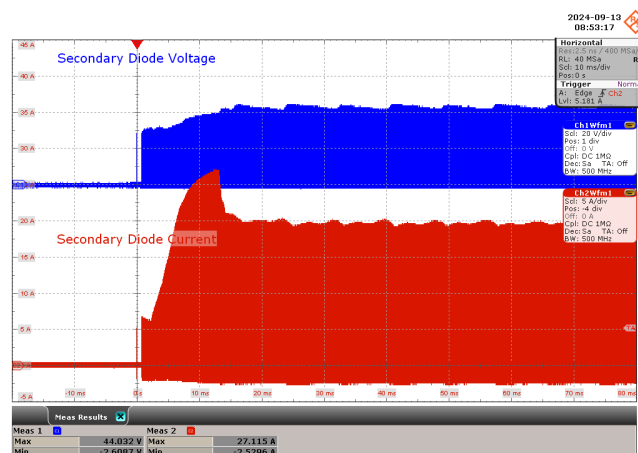
Secondary Diode Voltage_(MAX) = 38.5 VSecondary Diode Current_(MAX) = 29.1 A

Figure 69 – 115 VAC 60 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

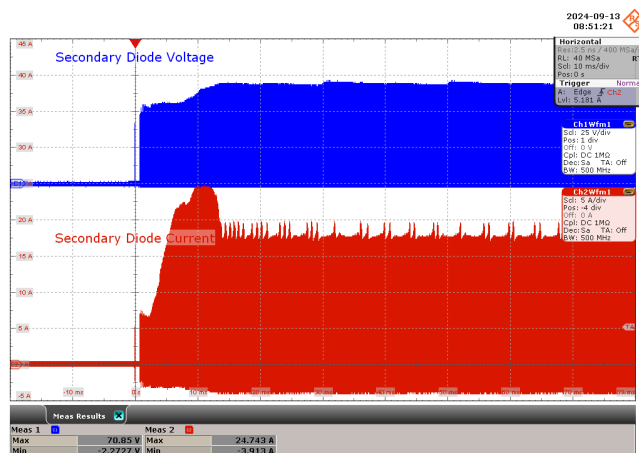
Secondary Diode Voltage_(MAX) = 44.0 VSecondary Diode Current_(MAX) = 27.1 A

Figure 70 – 230 VAC 50 Hz.

CH1: Secondary Diode Voltage, 25 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

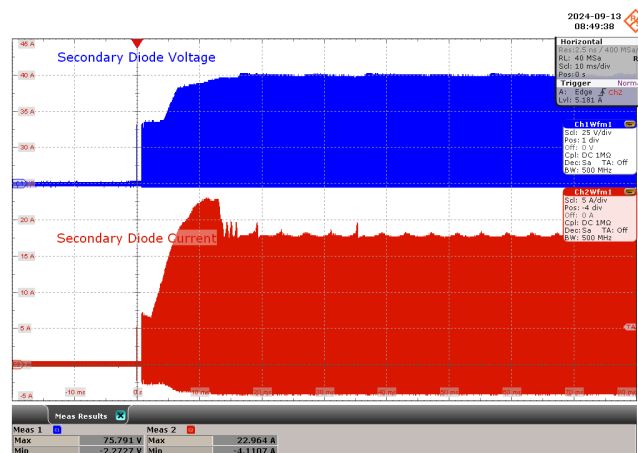
Secondary Diode Voltage_(MAX) = 70.9 VSecondary Diode Current_(MAX) = 24.7 A

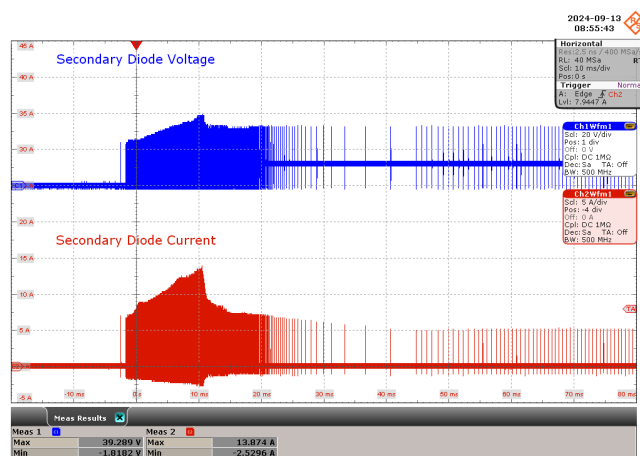
Figure 71 – 265 VAC 50 Hz.

CH1: Secondary Diode Voltage, 25 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

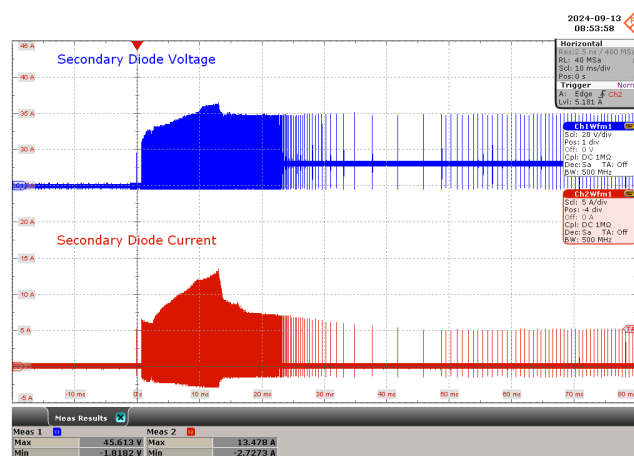
Secondary Diode Voltage_(MAX) = 75.8 VSecondary Diode Current_(MAX) = 23 A

12.3.4.2 No Load

**Figure 72** – 85 VAC 60 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

Secondary Diode Voltage_(MAX) = 39.3 VSecondary Diode Current_(MAX) = 13.9 A**Figure 73** – 115 VAC 60 Hz.

CH1: Secondary Diode Voltage, 20 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

Secondary Diode Voltage_(MAX) = 45.6 VSecondary Diode Current_(MAX) = 13.5 A**Figure 74** – 230 VAC 50 Hz.

CH1: Secondary Diode Voltage, 25 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

Secondary Diode Voltage_(MAX) = 63 VSecondary Diode Current_(MAX) = 13.7 A**Figure 75** – 265 VAC 50 Hz.

CH1: Secondary Diode Voltage, 25 V / div., 10 ms / div.

CH2: Secondary Diode Current, 5 A / div., 10 ms / div.

Secondary Diode Voltage_(MAX) = 68.9 VSecondary Diode Current_(MAX) = 13.5 A

12.4 Brown-In and Brown-Out

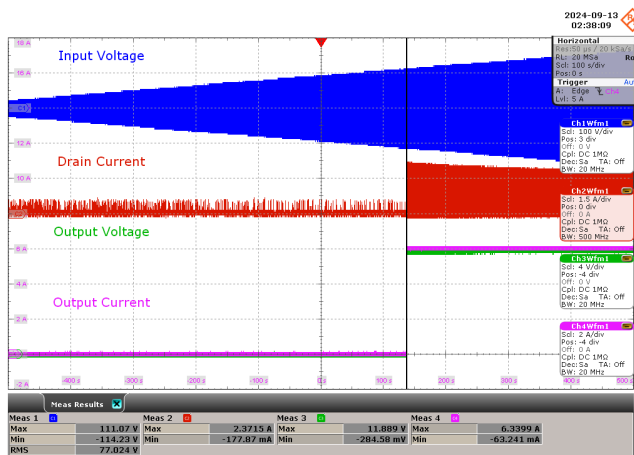


Figure 76 – Brown-In Full Load.

CH1: Input Voltage, 100 V / div., 100 s / div.
 CH2: Drain Current, 1.5 A / div., 100 s / div.
 CH3: Output Voltage, 4 V / div., 100 s / div.
 CH4: Output Current, 2 A / div., 100 s / div.
 $V_{\text{BROWN-IN}} = 77.0 \text{ V}_{\text{RMS}}$

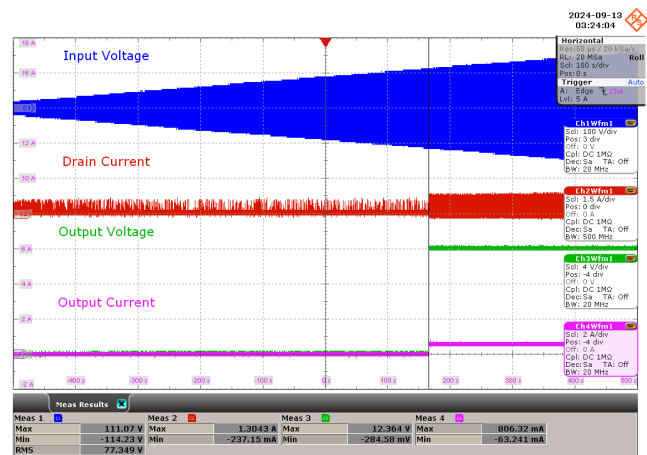


Figure 77 – Brown-In 10% Load.

CH1: Input Voltage, 100 V / div., 100 s / div.
 CH2: Drain Current, 1.5 A / div., 100 s / div.
 CH3: Output Voltage, 4 V / div., 100 s / div.
 CH4: Output Current, 2 A / div., 100 s / div.
 $V_{\text{BROWN-IN}} = 77.3 \text{ V}_{\text{RMS}}$

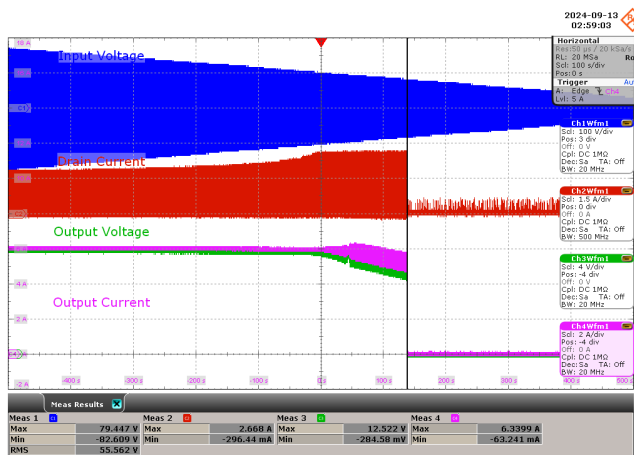


Figure 78 – Brown-Out Full Load.

CH1: Input Voltage, 100 V / div., 100 s / div.
 CH2: Drain Current, 1.5 A / div., 100 s / div.
 CH3: Output Voltage, 4 V / div., 100 s / div.
 CH4: Output Current, 2 A / div., 100 s / div.
 $V_{\text{BROWN-IN}} = 55.6 \text{ V}_{\text{RMS}}$

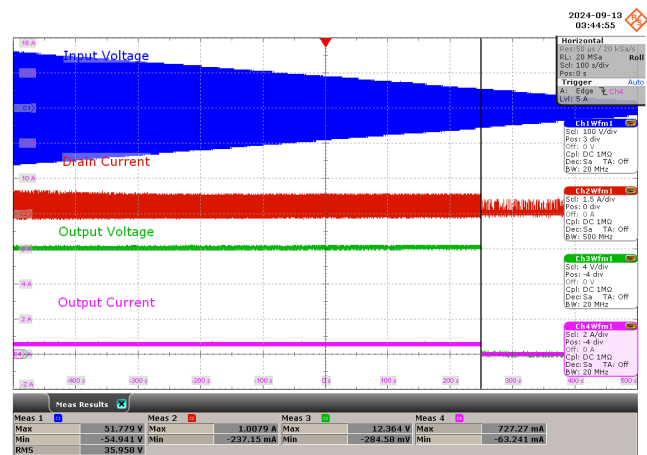


Figure 79 – Brown-Out 10% Load.

CH1: Input Voltage, 100 V / div., 100 s / div.
 CH2: Drain Current, 1.5 A / div., 100 s / div.
 CH3: Output Voltage, 4 V / div., 100 s / div.
 CH4: Output Current, 2 A / div., 100 s / div.
 $V_{\text{BROWN-IN}} = 36 \text{ V}_{\text{RMS}}$

12.5 Output Voltage Ripple

12.5.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe was utilized to minimize spurious signals due to pick-up. Details of the probe modification are provided in the Figures below.

The 4987BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors are one (1) 0.1 μF / 50 V ceramic type and one (1) 47 μF / 50 V aluminum electrolytic. The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).

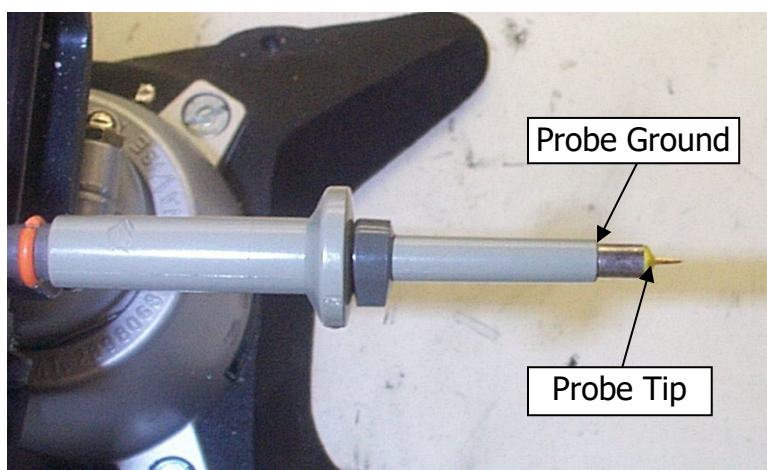


Figure 80 – Oscilloscope Probe Prepared for Ripple Measurement. (End Cap and Ground Lead Removed.)

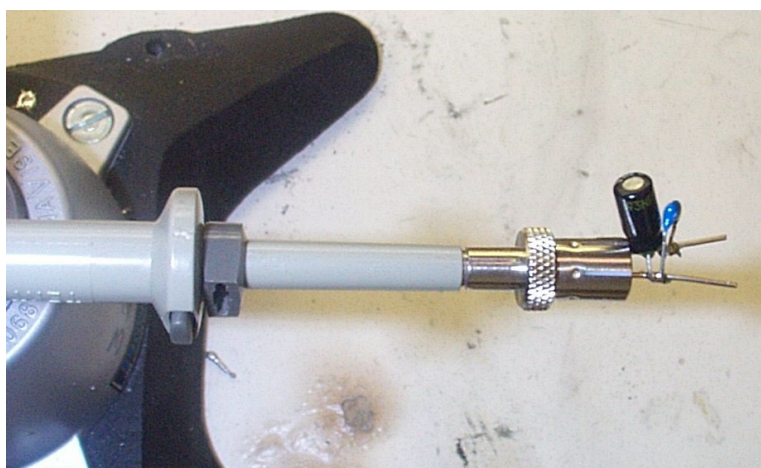


Figure 81 – Oscilloscope Probe with Probe Master (www.probemaster.com) 4987A BNC Adapter. (Modified with wires for ripple measurement, and two parallel decoupling capacitors added.)

12.5.2 Measurement Results

Note: All ripple measurements were taken at PCB end.

12.5.2.1 100% Load Condition

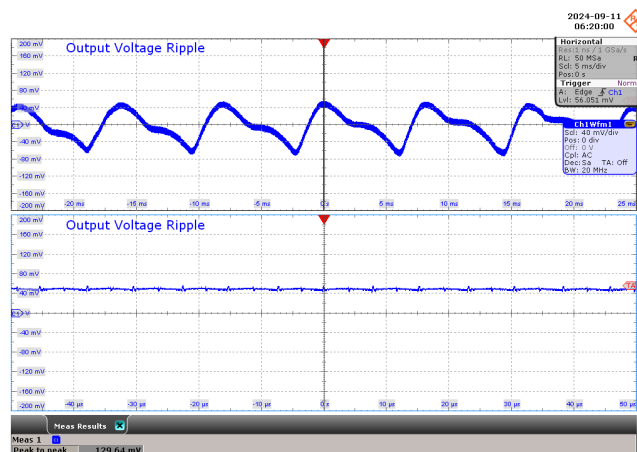


Figure 82 – 85 VAC 60 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 130 mV

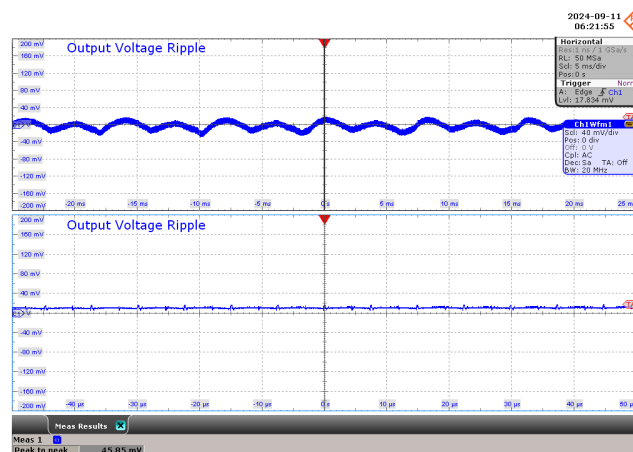


Figure 83 – 115 VAC 60 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 45.9 mV

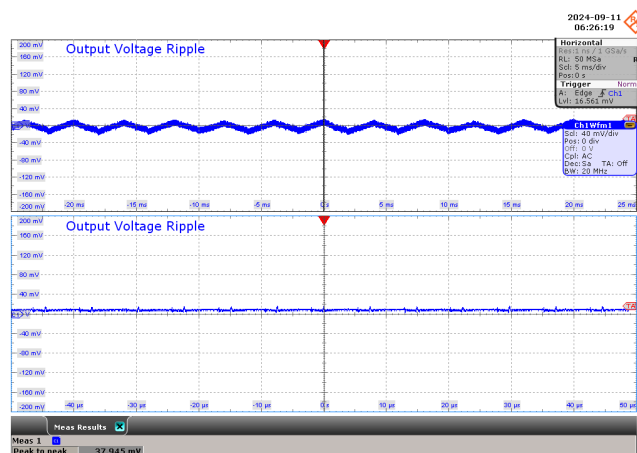


Figure 84 – 230 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 38 mV

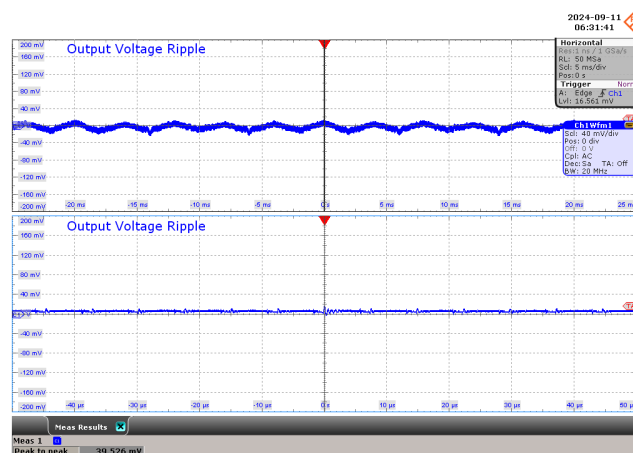
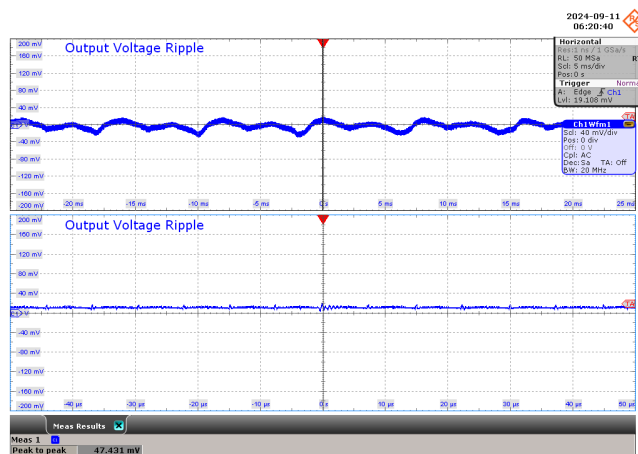


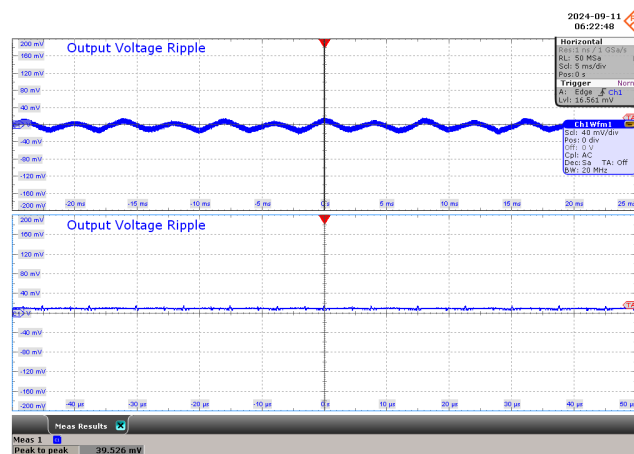
Figure 85 – 265 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 40 mV

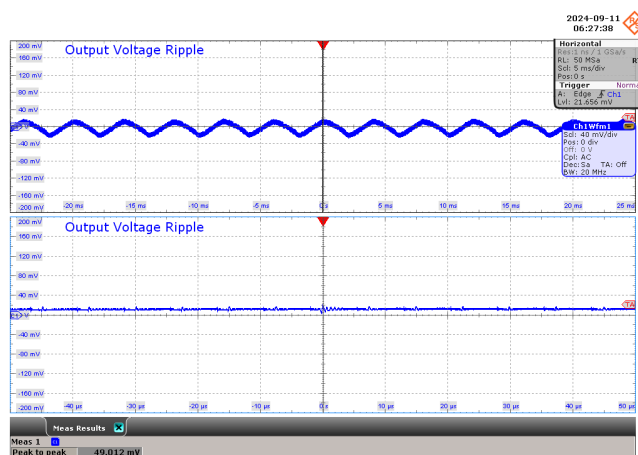
12.5.2.2 75% Load Condition

**Figure 86** – 85 VAC 60 Hz.

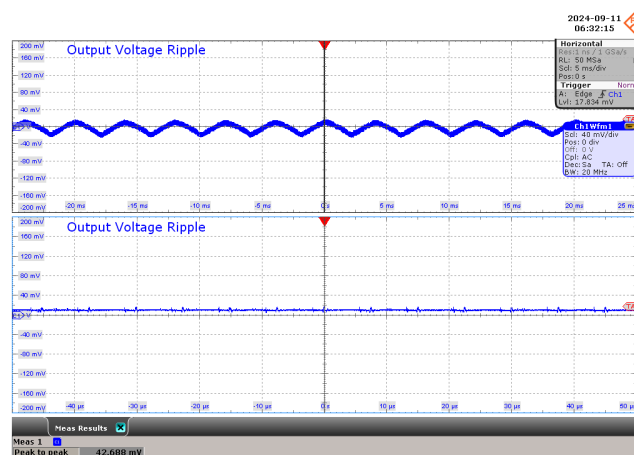
CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 47.4 mV

**Figure 87** – 115 VAC 60 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 40 mV

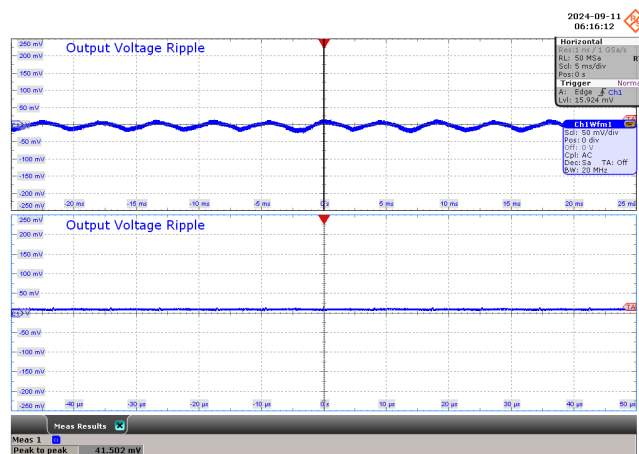
**Figure 88** – 230 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 49.0 mV

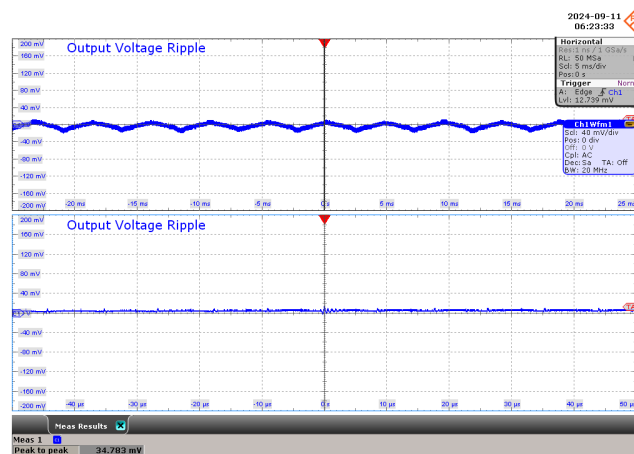
**Figure 89** – 265 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 42.7 mV

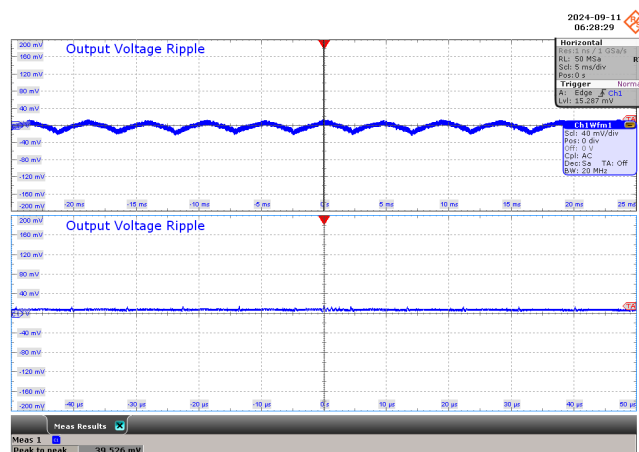
12.5.2.3 50% Load Condition

**Figure 90** – 85 VAC 60 Hz.

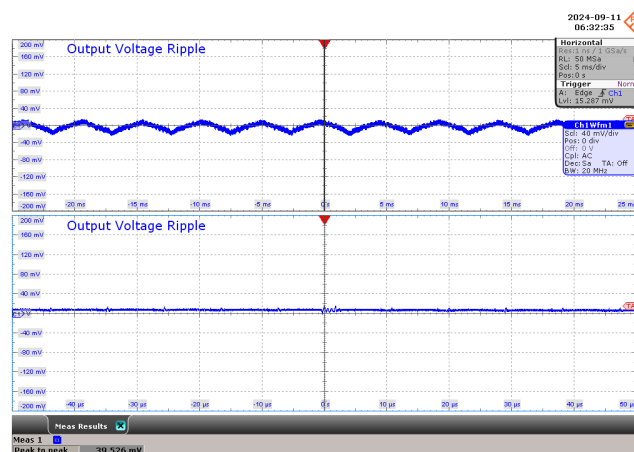
CH1: Output Ripple, 50 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 41.5 mV

**Figure 91** – 115 VAC 60 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 34.8 mV

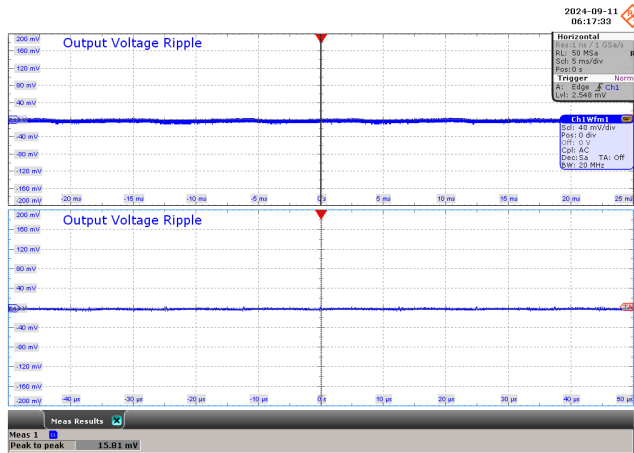
**Figure 92** – 230 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 39.5 mV

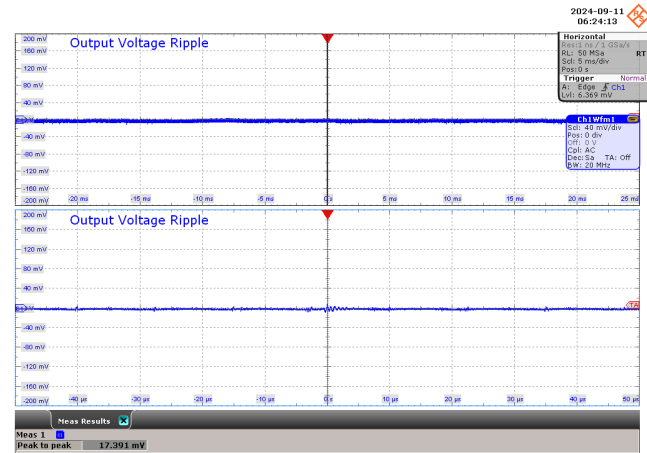
**Figure 93** – 265 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 39.5 mV

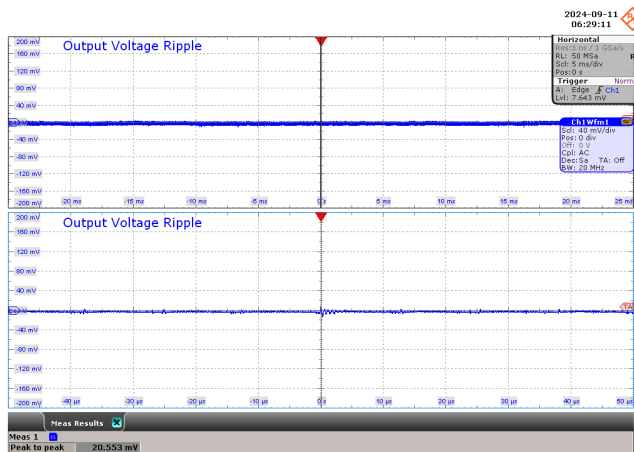
12.5.2.4 25% Load Condition

**Figure 94** – 85 VAC 60 Hz.

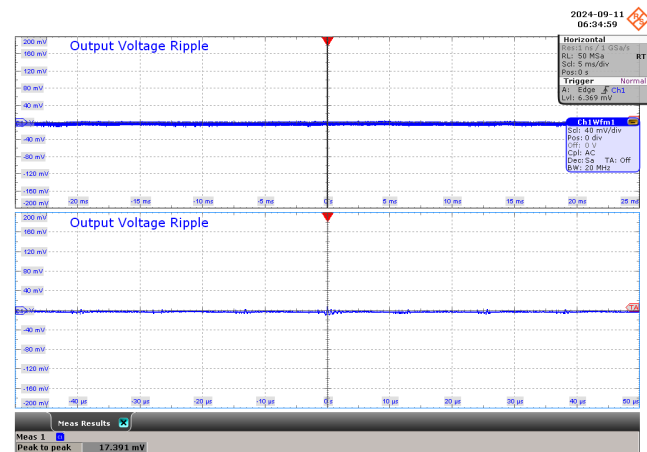
CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 15.8 mV

**Figure 95** – 115 VAC 60 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 17.4 mV

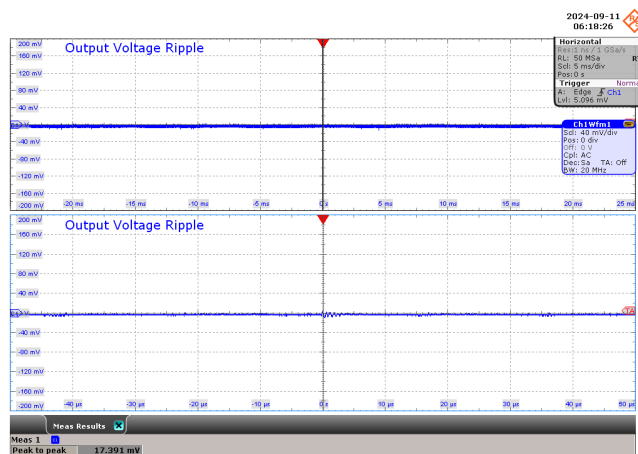
**Figure 96** – 230 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 20.6 mV

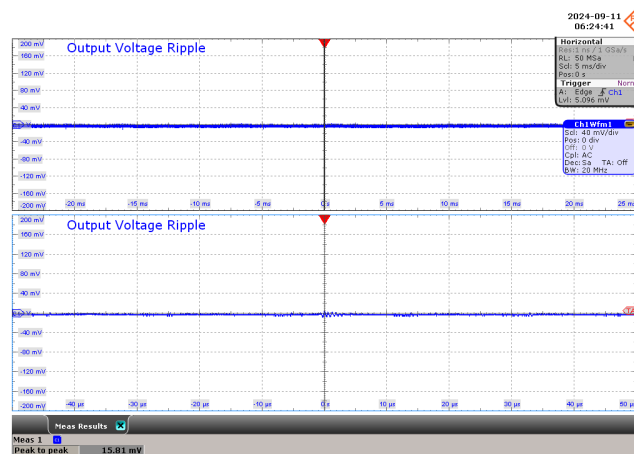
**Figure 97** – 265 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 μ s / div.
Output Ripple = 17.4 mV

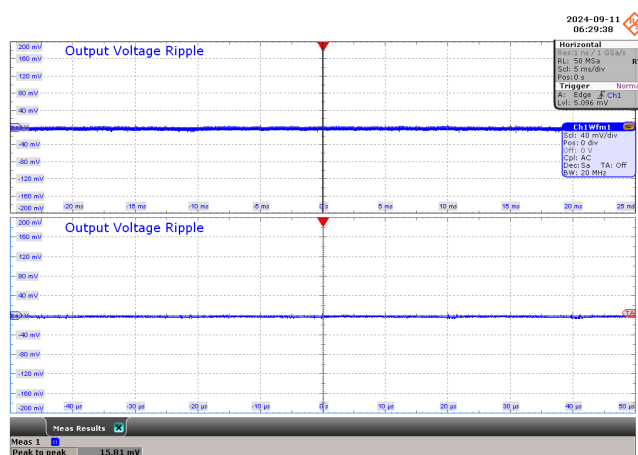
12.5.2.5 10% Load Condition

**Figure 98** – 85 VAC 60 Hz.

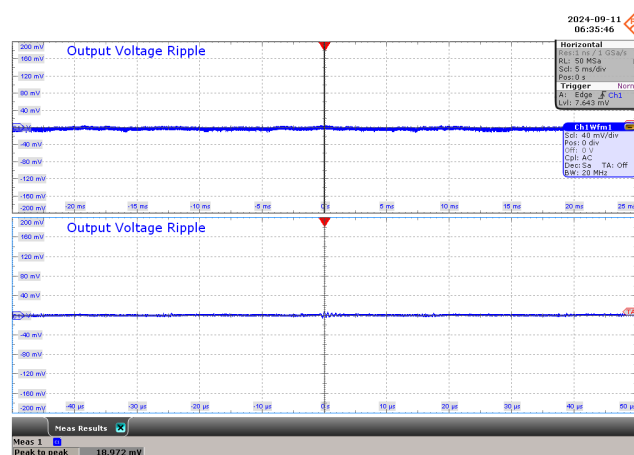
CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 µs / div.
Output Ripple = 17.4 mV

**Figure 99** – 115 VAC 60 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 µs / div.
Output Ripple = 15.8 mV

**Figure 100** – 230 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 µs / div.
Output Ripple = 15.8 mV

**Figure 101** – 265 VAC 50 Hz.

CH1: Output Ripple, 40 mV / div., 5 ms / div.
Zoom: 10 µs / div.
Output Ripple = 19 mV

12.5.3 Output Ripple Voltage Graph

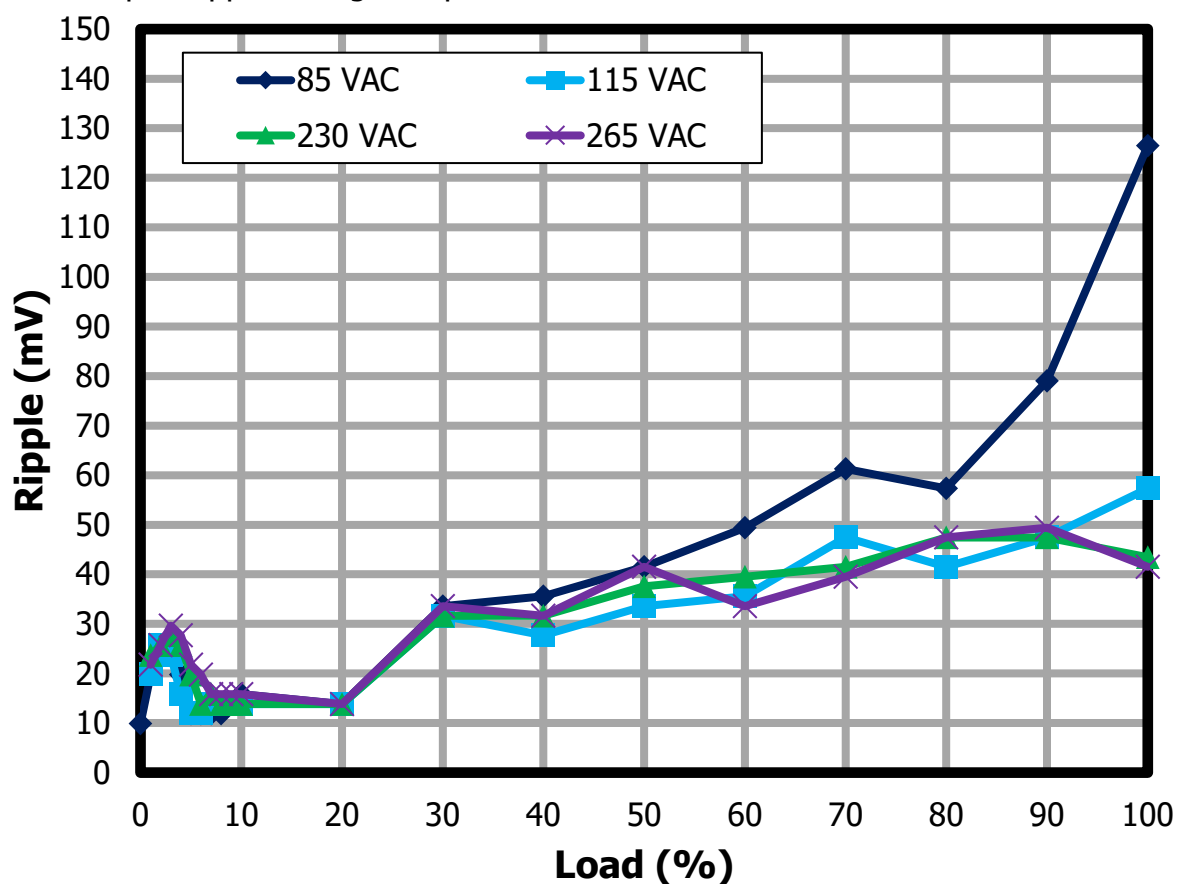


Figure 102 – Voltage Ripple (Measured at PCB End at Room Temperature).

13 Thermal Performance

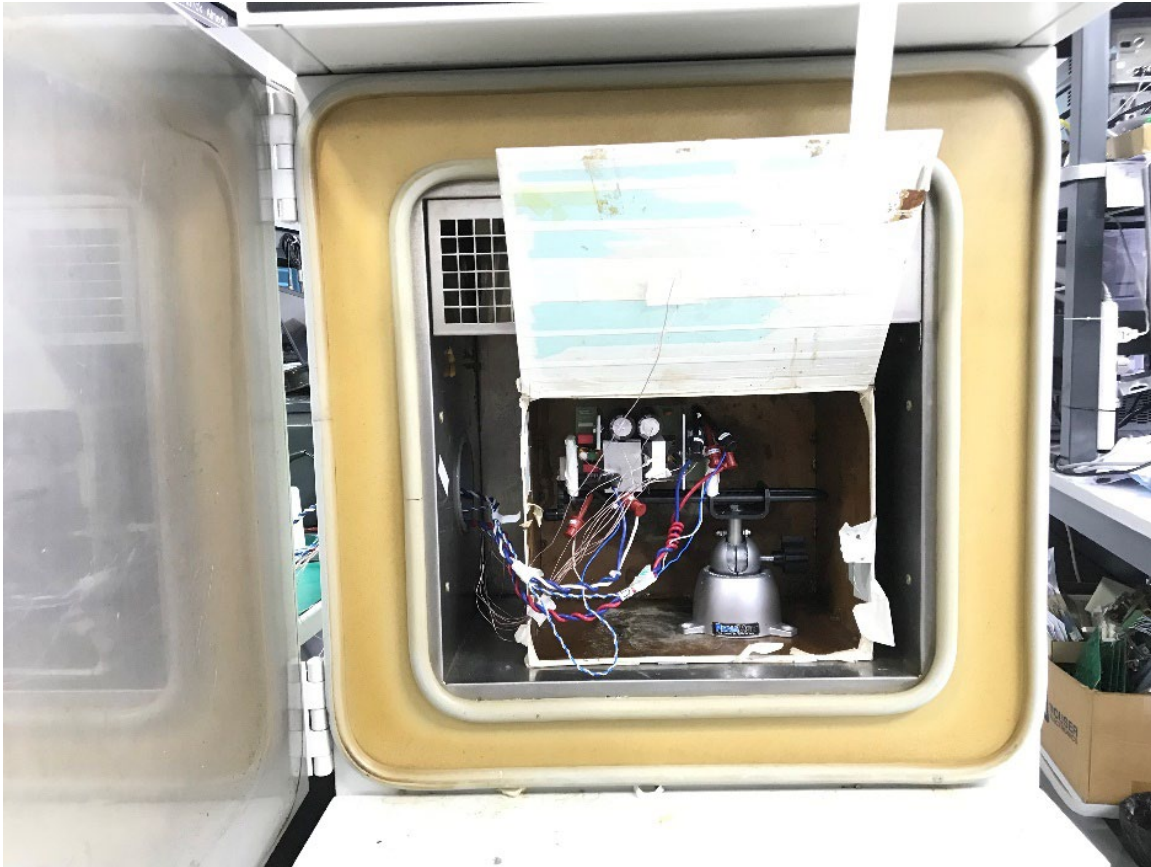


Figure 103 – Thermal Performance Set-up Using Thermal Chamber.

13.1 25 °C Ambient Thermals

To measure the temperature of components U2, T1, BR1, D3, C2, C15, and L2, T-type thermocouples were attached to each. The thermal data was then fed to the data logger. A thermal chamber was utilized to maintain a constant ambient temperature of 25 °C.

13.1.1 85 VAC Full Load at 25 °C Ambient

Test result after 2 hours running continuously at 85 VAC full load.

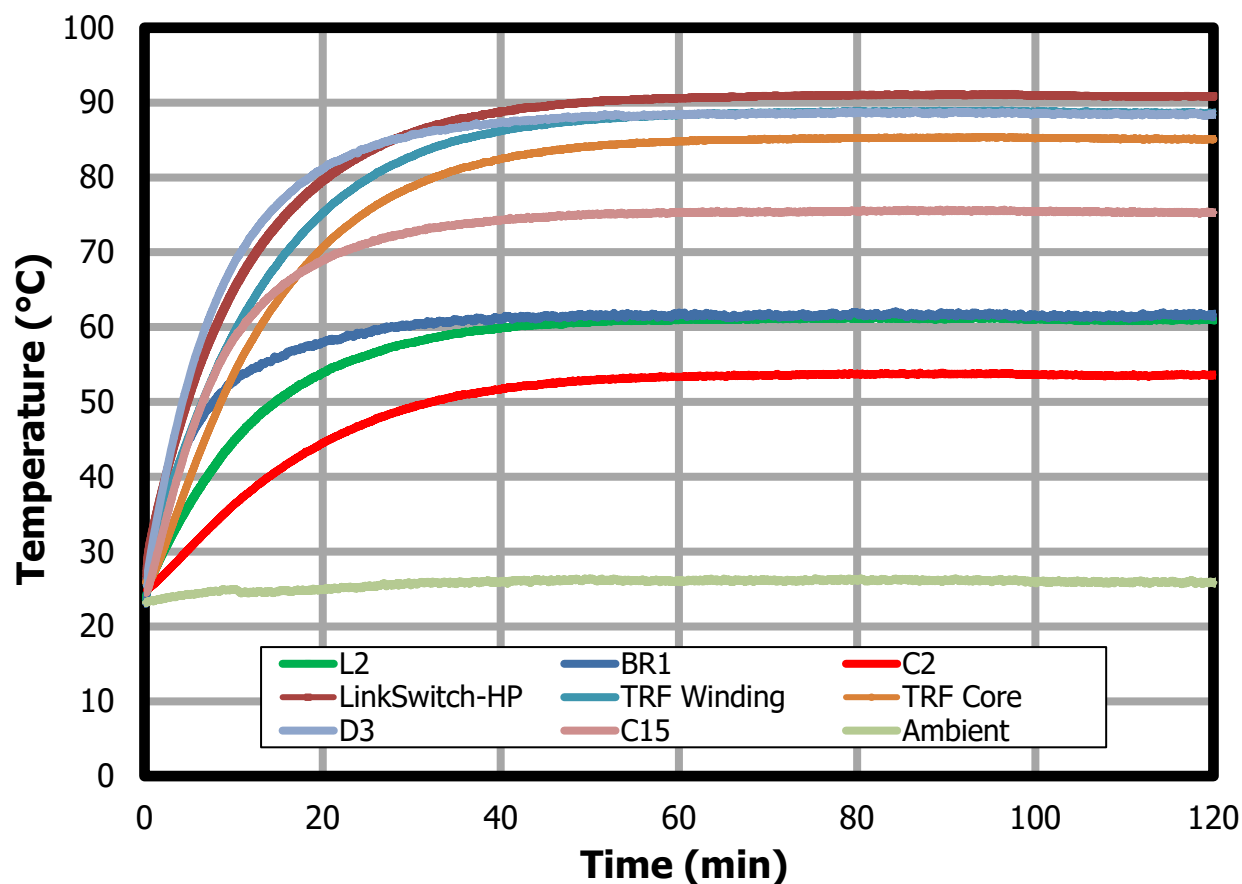


Figure 104 – 85 VAC 60 Hz. Top Side Discrete Component Temperatures.

Component	Temperature (°C)
Ambient	25.9
LNK6779E (U2)	90.8
Transformer Core (T1)	85.1
Transformer Winding (T1)	88.6
Bridge (BR1)	61.6
Secondary Diode (D3)	88.4
Bulk Capacitor (C2)	53.5
Output Capacitor (C15)	75.2
CMC (L2)	61

Table 13 – 85 VAC 60 Hz. Top Side Discrete Component Temperatures.

13.1.2 265 VAC Full Load at 25 °C Ambient

Test result after 2 hours running continuously at 265 VAC full load.

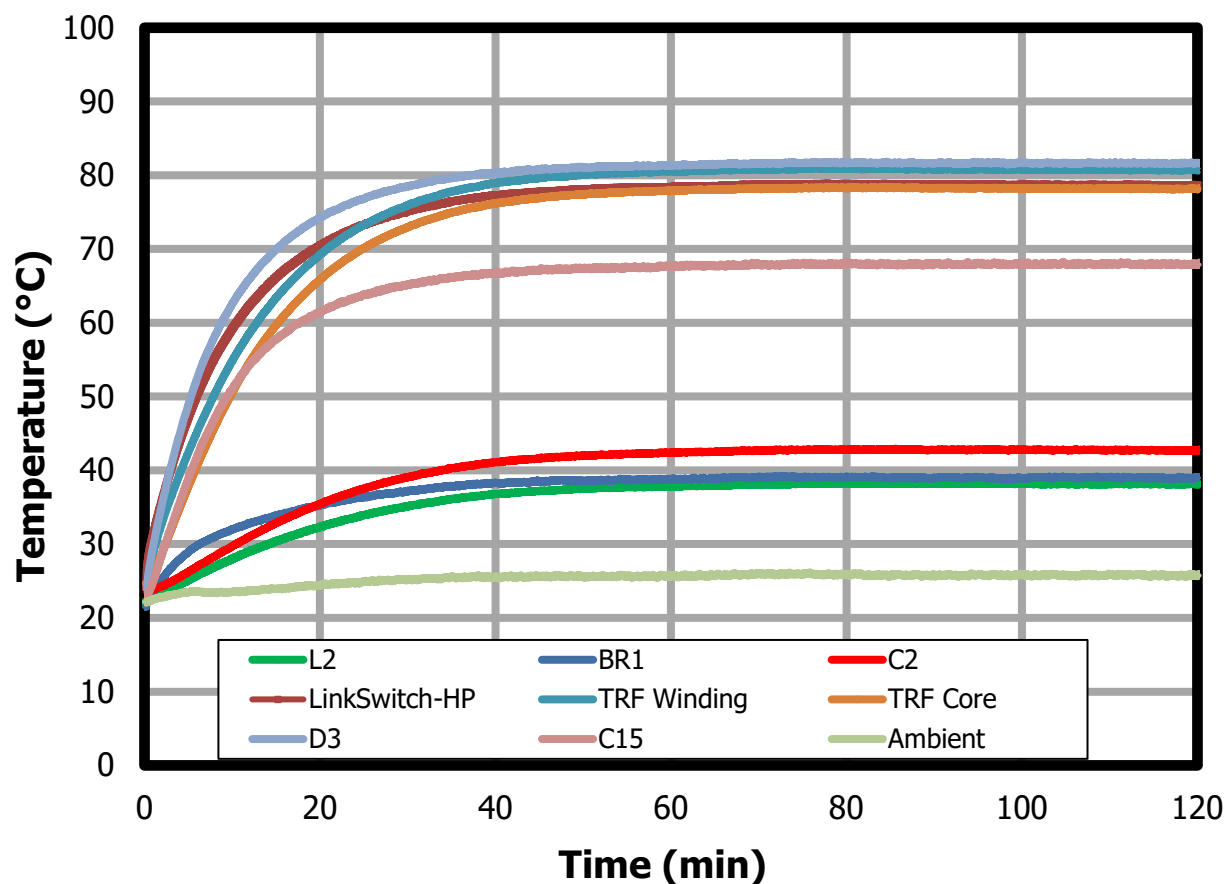


Figure 105 – 265 VAC 50 Hz. Top Side Discrete Component Temperatures.

Component	Temperature (°C)
Ambient	25.8
LNK6779E (U2)	78.7
Transformer Core (T1)	78.1
Transformer Winding (T1)	80.7
Bridge (BR1)	38.9
Secondary Diode (D3)	81.5
Bulk Capacitor (C2)	42.7
Output Capacitor (C15)	67.9
CMC (L2)	38.1

Table 14 – 265 VAC 50 Hz. Top Side Discrete Component Temperatures.

13.2 40 °C Ambient Thermals

A thermal chamber was utilized to maintain a constant ambient temperature at 40 °C. To measure the temperature of the top side discrete components U2, T1, BR1, D3, C2, C15, and L2, T-type thermocouples were attached to each. The thermal data was then fed to the data logger.

13.2.1 85 VAC Full Load at 40 °C Ambient (Thermal Chamber)

Test result after 2 hours running continuously at 85 VAC full load.

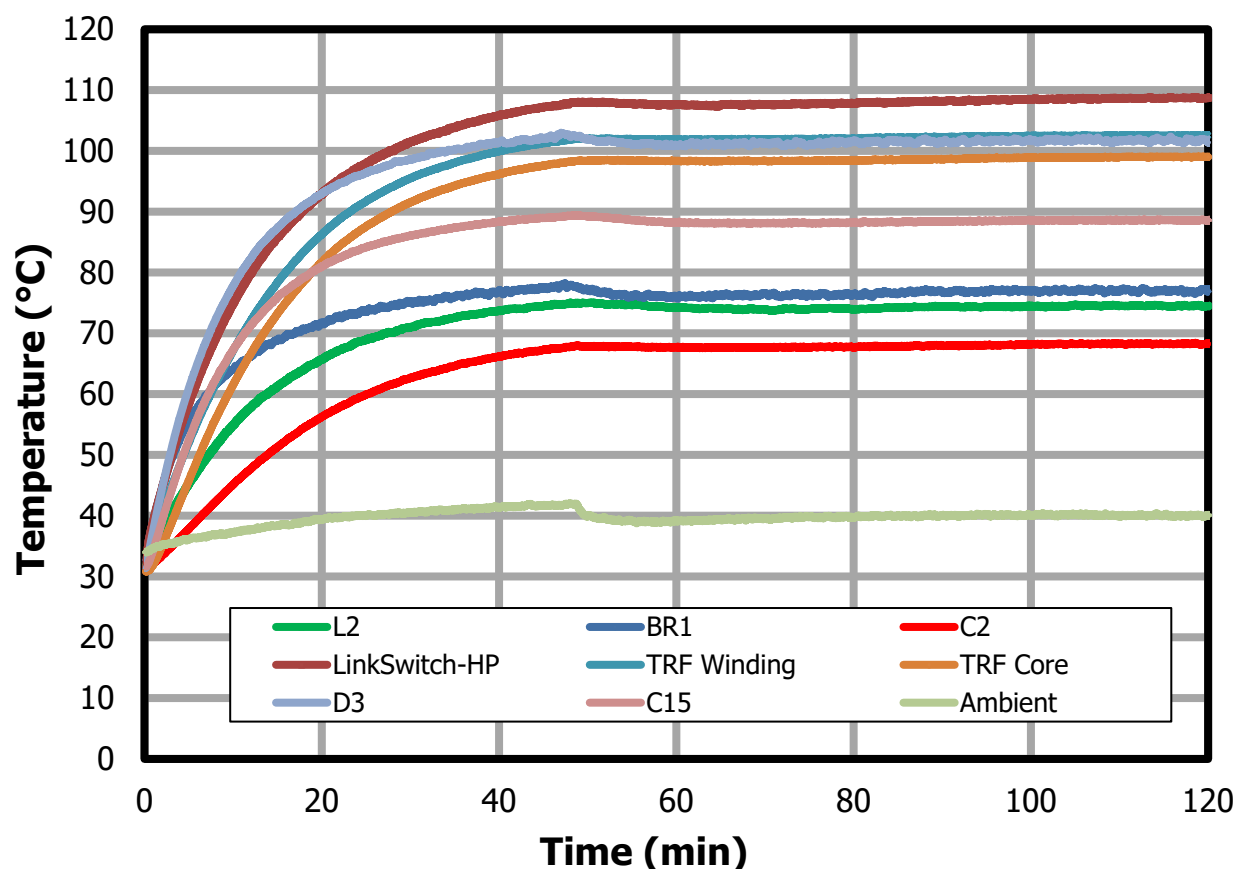


Figure 106 – 85 VAC 60 Hz. Temperatures at 40 °C Ambient.

Component	Temperature (°C)
Ambient	40.1
LNK6779E (U2)	109
Transformer Core (T1)	99.1
Transformer Winding (T1)	103
Bridge (BR1)	77.5
Secondary Diode (D3)	102
Bulk Capacitor (C2)	68.3
Output Capacitor (C15)	88.7
CMC (L2)	74.6

Table 15 – 85 VAC 60 Hz. Temperatures at 40 °C Ambient.

13.2.2 265 VAC Full Load at 40 °C Ambient (Thermal Chamber)

Test result after 2 hours running continuously at 265 VAC full load.

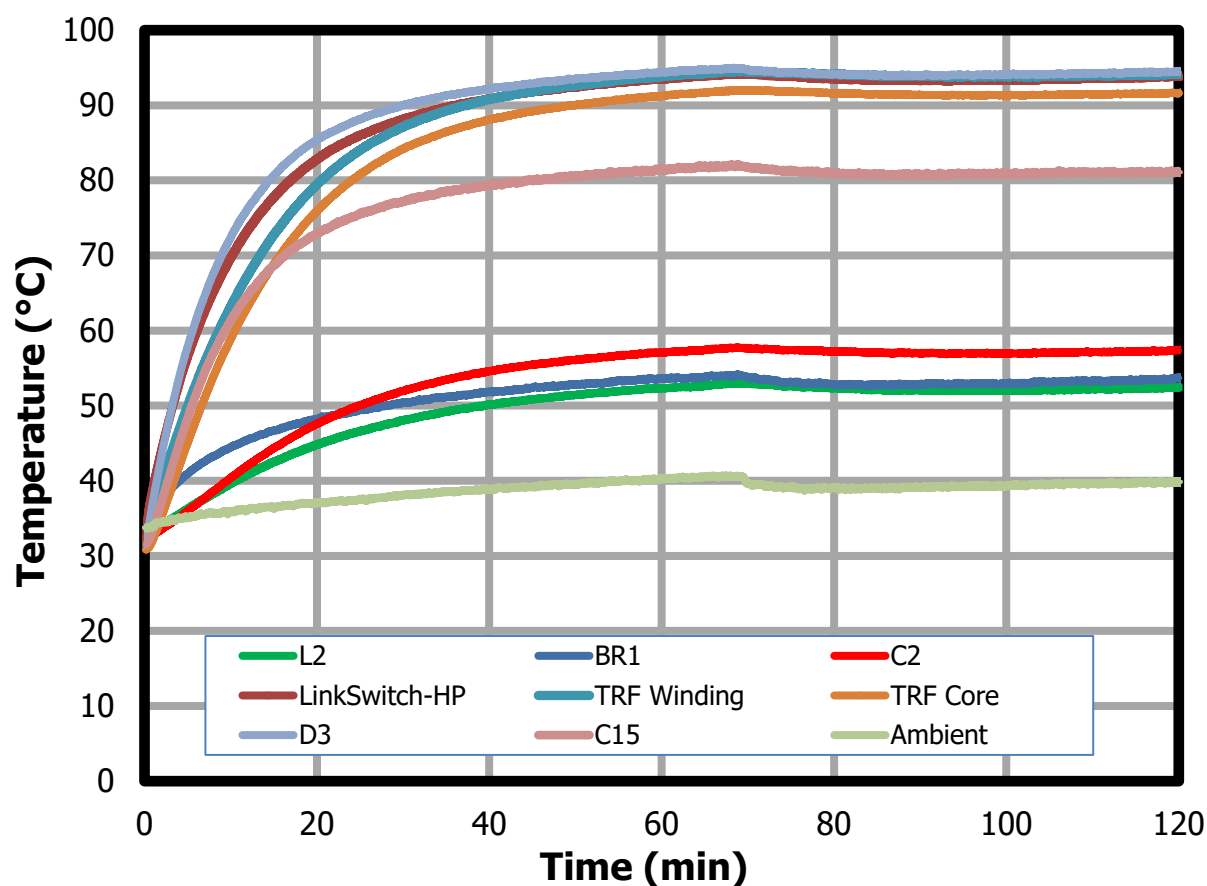


Figure 107 – 265 VAC 50 Hz. Temperatures at 40 °C Ambient.

Component	Temperature (°C)
Ambient	40.3
LNK6779E (U2)	94.1
Transformer Core (T1)	91.9
Transformer Winding (T1)	94.3
Bridge (BR1)	53.9
Secondary Diode (D3)	94.8
Bulk Capacitor (C2)	57.6
Output Capacitor (C15)	81.4
CMC (L2)	52.7

Table 16 – 265 VAC 50 Hz. Temperatures at 40 °C Ambient.

14.1.1 Start-Up Short

14.1.1 Running Short

14.1.1.1 Full Load

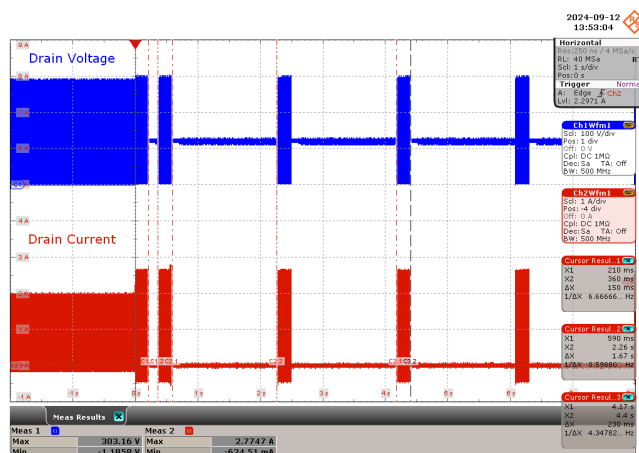


Figure 112 – 85 VAC 60 Hz. Output Short.

CH1: Drain Voltage, 100 V / div., 1 s / div.

CH2: Drain Current, 1 A / div., 1 s / div.

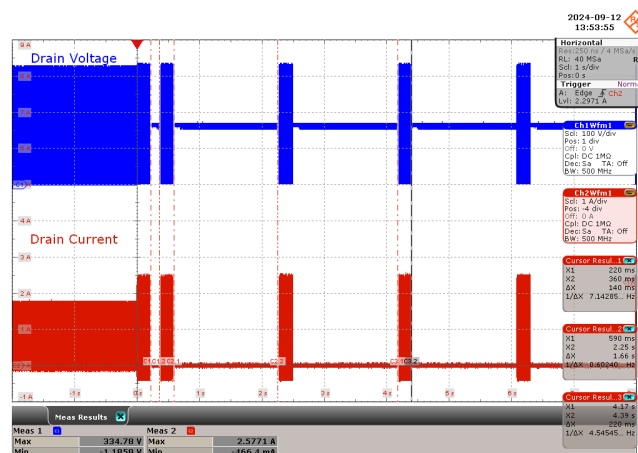
Drain Voltage_(MAX) = 303 VDrain Current_(MAX) = 2.77 A $t_{AR(OFF)1}$ = 150 ms $t_{AR(OFF)2}$ = 1.67 s $t_{AR(ON)}$ = 230 ms

Figure 113 – 115 VAC 60 Hz Output Short.

CH1: Drain Voltage, 100 V / div., 1 s / div.

CH2: Drain Current, 1 A / div., 1 s / div.

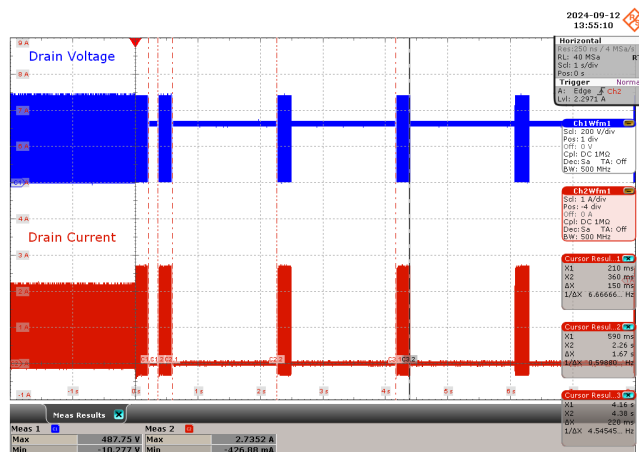
Drain Voltage_(MAX) = 335 VDrain Current_(MAX) = 2.58 A $t_{AR(OFF)1}$ = 140 ms $t_{AR(OFF)2}$ = 1.66 s $t_{AR(ON)}$ = 220 ms

Figure 114 – 230 VAC 50 Hz. Output Short.

CH1: Drain Voltage, 200 V / div., 1 s / div.

CH2: Drain Current, 1 A / div., 1 s / div.

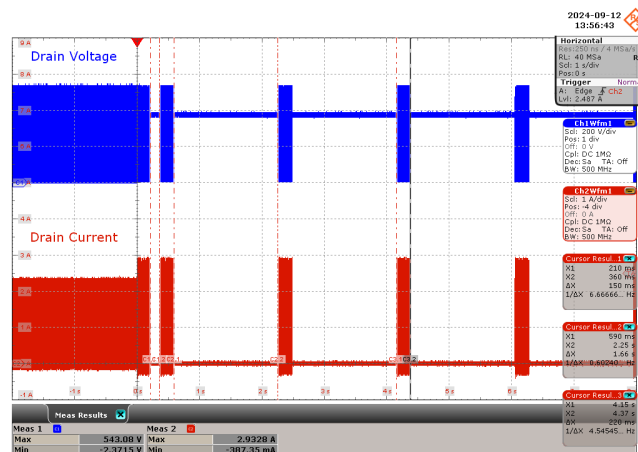
Drain Voltage_(MAX) = 488 VDrain Current_(MAX) = 2.74 A $t_{AR(OFF)1}$ = 150 ms $t_{AR(OFF)2}$ = 1.67 s $t_{AR(ON)}$ = 220 ms

Figure 115 – 265 VAC 50 Hz. Output Short.

CH1: Drain Voltage, 200 V / div., 1 s / div.

CH2: Drain Current, 1 A / div., 1 s / div.

Drain Voltage_(MAX) = 543 VDrain Current_(MAX) = 2.93 A $t_{AR(OFF)1}$ = 150 ms $t_{AR(OFF)2}$ = 1.66 s $t_{AR(ON)}$ = 220 ms

14.1.1.2 No Load

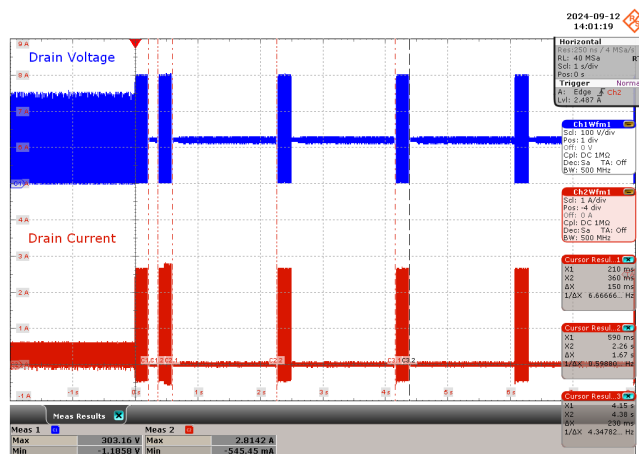


Figure 116 – 85 VAC 60 Hz. Output Short.
 CH1: Drain Voltage, 100 V / div., 1 s / div.
 CH2: Drain Current, 1 A / div., 1 s / div.
 Drain Voltage_(MAX) = 303 V
 Drain Current_(MAX) = 2.81 A
 t_{AR_OFF1} = 150 ms
 t_{AR_OFF2} = 1.67 s
 $t_{AR(ON)}$ = 230 ms

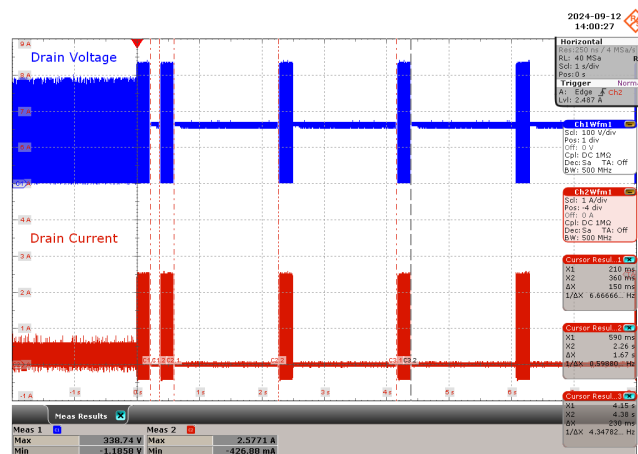


Figure 117 – 115 VAC 60 Hz Output Short.
 CH1: Drain Voltage, 100 V / div., 1 s / div.
 CH2: Drain Current, 1 A / div., 1 s / div.
 Drain Voltage_(MAX) = 339 V
 Drain Current_(MAX) = 2.57 A
 t_{AR_OFF1} = 150 ms
 t_{AR_OFF2} = 1.67 s
 $t_{AR(ON)}$ = 230 ms

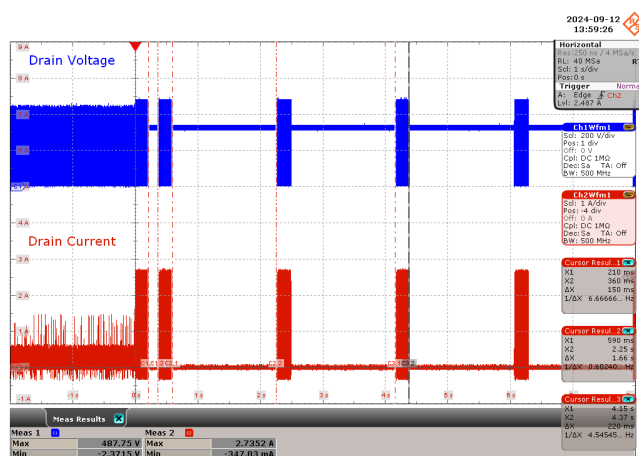


Figure 118 – 230 VAC 60 Hz. Output Short.
 CH1: Drain Voltage, 200 V / div., 1 s / div.
 CH2: Drain Current, 1 A / div., 1 s / div.
 Drain Voltage_(MAX) = 488 V
 Drain Current_(MAX) = 2.74 A
 t_{AR_OFF1} = 150 ms
 t_{AR_OFF2} = 1.66 s
 $t_{AR(ON)}$ = 220 ms

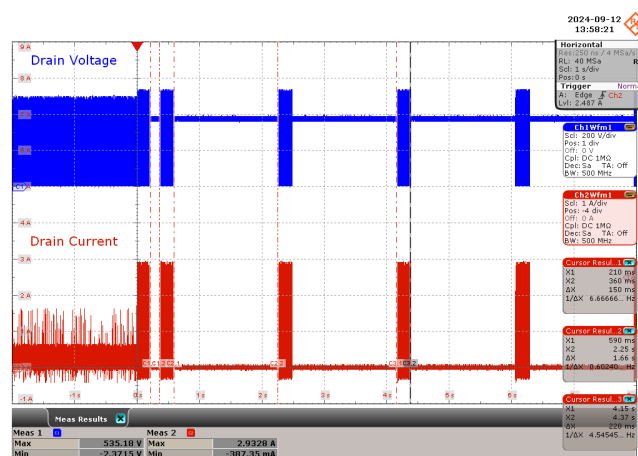


Figure 119 – 265 VAC 60 Hz. Output Short.
 CH1: Drain Voltage, 200 V / div., 1 s / div.
 CH2: Drain Current, 1 A / div., 1 s / div.
 Drain Voltage_(MAX) = 535 V
 Drain Current_(MAX) = 2.93 A
 t_{AR_OFF1} = 150 ms
 t_{AR_OFF2} = 1.66s
 $t_{AR(ON)}$ = 220 ms

14.1.1.3 Thermals

Component	Temperature (°C)
Ambient	26.3
LNK6779E (U2)	31.9
Transformer Core (T1)	39.9
Transformer Winding (T1)	39.2
Bridge (BR1)	27.7
Secondary Diode (D3)	49.6
Bulk Capacitor (C2)	28.5
Output Capacitor (C15)	44
CMC (L2)	27.1

Table 17 – 85 VAC 60 Hz. Discrete Component Temperatures - Output Short (1hr. Soak).

Component	Temperature (°C)
Ambient	24.4
LNK6779E (U2)	30.5
Transformer Core (T1)	36.1
Transformer Winding (T1)	35.1
Bridge (BR1)	25.1
Secondary Diode (D3)	45.1
Bulk Capacitor (C2)	26.4
Output Capacitor (C15)	39.4
CMC (L2)	24.8

Table 18 – 265 VAC 50 Hz. Discrete Component Temperatures - Output Short (1hr. Soak).

14.2 Over Temperature Protection

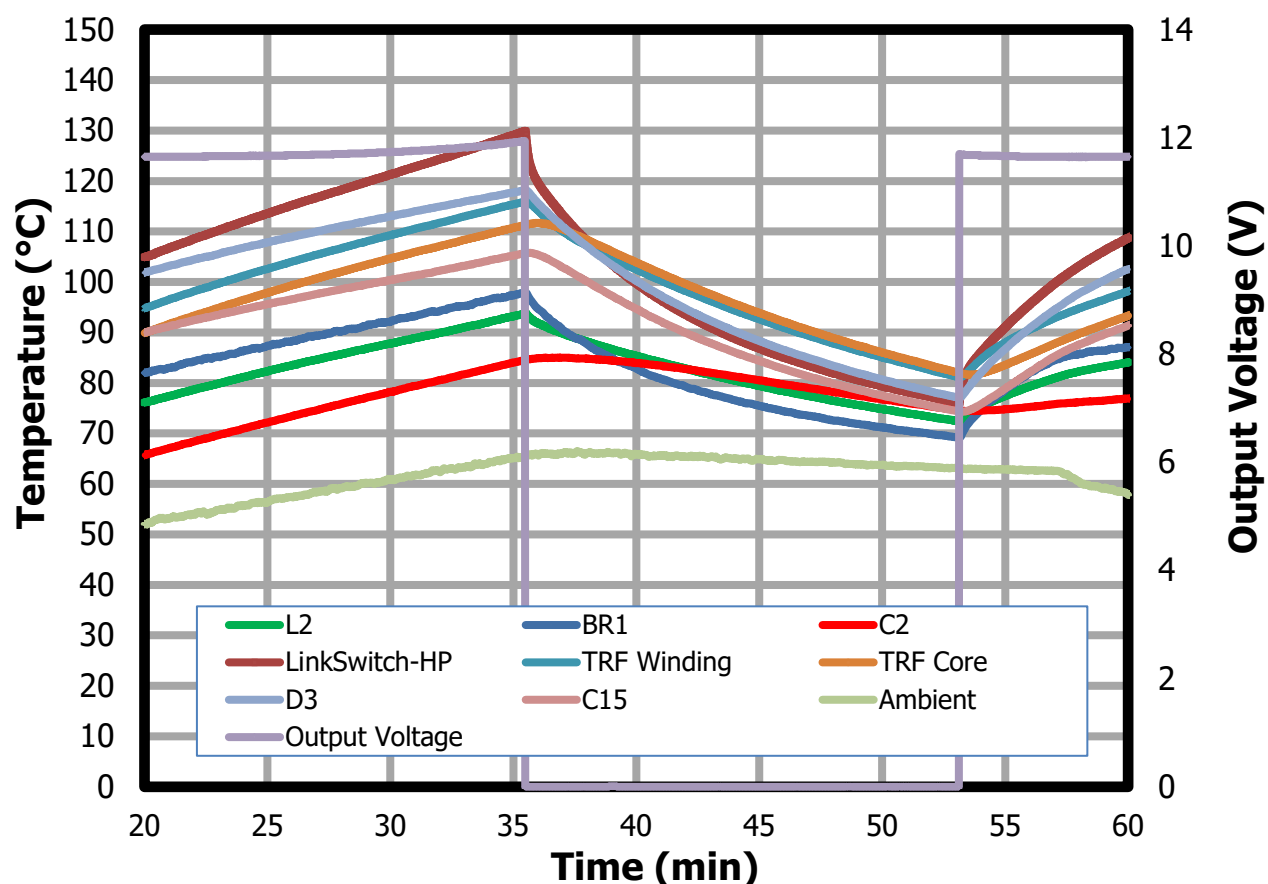


Figure 120 – 85 VAC 60 Hz. Full Load OTP.

Component	At OTP Trigger Temperature (°C)	At Recovery Temperature (°C)
Ambient	65.4	63.1
LNK6779E (U2)	130	76.1
Transformer Core (T1)	111	82
Transformer Winding (T1)	116	81.1
Bridge (BR1)	97.9	69.1
Secondary Diode (D3)	118	77.1
Bulk Capacitor (C2)	84.6	74.6
Output Capacitor (C15)	106	74.4
CMC (L2)	93.8	72.5

Table 19 – 85 VAC 60 Hz. Discrete Component Temperatures at Full Load OTP and Recovery.

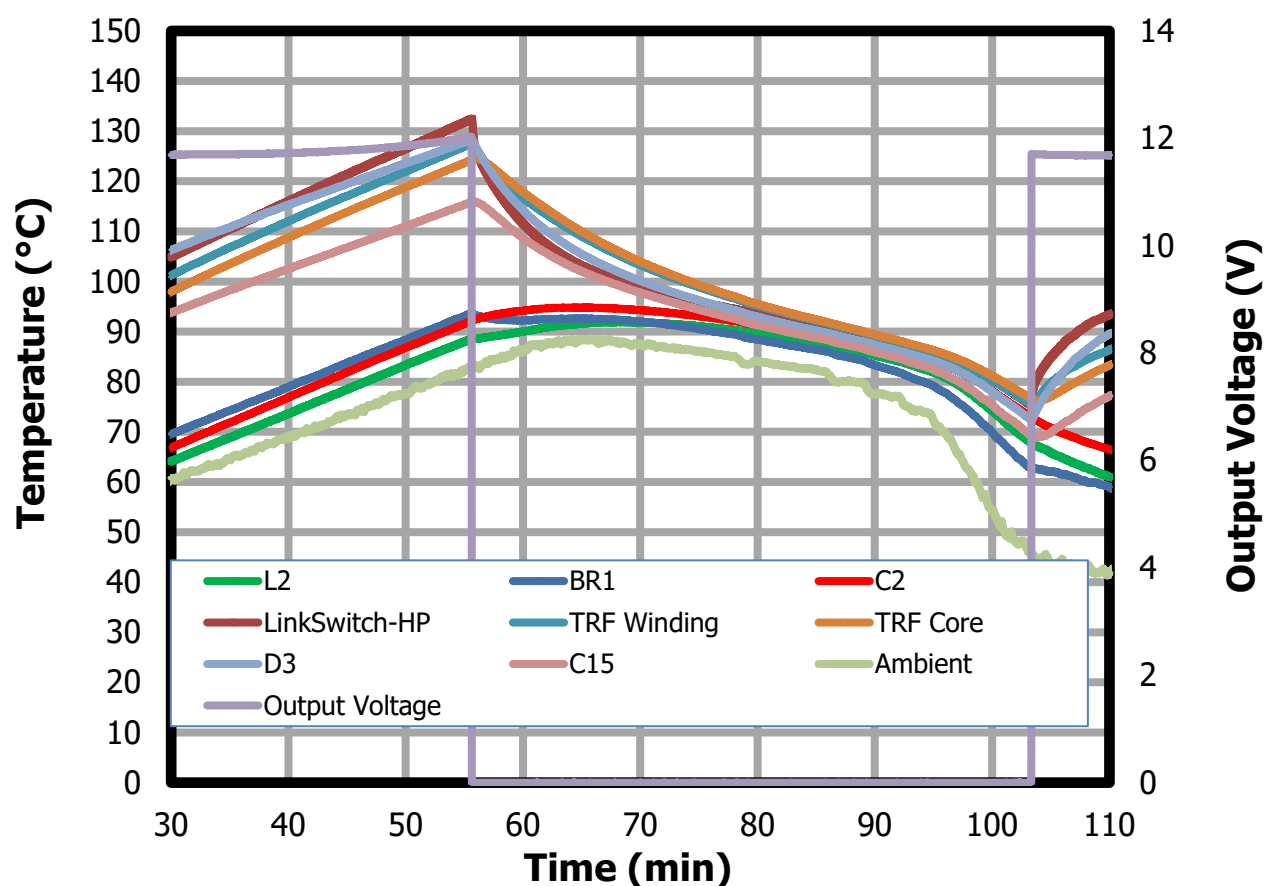


Figure 121 – 265 VAC 60 Hz. Full Load OTP.

Component	At OTP Trigger Temperature (°C)	At Recovery Temperature (°C)
Ambient	83.4	45.8
LNK6779E (U2)	133	75.2
Transformer Core (T1)	124	76.6
Transformer Winding (T1)	128	75.5
Bridge (BR1)	93.7	62.5
Secondary Diode (D3)	128	72.4
Bulk Capacitor (C2)	92.2	72.9
Output Capacitor (C15)	116	69.2
CMC (L2)	88.7	67.7

Table 20 – 265 VAC 50 Hz. Discrete Component Temperatures at Full Load OTP and Recovery.

Input (VAC)	IC Temperature (°C)	
	OTP Shutdown	Recover
85	130	76.1
265	133	75.2

Table 21 – IC Temperature at OTP Shutdown and Recovery.

15 Conducted EMI

Conducted emissions tests were performed at 115 VAC and 230 VAC at full load (12V, 6A). Measurements were taken with floating ground.

15.1 Test Set-up Equipment

15.1.1 Equipment and Load Used

1. Rohde and Schwarz ENV216 two line V-network.
2. Rohde and Schwarz ESRP EMI test receiver.
3. Input voltage set at 115 VAC and 230 VAC.
4. 12 V RLOAD resistance is 2 ohms.

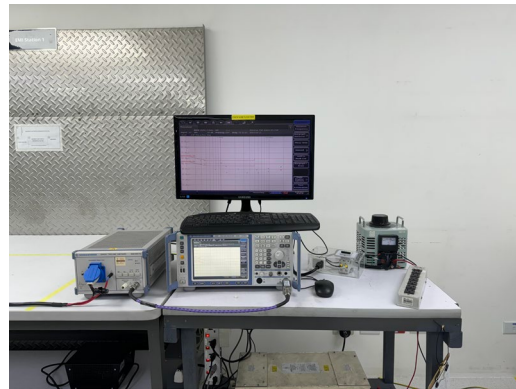
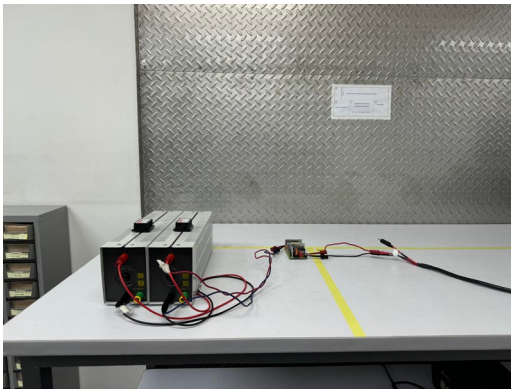


Figure 122 – EMI Test Set-up.

15.2 Output Float

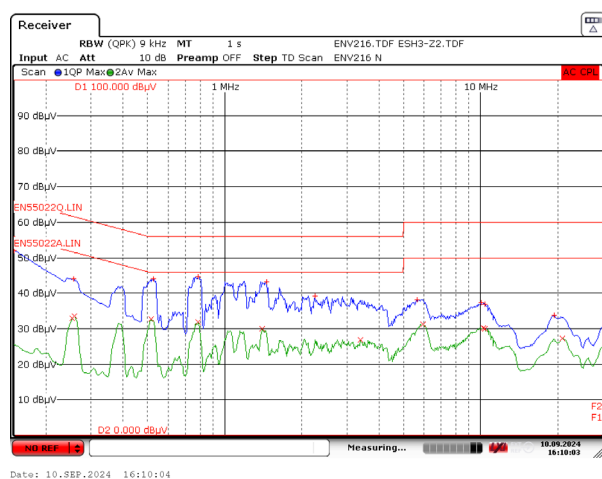


Figure 123 – 115 VAC 60 Hz.
Line / Neutral - Floating

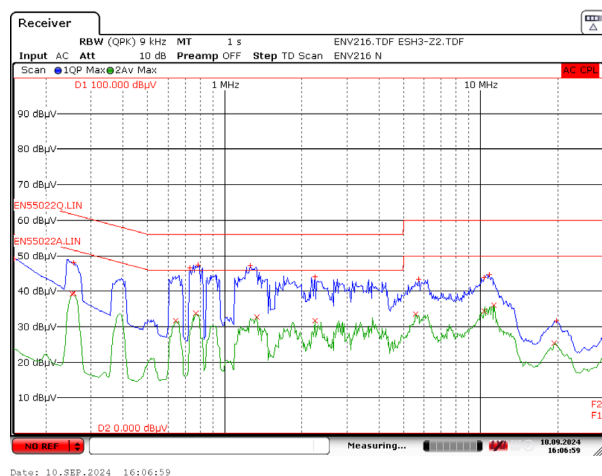


Figure 125 – 230 VAC 50 Hz.
Line / Neutral – Floating

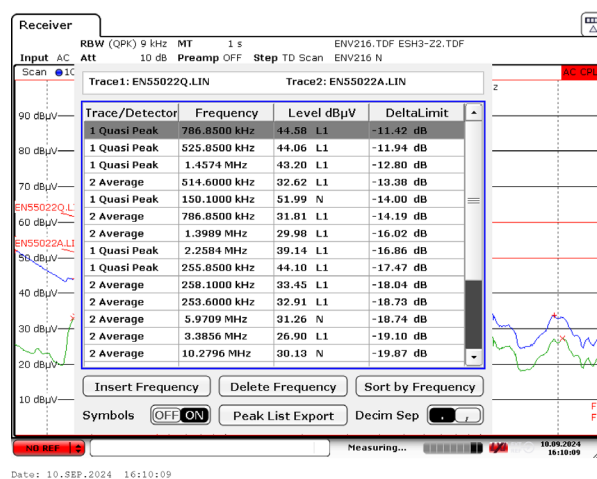


Figure 124 – 115 VAC 60 Hz.
Line / Neutral – Floating (Delta Limit)

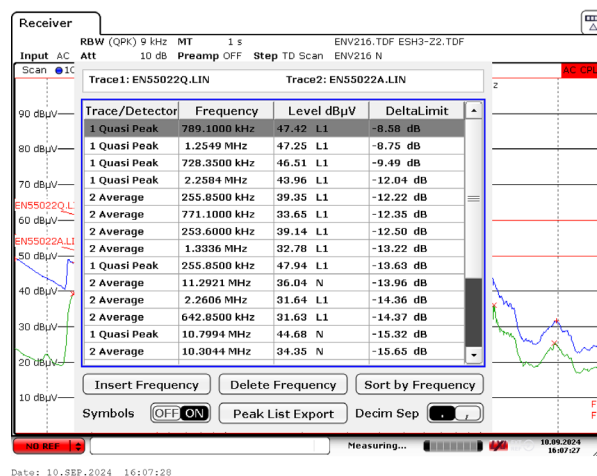


Figure 126 – 230 VAC 50 Hz.
Line / Neutral – Floating (Delta Limit)

16 Line Surge

IEC61000-4-5 differential mode and common mode input line surge testing was completed on a single test unit. Input voltage was set at 230 VAC / 60 Hz. Output was loaded at full load and operation was verified following each surge event.

16.1 Differential Mode Surge

DM Surge Level (V)	Input Voltage (VAC)	Injection Location	Injection Phase (°)	Test Result (Pass/Fail)
+1000	230	L to N	0	Pass
-1000	230	L to N	0	Pass
+1000	230	L to N	90	Pass
-1000	230	L to N	90	Pass
+1000	230	L to N	180	Pass
-1000	230	L to N	180	Pass
+1000	230	L to N	270	Pass
-1000	230	L to N	270	Pass

Note: In all PASS results, power supply is still functional after the test.

Table 22 – Differential Mode Surge at 230 VAC.

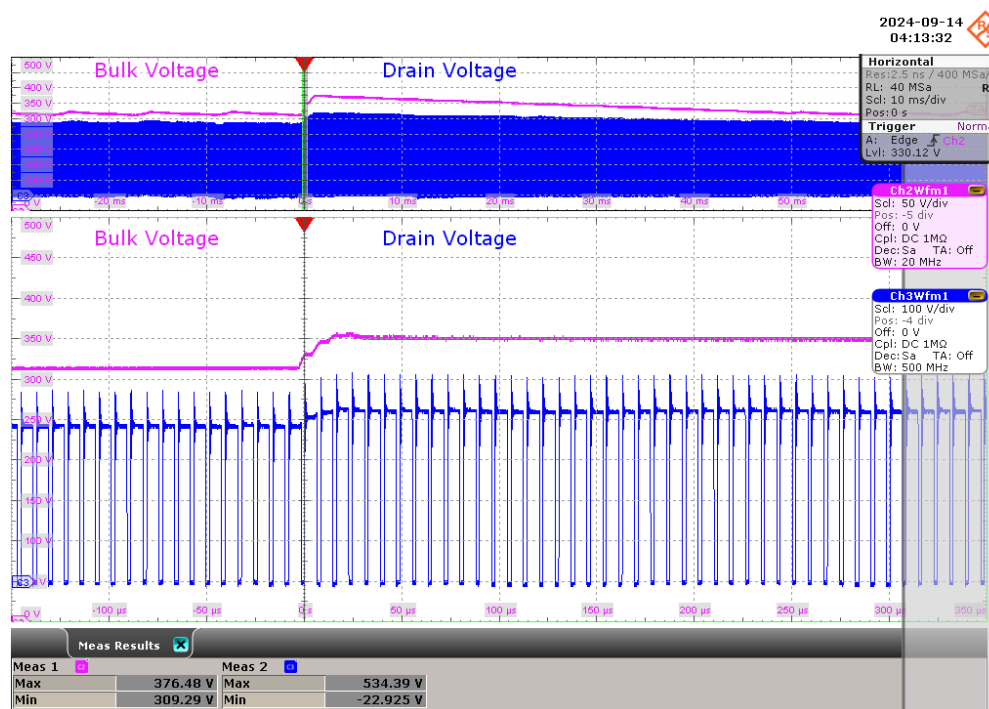


Figure 127 – Differential Mode Surge – Bulk Voltage and Drain Voltage Waveform.

CH1: Bulk Voltage, 50 V / div., 10 ms / div.

CH2: Drain Voltage, 100 V / div., 10 ms / div.

Zoom: 50 μ s / div.

Drain Voltage_(MAX): 534 V

16.2 Common Mode Ring Wave Surge

Surge Voltage	Phase Angle	IEC Coupling	Generator Impedance	Number Strikes	Result
+4000V	0°	L,N → PE	12 Ω	10	Pass
–4000V	0°	L,N → PE	12 Ω	10	Pass
+4000V	90°	L,N → PE	12 Ω	10	Pass
–4000V	90°	L,N → PE	12 Ω	10	Pass
+4000V	270°	L,N → PE	12 Ω	10	Pass
–4000V	270°	L,N → PE	12 Ω	10	Pass

Note: In all PASS results, power supply is still functional after the test.

Table 23 – Common Mode Ring Wave Surge at 230 VAC.

17 EFT

Input voltage was set at 230 VAC / 60 Hz. Output was loaded at full load and operation was verified following each surge event.

Surge Voltage	Phase Angle	IEC Coupling	Frequency	Burst Time	Reception Time	Step Duration	Result
+4000V	0°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
−4000V	0°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
+4000V	0°	L to N	100 kHz	750 μs	300 ms	120 s	Pass
−4000V	0°	L to N	100 kHz	750 μs	300 ms	120 s	Pass
+4000V	90°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
−4000V	90°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
+4000V	90°	L to N	100 kHz	750 μs	300 ms	120 s	Pass
−4000V	90°	L to N	100 kHz	750 μs	300 ms	120 s	Pass
+4000V	180°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
−4000V	180°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
+4000V	180°	L to N	100 kHz	750 μs	300 ms	120 s	Pass
−4000V	180°	L to N	100 kHz	750 μs	300 ms	120 s	Pass
+4000V	270°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
−4000V	270°	L to N	5 kHz	15 ms	300 ms	120 s	Pass
+4000V	270°	L to N	100 kHz	750 μs	300 ms	120 s	Pass
−4000V	270°	L to N	100 kHz	750 μs	300 ms	120 s	Pass

Note: In all PASS results, power supply is still functional after the test.

Table 24 – EFT at 230 VAC.

18 ESD

All ESD strikes were applied at end of cable with 230 VAC input voltage and full load.

Passed ± 8.8 kV contact discharge

Contact Discharge Voltage (kV)	Applied to	Number of Strikes	Test Result
+8.8	24 V	10	PASS
-8.8	24 V	10	PASS
+8.8	GND	10	PASS
-8.8	GND	10	PASS

Note: In all PASS results, power supply is still functional after the test.

Table 25 – ± 8.8 kV Contact Discharge at 230 VAC.

Passed ± 16.5 kV air discharge

Air Discharge Voltage (kV)	Applied to	Number of Strikes	Test Result
+16.5	24 V	10	PASS
-16.5	24 V	10	PASS
+16.5	GND	10	PASS
-16.5	GND	10	PASS

Note: In all PASS results, power supply is still functional after the test.

Table 26 – ± 16.5 kV Air Discharge at 230 VAC.

19 Revision History

Date	Author	Revision	Description and Changes	Reviewed
11-July-25	JA/CD/KP/JPM/ RPA	A	First Release	RPA



For the latest updates, visit our website: www.power.com

For patent information, Life support policy, trademark information and to access a list of Power Integrations worldwide Sales and engineering support locations and services, please use the links below.



<https://www.power.com/company/sales/sales-offices>



Power Integrations, Inc.

Tel: +1 408 414 9200 Fax: +1 408 414 9201
www.power.com